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LS TTL Data

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LS TTL Data

Formerly Titled "FAST and LS TTL Data"

Please Note: As ON Semiconductor has exited the FAST TTL business, all FAST data sheets have been removed from this publication. For further assistance, please contact your local ON Semiconductor representative.

DL121/D Rev. 6, Jan-2000



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CHAPTER 1 Selection Information LS TTL

GENERAL INFORMATION

TTL in Perspective

Since its introduction, TTL has become the most popular form of digital logic. It has evolved from the original gold-doped saturated 7400 logic, to Schottky-Clamped logic, and finally to the modern advanced families of TTL logic. The popularity of these TTL families stem from their ease of use, low cost, medium-to-high speed operation, and good output drive capability.

Low Power Schottky (LSTTL) was the industry standard logic family for many years. Since its inception, several more modern families have come out, with equal or better performance. We therefore recommend the VHC, High Speed and FACT products for all new 5.0 Volt designs. Further improvements in power reduction can be achieved using the LVX, LCX or VCX running at 3.3 Volts. Improvements in electrostatic discharge susceptibility in these newer CMOS products now make them the obviate the need for LSTTL in new designs. The VHC family is faster and lower power with similar drive characteristics compared to LSTTL. We highly recommend new designs use one or more of these CMOS families.

TTL Family Comparisons

General Characteristics for Schottky TTL Logic (All Maximum Ratings)

Characteristic	Syı	mbol	74LSxxx	Unit
Operating Voltage Range	٧	cc 'cc	5 ± 5%	Vdc
Operating Temperature Range		T _A	0 to 70	°C
Input Current	1	I _{IH}	20	μА
	IIN	I _{IL}	-400	μΑ
Output Drive	I,	ОН	-0.4	mA
Standard Output	L	OL	8.0	mA
	1.	SC	-20 to -100	mA
	I,	ОН	-15	mA
Buffer Output	I	OL	24	mA
	I,	sc	-40 to -225	mA

Speed/Power Characteristics for Schottky TTL Logic⁽¹⁾ (All Typical Ratings)

Characteristic	Symbol	Тур	Unit
Quiescent Supply Current/Gate	I _G	0.4	mA
Power/Gate (Quiescent)	P _G	2.0	mW
Propagation Delay	t _p	9.0	ns
Speed Power Product	_	18	рJ
Clock Frequency (D-F/F)	f _{max}	33	MHz
Clock Frequency (Counter)	f _{max}	40	MHz

NOTES: 1. Specifications are shown for the following conditions:

- a) $V_{CC} = 5.0 \text{ Vdc (AC)},$
- b) T_A = 25°C,
- c) $C_L = 15 pF$.

Functional Selection

Abbreviations

S = Synchronous

A = Asynchronous

B = Both Synchronous and Asynchronous

2S = 2-State Output 3S = 3-State Output

OC = Open-Collector Output

Inverters

Description	Type of Output	No.
Hex	2S OC	04 05

AND Gates

Description	Type of Output	No.
Quad 2-Input	2S	08

NAND Gates

Description	Type of Output	No.
Quad 2-Input	28	00

OR Gates

Description	Type of Output	No.
Quad 2-Input	28	32

NOR Gates

Description	Type of Output	No.
Dual 5-Input	2S	260

Exclusive OR Gates

Description	Type of Output	No.
Quad 2-Input	2\$	86

Schmitt Triggers

Description	Type of Output	No.
Hex, Inverting	2S	14
Quad 2-Input NAND Gate	2S	132

SSI Flip-Flops

Description	Clock Edge	No.
Dual D w/Set & Clear Dual JK w/Set & Clear Individual J, K, C _P , S _D , C _D Inputs	Pos Neg	74A 76A
Dual JK w/Set & Clear	Pos	109A

Multiplexers

Description	Type of Output	No.
Quad 2-to-1, Non-Inverting	2S	157
	3S	257B
Quad 2-to-1, Inverting	3S	258B
Dual 4-to-1, Non-Inverting	2S	153
	3S	253
8-to-1	2S	151
	3S	251
	2S	298

Encoders

Description	Type of Output	No.
10-to-4-Line BCD	2S	147
8-to-3-Line Priority Encoder	2S	148

Register Files

Description	Type of Output	No.
4 x 4	3S	670

Decoders/Demultiplexers

Description	Type of Output	No.
Dual 1-of-4	2S	139
	OC	156
1-of-8	2S	138
1-of-10	2S	42

Latches

Description	No. of Bits	Type of Output	No.
Transparent, Non-Inverting	8	3S	373
Addressable	8	2S	259

Shift Registers

	No. of	Type of	Mode*				
Description	Bits	Output	SR	SL	Hold	Reset	No.
Serial In-Parallel Out	8	2S	Х			А	164
Parallel In-Serial Out	8	2S	X		Χ		165
	8	2S	X		Χ	Α	166
Parallel In-Parallel Out	4	2S	X	Х	Χ	Α	194A
	4	2S	X			Α	195A
Parallel In-Parallel Out, Bidirectional	8	3S	Х	Х	Х	А	299

^{*} SR = Shift Right SL = Shift Left

Asynchronous Counters — Negative Edge-Triggered

Description	Load	Set	Reset	No.
Dual 4-Bit Binary			Х	393

^{*} The 716 and 718 are positive edge-triggered.

Display Decoders/Drivers with Open-Collector Outputs

Description	No.
1-of-10	145
BCD-to-7 Segment	247

Cascadable Synchronous Counters — Positive Edge-Triggered

Description	Type of Output	Load	Reset	No.
4-Bit Binary	2S 2S	S V	A	161A 163A
·	2S	S	S	

MSI Flip-Flops/Registers

Description	No. of Bits	Type of Output	Set or Reset	Clock Enable	No.
D-Type, Non-Inverting	4	28		Х	377
	6	2S	Α		174
	8	2S	Α		273
	8	3S			374
D-Type, Q and Q Outputs	4	2S	Α		175

Arithmetic Operators

Description	No.
4-Bit Adder	283

Magnitude Comparators

Description	Type of Output	P = Q	P>Q	P <q< th=""><th>No.</th></q<>	No.
4-Bit	2S	Х	Х	Х	85
8-Bit	2S	Х	Х		682
	2S	Х	Х		684
8-Bit with Output Enable	2S	Х			688

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Description	No.
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Precision Non-Retriggerable Monostable	221
Multivibrator	

Buffers/Line Drivers

Description	Type of Output	No.
Quad 2-Input NAND	ОС	38
Quad, Non-Inverting	3S	125A
		126A
Hex, Non-Inverting	3S	365A
		367A
Hex, Inverting		368A
Octal, Non-Inverting	3S	244
Bus Pinout	3S	541
Octal, Inverting	3S	240

Transceivers

Description	Type of Output	No.
Octal, Non-Inverting	38	245
	OC	641
Octal, Inverting	3S	640
	OC	642

CHAPTER 2 Circuit Characteristics

CIRCUIT CHARACTERISTICS

FAMILY CHARACTERISTICS LS TTL

The Low Power Schottky (LS TTL) family combines a current and power reduction improvement over standard 7400 TTL by a factor of 5. This is accomplished by using Schottky diode clamping to prevent saturation and advanced processing.

CIRCUIT FEATURES

Circuit features of the LS are best understood by examining the TTL 2-input NAND gate (Figure 1). While LS has been a popular series in the past, more modern products such as VHC should be replacing LSTTL in new designs. For applications where high drive is required, FACT is an ideal choice.

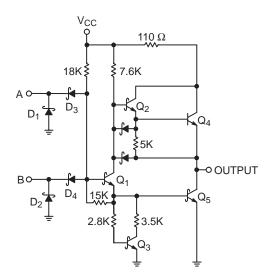


Figure 1. LS00 — 2-Input NAND Gate

INPUT CONFIGURATION

ON Semiconductor LSTTL circuits do not use the multi-emitter input structure that originally gave TTL its name. Most LS elements use a DTL type input circuit with Schottky diodes to perform the AND function, as exemplified by D3 and D4 in Figure 1. Compared to the classical multi-emitter structure, this circuit is faster and increases the input breakdown voltage. Inputs of this type are tested for leakage with an applied input voltage of 7.0 V and the input breakdown voltage is typically 15 V or more.

Another input arrangement often used in LS MSI has three diodes connected as shown in Figure 2. This configuration gives a slightly higher input threshold than that of Figure 1. A third input configuration that is sometimes used in LS TTL employs a vertical PNP transistor as shown in Figure 3. This arrangement also gives a higher input threshold and has

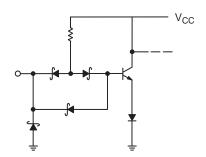


Figure 2. Diode Cluster Input

INPUT CHARACTERISTICS

Figure 4 shows the typical input characteristics of LS. Typical transfer characteristics can be found in Figure 5 and

the additional advantage of reducing the amount of current that the signal source must sink. Both the diode cluster arrangement and the PNP input configuration have breakdown voltage ratings greater than 7.0 V.

All inputs are provided with clamping diodes, exemplified by D1 and D2 in Figure 1. These diodes conduct when an input signal goes negative, which limits undershoot and helps to control ringing on long signal lines following a HIGH-to-LOW transition. These diodes are intended only for the suppression of transient currents and should not be used as steady-state clamps in interface applications. A clamp current exceeding 2.0 mA and with a duration greater than 500 ns can activate a parasitic lateral NPN transistor, which in turn can steal current from internal nodes of an LS circuit and thus cause logic errors.

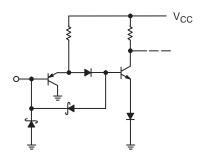


Figure 3. PNP Input

input threshold variation with temperature information is provided in Table 1.

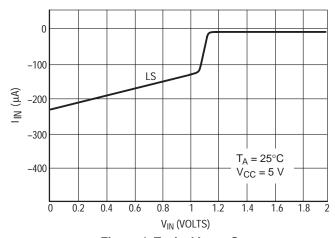


Figure 4. Typical Input Current versus Input Voltage

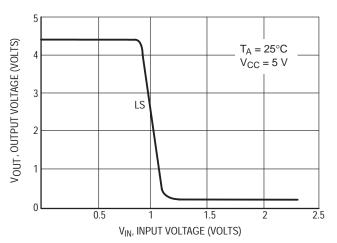


Figure 5. Typical Output versus Input Voltage Characteristic

Table 1. Typical Input Threshold Variation with Temperature

	−55°C	+25°C	+125°C
ALS	1.8	1.5	1.3
S	1.5	1.3	1.1
LS	1.2	1.0	0.8

OUTPUT CONFIGURATION

The output circuitry of LSTTL has several features not found in conventional TTL. A few of these features are discussed below.

Referring to Figure 1, the base of the pull-down output transistor Q5 is returned to ground through Q3 and a pair of resistors instead of through a simple resistor. This arrangement is called a squaring network since it squares up the transfer characteristics (Figure 5) by preventing conduction in the phase splitter Q1 until the input voltage rises high enough to allow Q1 to supply base current to Q5. The squaring network also improves the propagation delay by providing a low resistance path to discharge capacitance at the base of Q5 during turn-off.

The output pull-up circuit is a 2-transistor Darlington circuit with the base of the output transistor returned through

a 5.0K resistor to the output terminals, unlike 74H and 74S where it is returned to ground which is a more power consuming configuration. This configuration allows the output to pull up to one V_{BE} below V_{CC} for low values of output current.

Figure 6 shows the extra circuitry used to obtain the "high Z" condition in 3-state outputs. When the Output Enable signal is HIGH, both the phase splitter and the Darlington pull-up are turned off. In this condition the output circuitry is non-conducting, which allows the outputs of two or more such circuits to be connected together in a bus application wherein only one output is enabled at any particular time.

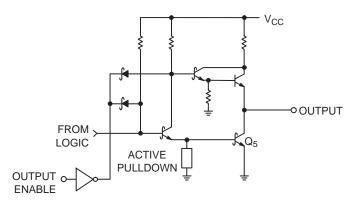


Figure 6. Typical 3-State Output Control

OUTPUT CHARACTERISTICS

Figure 7 shows the LOW-state output characteristics for LS. For LOW I_{OL} values, the pull-down transistor is

clamped out of deep saturation to shorten the turn-off delay. Figure 8 shows the HIGH-state output characteristics.

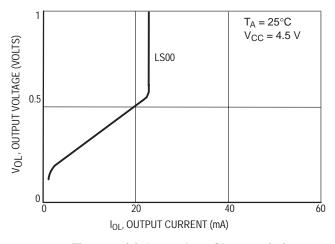


Figure 7. (a) Output Low Characteristic

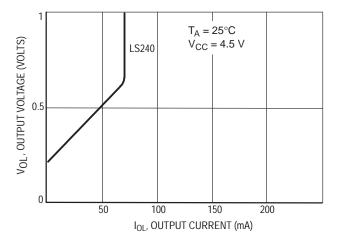
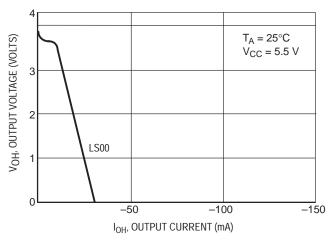


Figure 7. (b) Output Low Characteristic





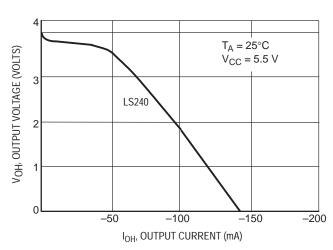


Figure 8. (b) Output High Characteristic

AC SWITCHING CHARACTERISTICS

The propagation through a logic element depends on power supply voltage, ambient temperature, and output load. The effect of each of these parameters on ac propagation is shown in Figures 9 through 11.

Propagation delays are specified with only one output switching, the delay through a logic-element will increase to some extent when multiple outputs switch simultaneously due to inductance internal to the IC package.

For LS TTL, limits are guaranteed at 25°C, $V_{CC} = 5.0$ V, and $C_L = 15$ pF (normally, resistive load has minimal effect on propagation delay) TTL limits are guaranteed over the commercial or military temperature and supply voltage ranges and with $C_L = 50$ pF.

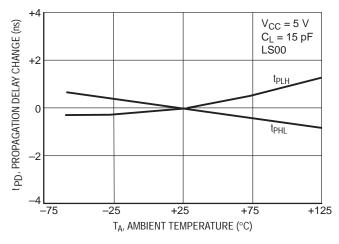


Figure 9.

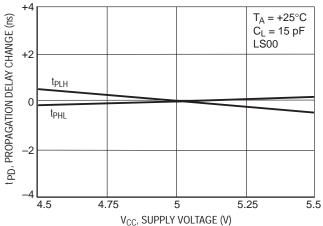
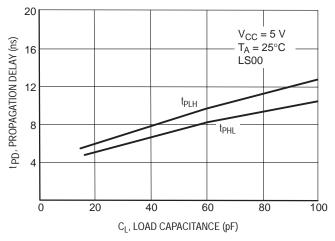


Figure 10.



*Data for Figure 11 was taken with only one output switching at a time.

Figure 11. *

ESD CHARACTERISTICS

Electrostatic Discharge (ESD) sensitivity for ON Semiconductor TTL is characterized using several methodologies (HBM, MM, CDM). It is extremely important to understand that ESD sensitivity values alone are not sufficient when comparing devices. In an attempt to reduce correlation problems between various pieces of test equipment, all of which meet Mil-Std-883C requirements, tester specific information as well as actual device ESD

hardness levels are given in controlled documents and are available upon request. The continuing improvements of ESD sensitivity through redesigns of ON Semiconductor TTL has resulted in minimum ESD levels for all new products and redesigns of >3500 volts for LS. For device specific values reference the following specification:

LS: 12MRM 93831A

CHAPTER 3 Design Considerations Testing and Applications Assistance Form

DESIGN CONSIDERATIONS

NOISE IMMUNITY

When mixing TTL families it is often desirable to know the guaranteed noise immunity for both LOW and HIGH logic levels. Table 2 lists the guaranteed logic levels for various TTL families and can be used to calculate noise margin. Table 3 specifies these noise margins for systems containing LS, S, and/or ALS TTL. Note that Table 3 represents "worst case" limits and assumes a maximum power supply and temperature variation across the IC's which are interconnected, as well as maximum rated load. Increased noise immunity can be achieved by designing with decreased maximum allowable operating ranges.

Table 2. Worst Case TTL Logic Levels

Electrical Characteristics

			Military (-55 to +125°C)		Com	mercia	l (0 to 7	70°C)			
		TTL Families	V _{IL}	V _{IH}	V _{OL}	V _{OH}	V _{IL}	V _{IH}	V _{OL}	V _{OH}	Unit
TTL		Standard TTL 9000, 54/74	0.8	2.0	0.4	2.4	0.8	2.0	0.4	2.4	V
HTTL		High Speed TTL 54/74H	0.8	2.0	0.4	2.4	0.8	2.0	0.4	2.4	V
LPTTL		Low Power TTL 93L00 (MSI)	0.7	2.0	0.3	2.4	0.8	2.0	0.3	2.4	V
STTL		Schottky TTL 54/74S, 93S00	0.8	2.0	0.5	2.5	0.8	2.0	0.5	2.7	V
LSTTL		Low Power Schottky TTL 54/74LS	0.7	2.0	0.4	2.5	0.8	2.0	0.5	2.7	V
ALS TTL	(5% V _{CC})	Advanced LS TTL, 54/74ALS	1		1		0.8	2.0	0.5	2.75	V
	(10% V _{CC})		0.8	2.0	0.4	2.5	0.8	2.0	0.5	2.5	V

 V_{OL} and V_{OH} are the voltages generated at the output V_{IL} and V_{IH} are the voltage required at the input to generate the appropriate levels. The numbers given above are guaranteed worst-case values.

Table 3. (a)
LOW Level Noise Margins (Commercial)

То				
From	LS	S	ALS	Unit
LS	300	300	300	mV
S	300	300	300	mV
ALS	300	300	300	mV

From " V_{OL} " to " V_{IL} "

POWER CONSUMPTION

With the exception of ECL, all logic families exhibit increased power consumption at high frequencies. Care must be taken when switching multiple gates at high frequencies to assure that their combined dissipation does not exceed package and/or device capabilities. TTL devices are more efficient at high frequencies than CMOS.

Table 3. (b)
HIGH Level Noise Margins (Commercial)

То				
From	LS	S	ALS	Unit
LS	700	700	700	mV
S	700	700	700	mV
ALS (5% V _{CC})	750	750	750	mV
ALS (10% V _{CC})	500	500	500	mV

From "VOH" to "VIH"

FAN-IN AND FAN-OUT

In order to simplify designing with ON Semiconductor TTL devices, the input and output loading parameters of all families are normalized to the following values:

- 1 TTL Unit Load (U.L.) = 40 μA in the HIGH state (Logic "1")
- 1 TTL Unit Load (U.L.) = 1.6 mA in the LOW state (Logic "0")

Input loading and output drive factors of all products described in this handbook are related to these definitions.

EXAMPLES — INPUT LOAD

- 1. A 7400 gate, which has a maximum I_{IL} of 1.6 mA and I_{IH} of 40 μ A is specified as having an input load factor of 1 U.L. (Also called a fan-in of 1 load.)
- 2. The 74LS95B which has a value of I_{IL} = 0.8 mA and I_{IH} of 40 μA on the CP terminal, is specified as having an input LOW load factor of:

$$\frac{0.8~\text{mA}}{1.6~\text{mA}}$$
 or 0.5 U.L. and an input HIGH load factor of $\frac{40~\mu\text{A}}{40~\mu\text{A}}$ or 1 U.L.

3. The 74LS00 gate which has an I_{IL} of 0.4 mA and an I_{IH} of 20 μA , has an input LOW load factor of:

$$\frac{\text{0.4 mA}}{\text{1.6 mA}} \text{ or 0.25 U.L.} \quad \text{an input HIGH load factor of} \quad \frac{20 \ \mu\text{A}}{40 \ \mu\text{A}} \quad \text{or 0.5 U.L.}$$

EXAMPLES — OUTPUT DRIVE

1. The output of the 7400 will sink 16 mA in the LOW (logic "0") state and source $800\,\mu\text{A}$ in the HIGH (logic "1") state. The normalized output LOW drive factor is therefore:

$$\frac{16 \text{ mA}}{1.6 \text{ mA}} = 10 \text{ U.L.}$$

and the output HIGH drive factor is

$$\frac{800~\mu\text{A}}{40~\text{uA}}~~\text{or 20 U.L.}$$

2. The output of the 74LS00 will sink 8.0 mA in the LOW state and source 400 μ A in the HIGH state. The normalized output LOW drive factor is:

$$\frac{8.0 \text{ mA}}{1.6 \text{ mA}} = 5 \text{ U.L.}$$

and the output HIGH drive factor is

$$\frac{400~\mu\text{A}}{40~\mu\text{A}}~\text{or}~10~\text{U.L.}$$

Relative load and drive factors for the basic TTL families are given in Table 4.

Table 4.

FAMILY	INPUT	LOAD	OUTPUT DRIVE		
PAMILI	HIGH	LOW	HIGH	LOW	
74LS00	0.5 U.L.	0.25 U.L.	10 U.L.	5 U.L.	
7400	1 U.L.	1 U.L.	20 U.L.	10 U.L.	
9000	1 U.L.	1 U.L.	20 U.L.	10 U.L.	
74H00	1.25 U.L.	1.25 U.L.	25 U.L.	12.5 U.L.	
74S00	1.25 U.L	1.25 U.L.	25 U.L.	12.5 U.L.	
74 ALS	0.5 U.L	0.0625 U.L	10 U.L.	5 U.L.	

Values for MSI devices vary significantly from one element to another. Consult the appropriate data sheet for actual characteristics.

WIRED-OR APPLICATIONS

Certain TTL devices are provided with an "open" collector output to permit the Wired-OR (actually Wired-AND) function. This is achieved by connecting open collector outputs together and adding an external pull-up resistor.

The value of the pull-up resistor is determined by considering the fan-out of the OR tie and the number of devices in the OR tie. The pull-up resistor value is chosen from a range between maximum value (established to maintain the required V_{OH} with all the OR tied outputs HIGH) and a minimum value (established so that the OR tie fan-out is not exceeded when only one output is LOW).

MINIMUM AND MAXIMUM PULL-UP RESISTOR VALUES

$$R_{X(MIN)} = \frac{V_{CC(MAX)} - V_{OL}}{I_{OL} - N_2(LOW) \bullet 1.6 \text{ mA}} \qquad R_{X(MAX)} = \frac{V_{CC(MIN)} - V_{OH}}{N_1 \bullet I_{OH} + N_2(HIGH) \bullet 40 \, \mu A}$$
 where:
$$R_X = \text{External Pull-up Resistor}$$

$$N_1 = \text{Number of Wired-OR Outputs}$$

$$N_2 = \text{Number of Input Unit Loads (U.L.) being Driven}$$

$$I_{OH} = I_{CEX} = \text{Output HIGH Leakage Current}$$

$$I_{OL} = \text{LOW Level Fan-out Current of Driving Element}$$

$$V_{OL} = \text{Output LOW Voltage Level (0.5 V)}$$

$$V_{OH} = \text{Output HIGH Voltage Level (2.4 V)}$$

$$V_{CC} = \text{Power Supply Voltage}$$

Example: Four 74LS03 gate outputs driving four other LS gates or MSI inputs.

$$\begin{split} R_{X(MIN)} = & \frac{5.25 \text{ V} - 0.5 \text{ V}}{8.0 \text{ mA} - 1.6 \text{ mA}} = \frac{4.75 \text{ V}}{6.4 \text{ mA}} = 742 \, \Omega \\ R_{X(MAX)} = & \frac{4.75 \text{ V} - 2.4 \text{ V}}{4 \bullet 100 \, \mu\text{A} + 2 \bullet 40 \, \mu\text{A}} = \frac{2.35 \text{ V}}{0.48 \text{ mA}} = 4.9 \, k\Omega \\ & \text{where:} \\ & N_1 & = 4 \\ & N_2 \text{ (HIGH)} & = 4 \bullet 0.5 \text{ U.L.} = 2 \text{ U.L.} \\ & N_2 \text{ (LOW)} & = 4 \bullet 0.25 \text{ U.L.} = 1 \text{ U.L.} \\ & I_{OH} & = 100 \, \mu\text{A} \\ & I_{OL} & = 8.0 \, \text{mA} \\ & \text{V}_{OL} & = 0.5 \text{ V} \\ & \text{V}_{OH} & = 2.4 \text{ V} \end{split}$$

Any value of pull-up resistor between 742 Ω and 4.9 k Ω can be used. The lower values yield the fastest speeds while the higher values yield the lowest power dissipation.

UNUSED INPUTS

For best noise immunity and switching speed, unused TTL inputs should not be left floating, but should be held between 2.4 V and the absolute maximum input voltage.

Two possible ways of handling unused inputs are:

- 1. Connect unused input to V_{CC}, LS TTL inputs have a breakdown voltage >7.0 V and require, therefore no series resistor.
- 2. Connect the unused input to the output of an unused gate that is forced HIGH.

CAUTION: Do not connect an unused LS input to another input of the same NAND or AND function. This method, recommended for normal TTL, increases the input coupling capacitance and thus reduces the ac noise immunity.

INPUT CAPACITANCE

As a rule of thumb, LS TTL inputs have an average capacitance of 5.0 pF for DIP packages. For an input that serves more than one internal function, each additional function adds approximately 1.5 pF.

LINE DRIVING

Because of its superior capacitive drive characteristics, TTL logic is often used in line driving applications which require various termination techniques to maintain signal integrity. Parameters associated with this application are listed in Table 5.

It is also often necessary to construct load lines to determine reflection waveforms in line driving applications. The input and output characteristics graphs of Section 2 (Figures 4, 7, and 8) can be very useful for this purpose.

OUTPUT RISE AND FALL TIMES

provide important information in determining reflection waveforms and crosstalk coefficients. Typical rise and fall times are approximately 6 ns for LS with a 50 pF load (measured 10–90%). Output rise and fall times become longer as capacitive load is increased.

INTERCONNECTION DELAYS

For those parts of a system in which timing is critical, designers should take into account the finite delay along the interconnections. These range from about 0.12 to 0.15 ns/inch for the type of interconnections normally used in TTL systems. Exceptions occur in systems using ground planes to reduce ground noise during a logic transition; ground planes give higher distributed capacitance and delays of about 0.15 to 0.22 ns/inch.

Most interconnections on a logic board are short enough that the wiring and load capacitance can be treated as a lumped capacitance for purposes of estimating their effect

on the propagation delay of the driving circuit. When an interconnection is long enough that its delay is one-fourth to one-half of the signal transition time, the driver output waveform exhibits noticeable slope changes during a transition. This is evidence that during the initial portion of the output voltage transition the driver sees the characteristic impedance of the interconnection (normally 100 Ω to 200 Ω), which for transient conditions appears as a resistor returned to the quiescent voltage existing just before the beginning of the transition. This characteristic impedance forms a voltage divider with the driver output impedance, tending to produce a signal transition having the same rise or fall time as in the no-load condition but with a reduced amplitude. This attenuated signal travels to the far end of the interconnection, which is essentially an unterminated transmission line, whereupon the signal starts doubling. Simultaneously, a reflection voltage is generated which has the same amplitude and polarity as the original signal, e.g., if the driver output signal is positive-going the reflection will be positive-going, and as it travels back toward the driver it adds to the line voltage. At the instant the reflection arrives at the driver it adds algebraically to the still-rising driver output, accelerating the transition rate and producing the noticeable change in slope.

Table 5.

Output Characteristics for Schottky TTL Logic

(ALL MAXIMUM RATINGS)	LS		
Characteristic	Symbol	74LSxxx	Unit
Operating Voltage Range	V _{CC}	5 ± 5%	Vdc
Output Drive:	I _{OH}	-0.4	mA
Standard Output	I _{OL}	8.0	mA
	I _{SC}	−20 to −100	mA
	I _{OH}	– 15	mA
Buffer Output	I _{OL}	24	mA
	I _{SC}	-40 to -225	mA

If an interconnection is of such length that its delay is longer than half the signal transition time, the attenuated output of the driver has time to reach substantial completion before the reflection arrives. In the limit, the waveform observed at the driver output is a 2-step signal with a pedestal. In this circumstance the first load circuit to receive a full signal is the one at the far end, because of the doubling effect, while the last one to receive a full signal is the one nearest the driver since it must wait for the reflection to complete the transition. Thus, in a worst-case situation, the net contribution to the overall delay is twice the delay of the interconnection because the initial part of the signal must travel to the far end of the line and the reflection must return.

When load circuits are distributed along an interconnection, the input capacitance of each will cause a small reflection having a polarity opposite that of the signal

transition, and each capacitance also slows the transition rate of the signal as it passes by. The series of small reflections, arriving back at the driver, is subtractive and has the effect of reducing the apparent amplitude of the signal. The successive slowing of the transition rate of the transmitted signal means that it takes longer for the signal to rise or fall to the threshold level of any particular load circuit. A rough but workable approach is to treat the load capacitances as an increase in the intrinsic distributed capacitance of the interconnection. Increasing the distributed capacitance of a transmission line reduces its impedance and increases its delay. A good approximation for ordinary TTL interconnections is that distributed load capacitance decreases the characteristic impedance by about one-third and increases the delay by one-half.

ABSOLUTE MAXIMUM RATINGS (above which the useful life may be impaired)

Functional operation under these conditions is not implied.

CHARACTERISTIC	LS
Storage Temperature	−65°C to +150°C
Temperature (Ambient) Under Bias	−55°C to +125°C
V _{CC} Pin Potential to Ground Pin	−0.5 V to +7.0 V
*Input Voltage (dc) Diode Inputs	−0.5 V to +15 V
*Input Current (dc)	-30 mA to +5.0 mA
Voltage Applied to Open Collector Outputs	
(Output HIGH)	-0.5 V to +10 V
High Level Voltage Applied to Disabled	
3-State Output	5.5 V
Current Applied to Output in Low State (Max)	Twice Rated I _{OL}

^{*}Either input voltage limit or input current limit is sufficient to protect the inputs — Circuits with 5.5 V maximum limits are listed below.

Device types having inputs limited to 5.5 V are as follows:

SN74LS245

- Inputs connected to outputs.

SN74LS640/641/642/645

- Inputs connected to outputs.

SN74LS299 SN74LS151/251 - Certain Inputs. - Multiplexer Inputs.

DEFINITION OF SYMBOLS AND TERMS USED IN THIS DATA BOOK

- **CURRENTS** Positive current is defined as conventional current flow into a device. Negative current is defined as conventional current flow out of a device. All current limits are specified as absolute values.
- I_{CC} **Supply Current**—The current flowing into the V_{CC} supply terminal of a circuit with the specified input conditions and the outputs open. When not specified, input conditions are chosen to guarantee worst case operation.
- I_{IH} Input HIGH current The current flowing into an input when a specified HIGH voltage is applied to that input.
- Input LOW current The current flowing out of an input when a specified LOW voltage is applied to that input.
- I_{OH}
 Output HIGH current. The leakage current flowing into a turned off open collector output with a specified HIGH output voltage applied. For devices with a pull-up circuit, the I_{OH} is the current flowing out of an output which is in the HIGH state.
- I_{OL} Output LOW current The current flowing into an output which is in the LOW state.
- IOS Output short-circuit current The current flowing out of an output which is in the HIGH state when that output is short circuit to ground (or other specified potential).
- I_{OZH} Output off current HIGH The current flowing into a disabled 3-state output with a specified HIGH output voltage applied.
- I_{OZL} Output off current LOW The current flowing out of a disabled 3-state output with a specified LOW output voltage applied.
- **VOLTAGES** All voltages are referenced to ground. Negative voltage limits are specified as absolute values (*i.e.*, –10 V is greater than –1.0 V).
- V_{CC} **Supply voltage** The range of power supply voltage over which the device is guaranteed to operate within the specified limits.
- V_{IK(MAX)} Input clamp diode voltage The most negative voltage at an input when the specified current is forced out of that input terminal. This parameter guarantees the integrity of the input diode which is intended to clamp negative ringing at the input terminal.
- V_{IH} Input HIGH voltage The range of input voltages recognized by the device as a logic HIGH.
- V_{IH(MIN)} **Minimum input HIGH voltage** The minimum allowed input HIGH in a logic system. This value represents the guaranteed input HIGH threshold for the device.
- V_{II} Input LOW voltage The range of input voltages recognized by the device as a logic LOW.
- V_{IL(MAX)} **Maximum input LOW voltage** The maximum allowed input LOW in a system. This value represents the guaranteed input LOW threshold for the device.
- V_{OH(MIN)} Output HIGH voltage The minimum guaranteed voltage at an output terminal for the specified output current I_{OH} and at the minimum value of V_{CC}.
- V_{OL(MAX)} Output LOW voltage The maximum guaranteed voltage at an output terminal sinking the maximum specified load current I_{OL}.
- V_{T+} **Positive-going threshold voltage** The input voltage of a variable threshold device (*ie.*, Schmitt Trigger) that is interpreted as a V_{IH} as the input transition rises from below $V_{T-(MIN)}$.
- V_{T-} **Negative-going threshold voltage** The input voltage of a variable threshold device (*ie.*, Schmitt Trigger) that is interpreted as a V_{IL} as the input transition falls from above $V_{T+(MAX)}$.

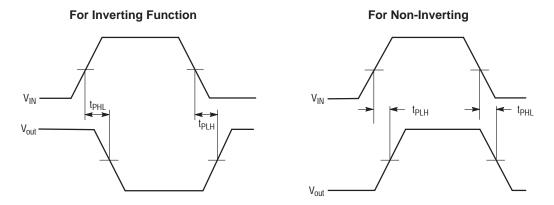
AC SWITCHING PARAMETERS AND WAVEFORMS

t_{PLH} LOW-TO-HIGH propagation delay time :

The time delay between specified reference points, typically 1.3 V for LS, on the input and output voltage waveforms, with the output changing from the defined LOW level to the defined HIGH level.

t_{PHL} HIGH-TO-LOW propagation delay time:

The time delay between specified reference points, typically 1.3 V for LS, on the input and output voltage waveforms, with the output changing from the defined HIGH level to the defined LOW level.



t_r Waveform Rise Time:

LOW to HIGH logic transition time, measured from the 10% to 90% points of the waveform.

t_f Waveform Fall Time:

HIGH to LOW logic transition time, measured the 90% to the 10% points of the waveform.

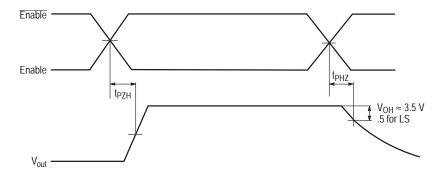


t_{PHZ} Output disable time: HIGH to Z

The time delay between the specified reference points on the input and output voltage waveforms, with the 3-state output changing from the defined HIGH level to a high impedance (OFF) state. Reference point on the output voltage waveform is $V_{OH} - 0.5 \text{ V}$ for LS and $V_{OH} - 0.3 \text{ V}$ for FAST.

t_{PZH} Output enable time: Z to HIGH

The time delay between the specified reference points on the input and output voltage waveforms, with the 3-state output changing from a high impedance (OFF) state to a HIGH level.

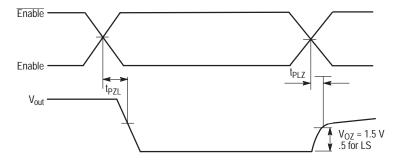


t_{PLZ} Output disable time: LOW to Z

The time delay between the specified reference points on the input and output voltage waveforms, with the 3-state output changing from the defined LOW level to a high impedance (OFF) state. Reference point on the output voltage waveform is $V_{OL} + 0.5 \text{ V}$ for LS.

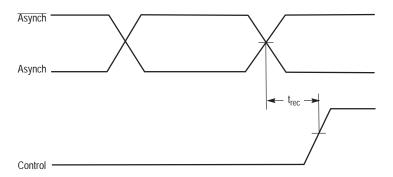
t_{PZL} Output enable time: Z to LOW

The time delay between the specified reference points on the input and output voltage waveforms with the 3-state output changing from a high impedance (OFF) state to a HIGH level.



t_{rec} Recovery time

Time required between an asynchronous signal (SET, RESET, CLEAR or PARALLEL load) and the active edge of a synchronous control signal, to insure that the device will properly respond to the synchronous signal.

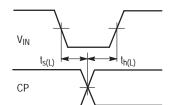


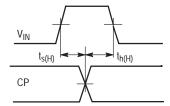
th Hold Time

The interval of time from the active edge of the control signal (usually the clock) to when the data to be recognized is no longer required to ensure proper interpretation of the data. A negative hold time indicates that the data may be removed at some time prior to the active edge of the control signal.

t_s Setup time

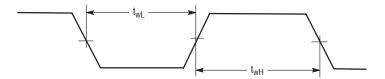
The interval of time during which the data to be recognized is required to remain constant prior to the active edge of the control signal to ensure proper data recognition. A negative setup time indicates that data may be initiated sometime after the active transition of the timing pulse and still be recognized.





$t_{\rm w}$ or **Pulse width**

 t_{pw} The time between the specified amplitude points (1.3 V for LS) on the leading and trailing edges of a pulse.



f_{MAX} Toggle frequency/operating frequency

The maximum rate at which clock pulses meeting the clock requirements (ie., t_{WH} , t_{WL} , and t_r , t_f) may be applied to a sequential circuit. Above this frequency the device may cease to function.

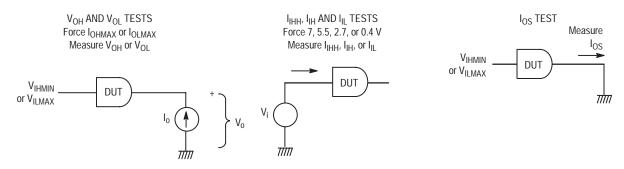
f_{MAX}min Guaranteed maximum clock frequency

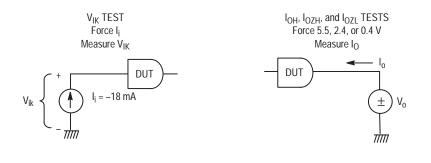
The lowest possible value for f_{MAX}.

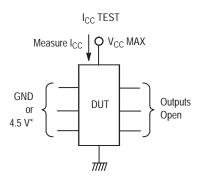
TESTING

DC TEST CIRCUITS

The following test circuits and forcing functions represent ON Semiconductor's typical DC test procedures.







^{*}Unless otherwise indicated, input conditions are selected to produce a worst case condition.

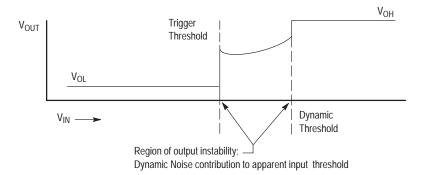
AC TEST CIRCUITS

The following test circuits and conditions represent ON Semiconductor's typical test procedures. AC waveforms and terminology can be found on pages 22 to 24.

FUNCTIONAL TESTING OF TTL IN A NOISY ENVIRONMENT/"DYNAMIC" THRESHOLD

Testing noise (noise generated by the test system itself and noise generated by TTL devices under test interacting with the test system) adds to, or subtracts from the threshold voltage applied to the TTL device under test. For this reason ON Semiconductor does not recommend functional testing of TTL devices using threshold levels of 0.8 V and 2.0 V.

Instead, good TTL testing techniques call for hard levels of less than $0.5~V~V_{IL}$ and greater than $2.4~V~V_{IH}$ to be applied for functional testing. Input threshold voltages should be tested separately, and only (for noise reasons above) after setting the device state with a hard level.



The $V_{\rm IN}$ versus $V_{\rm OUT}$ plot shows the practical effect of testing noise on a logic IC device. The actual device *Trigger threshold* is represented by the initial low to high output transition. The device will oscillate if the input voltage does not exceed the trigger threshold plus the noise generated by the interaction of the test system or given application with the device.

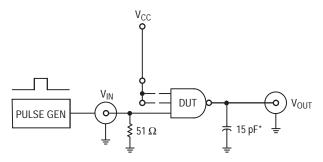
The *Dynamic threshold* (that creates Quiescent outputs), is the input logic level required to overcome the interactive DYNAMIC NOISE generated by a device switching states.

The amount of interactive DYNAMIC NOISE can be characterized by the difference between the Trigger threshold and the Dynamic threshold of the device under test. A simple number cannot be assigned to this parameter as it is heavily dependent on any given application or test environment.

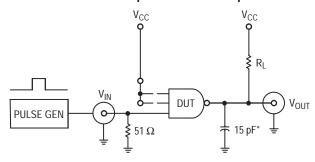
So although the Trigger threshold of any given device will correlate well between any test system, the correlation of "Dynamic" threshold cannot be made directly and will have meaning only in a relative sense.

LS TEST CIRCUITS

Test Circuit for Standard Output Devices

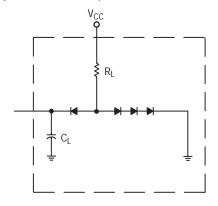


Test Circuit for Open Collector Output Devices



*includes all probe and jig capacitance

Optional LS Load (Guaranteed—Not Tested)



PULSE GENERATOR SETTINGS (UNLESS OTHERWISE SPECIFIED)

LS

Frequency = 1 MHz Duty Cycle = 50%

1 TLH $(t_r) = 6 \text{ ns } (15)^*$

1 THL $(t_f) = 6 \text{ ns } (15)^*$ Amplitude = 0 to 3 V

* The specified propagation delay limits can be guaranteed with a 15 ns input rise time on all parameters except those requiring narrow pulse widths. Any frequency measurement over 15 MHz or pulse width less than 30 ns must be performed with a 6 ns input rise time.

APPLICATIONS ASSISTANCE FORM

In the event that you have any questions or concerns about the performance of any ON Semiconductor device listed in this catalog, please contact your local ON Semiconductor sales office or the ON Semiconductor Help line for assistance. If further information is required, you can request direct factory assistance.

Please fill out as much of the form as is possible if you are contacting ON Semiconductor for assistance or are sending devices back to ON Semiconductor for analysis. Your information can greatly improve the accuracy of analysis and can dramatically improve the correlation response and resolution time.

Items 4 thru 8 of the following form contains important questions that can be invaluable in analyzing application or device problems. It can be used as a self-help diagnostic guideline or for a baseline of information gathering to begin a dialog with ON Semiconductor representatives.

-	N Semiconductor Device Correl Please fill out entire form and retur			-orm kQA Dept., 5005 E. McDowell, Phoenix, AZ 85008.			
1)	Name of Person Requesting Cor	relation:					
.,	Phone No:	Job Title:		Company:			
2)							
3)	Device Type (user part number):		_				
	Industry Generic Device Type: _						
-,	# of devices in question*:						
	# returned for correlation:						
				ON Semiconductor devices that pass inspection? code(s) if applicable			
	If none, does customer have vi	able alternate vend	lor(s) for device type				
6)	Date code(s) and Serial Number((ON Semiconductor's and/or other	s) of devices returner vendor) for comp	ed for correlation — parison:	If possible, please provide one or two "good" units			
7)	Describe USER process that dev						
	Incoming component insp	Incoming component inspection {test system = ?}:					
	Design prototyping:						
	Board test/burn-in:						
8)	Please describe the device corre	lation operating par	rameters as complet	rely as possible for device(s) in question:			
>	or output loading conditions (re information includes:	sistors, caps, clam		out not under test, whatever), including any input or devices being driven). Potentially critical			
	Input waveform timing rela Input edge rates	tionships					
	Input Overshoot or Unders Output Overshoot or Unders						
>	Photographs, plots or sketches waveforms are greatly desirable.	of relevent inputs a	and outputs with vol	tages and time divisions clearly identified for all			
>	test systems. Dynamic characteri	stics of Ground and	V _{CC} during device s	racteristics vary greatly between applications and switching can dramatically effect input and internal sically close to the device in question as possible.			
>	Are there specific circumstances	that seem to make	the questionable un	nit(s) worse? Better?			
	Temperature						
	V _{CC}						
	Input rise/fall time						
>				parameters such as V_{CC} , input voltages, Func step			

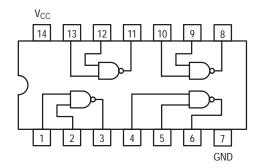
rate, voltage expected, time to measure.



CHAPTER 4 LS Data Sheets

Quad 2-Input NAND Gate

• ESD > 3500 Volts





ON Semiconductor

Formerly a Division of Motorola http://onsemi.com

> LOW POWER SCHOTTKY

GUARANTEED OPERATING RANGES

Symbol	mbol Parameter		Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	T _A Operating Ambient Temperature Range		25	70	°C
I _{OH} Output Current – High				-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



PLASTIC N SUFFIX CASE 646



SOIC D SUFFIX CASE 751A

ORDERING INFORMATION

Device	Package	Shipping
SN74LS00N	14 Pin DIP	2000 Units/Box
SN74LS00D	14 Pin	2500/Tape & Reel

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

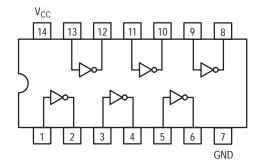
			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test C	onditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inp All Inputs	ut HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inp All Inputs	ut LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} :	= –18 mA
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V _{CC} = MIN, I _{OH} or V _{IL} per Tru	= MAX, V _{IN} = V _{IH} th Table
V	Output I OW Voltage		0.25	0.4	V		$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
I	Input HIGH Current			20	μΑ	V _{CC} = MAX, V _{IN}	_V = 2.7 V
Iн	Input nigh Current			0.1	mA	V _{CC} = MAX, V _{IN}	_J = 7.0 V
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN}	_l = 0.4 V
los	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
	Power Supply Current						
I _{CC}	Total, Output HIGH			1.6	mA	V _{CC} = MAX	
	Total, Output LOW			4.4			

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Turn-Off Delay, Input to Output		9.0	15	ns	V _{CC} = 5.0 V
t _{PHL}	Turn-On Delay, Input to Output		10	15	ns	$C_L = 15 pF$

Hex Inverter





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> LOW POWER SCHOTTKY

GUARANTEED OPERATING RANGES

Symbol	Symbol Parameter		Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	T _A Operating Ambient Temperature Range		25	70	°C
I _{OH}	I _{OH} Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



PLASTIC N SUFFIX CASE 646



SOIC D SUFFIX CASE 751A

ORDERING INFORMATION

Device	Package	Shipping
SN74LS04N	14 Pin DIP	2000 Units/Box
SN74LS04D	14 Pin	2500/Tape & Reel

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

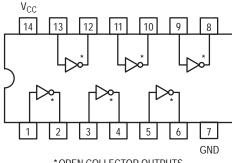
			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test C	onditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inp All Inputs	ut HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inp All Inputs	ut LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} :	= –18 mA
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V _{CC} = MIN, I _{OH} or V _{IL} per Tru	= MAX, V _{IN} = V _{IH} th Table
V	Output LOW Voltage		0.25	0.4	V		$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
I	Input HIGH Current			20	μΑ	V _{CC} = MAX, V _{IN}	↓ = 2.7 V
Iн	input nigh Curient			0.1	mA	V _{CC} = MAX, V _{IN}	_J = 7.0 V
I _{IL}	Input LOW Current			-0.4	mA	$V_{CC} = MAX$, $V_{IN} = 0.4 V$	
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
	Power Supply Current						
I _{CC}	Total, Output HIGH			2.4	mA	V _{CC} = MAX	
	Total, Output LOW			6.6			

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Turn-Off Delay, Input to Output		9.0	15	ns	V _{CC} = 5.0 V
t _{PHL}	Turn-On Delay, Input to Output		10	15	ns	C _L = 15 pF

Hex Inverter



*OPEN COLLECTOR OUTPUTS



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> LOW **POWER SCHOTTKY**

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range		25	70	°C
V _{OH}	Output Voltage – High			5.5	V
I _{OL}	Output Current – Low			8.0	mA



N SUFFIX CASE 646



SOIC **D SUFFIX CASE 751A**

ORDERING INFORMATION

Device	Package	Shipping		
SN74LS05N	14 Pin DIP	2000 Units/Box		
SN74LS05D	14 Pin	2500/Tape & Reel		

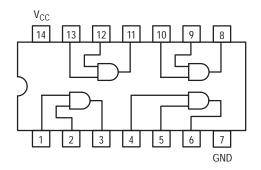
DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test C	onditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$	
I _{OH}	Output HIGH Current			100	μΑ	$V_{CC} = MIN, V_{OH} = MAX$	
V _{OL}	Output LOW Voltage		0.25	0.4	٧		$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{II} \text{ or } V_{IH}$
VOL	Odiput LOW Voltage		0.35	0.5	٧	I _{OL} = 8.0 mA	per Truth Table
l	Input HIGH Current			20	μΑ	V _{CC} = MAX, V _{IN}	1 = 2.7 V
Iн	input riiGi i Curient			0.1	mA	V _{CC} = MAX, V _{IN}	_I = 7.0 V
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN}	_I = 0.4 V
	Power Supply Current						
Icc	Total, Output HIGH			2.4	mA	$V_{CC} = MAX$	
	Total, Output LOW			6.6			

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Turn-Off Delay, Input to Output		17	32	ns	V _{CC} = 5.0 V
t _{PHL}	Turn-On Delay, Input to Output		15	28	ns	$C_L = 15 \text{ pF, } R_L = 2.0 \text{ k}\Omega$

Quad 2-Input AND Gate





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> LOW POWER SCHOTTKY

GUARANTEED OPERATING RANGES

Symbol	bol Parameter		Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	T _A Operating Ambient Temperature Range		25	70	°C
I _{OH}	I _{OH} Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



PLASTIC N SUFFIX CASE 646



SOIC D SUFFIX CASE 751A

Device	Package	Shipping		
SN74LS08N	14 Pin DIP	2000 Units/Box		
SN74LS08D	14 Pin	2500/Tape & Reel		

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test C	onditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inp All Inputs	ut HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inp All Inputs	ut LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} :	= –18 mA
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V _{CC} = MIN, I _{OH} or V _{IL} per Tru	= MAX, V _{IN} = V _{IH} th Table
V	Output I OW Voltage		0.25	0.4	V		$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	$I_{OL} = 8.0 \text{ mA}$	V _{IN} = V _{IL} or V _{IH} per Truth Table
l	Input HIGH Current			20	μА	V _{CC} = MAX, V _{IN}	_V = 2.7 V
IIH	input riiGri Gunent			0.1	mA	$V_{CC} = MAX, V_{IN}$	_V = 7.0 V
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN}	_J = 0.4 V
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
	Power Supply Current						
I _{CC}	Total, Output HIGH			4.8	mA	$V_{CC} = MAX$	
	Total, Output LOW			8.8			

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

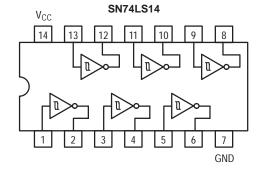
		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Turn-Off Delay, Input to Output		8.0	15	ns	V _{CC} = 5.0 V
t _{PHL}	Turn-On Delay, Input to Output		10	20	ns	$C_L = 15 pF$

Schmitt Triggers Dual Gate/Hex Inverter

The SN74LS14 contains logic gates/inverters which accept standard TTL input signals and provide standard TTL output levels. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. Additionally, they have greater noise margin than conventional inverters.

Each circuit contains a Schmitt trigger followed by a Darlington level shifter and a phase splitter driving a TTL totem pole output. The Schmitt trigger uses positive feedback to effectively speed-up slow input transitions, and provide different input threshold voltages for positive and negative-going transitions. This hysteresis between the positive-going and negative-going input thresholds (typically 800 mV) is determined internally by resistor ratios and is essentially insensitive to temperature and supply voltage variations.

LOGIC AND CONNECTION DIAGRAMS



GUARANTEED OPERATING RANGES

Symbol	mbol Parameter		Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	T _A Operating Ambient Temperature Range		25	70	°C
I _{OH}	I _{OH} Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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LOW POWER SCHOTTKY



N SUFFIX CASE 646



SOIC D SUFFIX CASE 751A

Device	Package	Shipping
SN74LS14N	14 Pin DIP	2000 Units/Box
SN74LS14D	14 Pin	2500/Tape & Reel

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
V _{T+}	Positive-Going Threshold Voltage	1.5		2.0	V	V _{CC} = 5.0 V
V _{T-}	Negative-Going Threshold Voltage	0.6		1.1	V	V _{CC} = 5.0 V
$V_{T+}-V_{T-}$	Hysteresis	0.4	0.8		V	V _{CC} = 5.0 V
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage	2.7	3.4		V	$V_{CC} = MIN$, $I_{OH} = -400 \mu A$, $V_{IN} = V_{IL}$
V	Outrot I OW Vales as		0.25	0.4	V	V_{CC} = MIN, I_{OL} = 4.0 mA, V_{IN} = 2.0 V
V _{OL}	Output LOW Voltage		0.35	0.5	V	V_{CC} = MIN, I_{OL} = 8.0 mA, V_{IN} = 2.0 V
I _{T+}	Input Current at Positive-Going Threshold		-0.14		mA	V _{CC} = 5.0 V, V _{IN} = V _{T+}
I _T _	Input Current at Negative-Going Threshold		-0.18		mA	$V_{CC} = 5.0 \text{ V}, V_{IN} = V_{T-}$
	land the Head Comment		1.0	20	μΑ	$V_{CC} = MAX, V_{IN} = 2.7 V$
l _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX, V _{OUT} = 0 V
	Power Supply Current		8.6	16		
	Total, Output HIGH					
Icc			12	21	mA	V _{CC} = MAX
	Total, Output LOW					

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

Symbol	Parameter	Max	Unit	Test Conditions
t _{PLH}	Propagation Delay, Input to Output	22	ns	V _{CC} = 5.0 V
t _{PHL}	Propagation Delay, Input to Output	22	ns	C _L = 15 pF

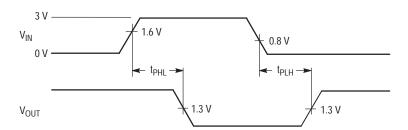


Figure 1. AC Waveforms

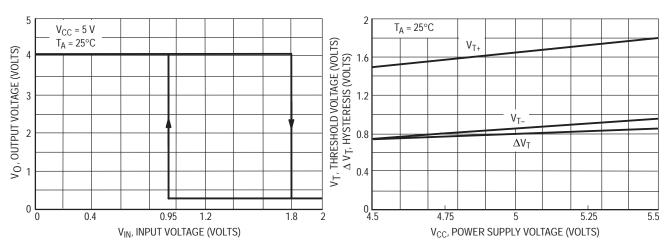


Figure 2. V_{IN} versus V_{OUT} Transfer Function

Figure 3. Threshold Voltage and Hysteresis versus Power Supply Voltage

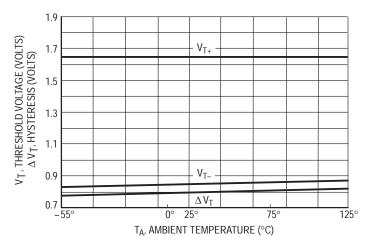
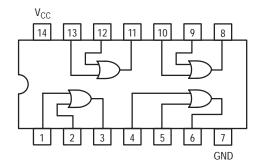


Figure 4. Threshold Voltage Hysteresis versus Temperature

Quad 2-Input OR Gate





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GUARANTEED OPERATING RANGES

Symbol	ymbol Parameter		Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	T _A Operating Ambient Temperature Range		25	70	°C
I _{OH}	I _{OH} Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



PLASTIC N SUFFIX CASE 646



SOIC D SUFFIX CASE 751A

Device	Package	Shipping	
SN74LS32N	14 Pin DIP	2000 Units/Box	
SN74LS32D	14 Pin	2500/Tape & Reel	

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

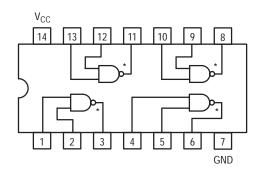
			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test C	onditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inp All Inputs	ut HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	= –18 mA
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN, I_{OH}$ or V_{IL} per Truth	= MAX, V _{IN} = V _{IH} Table
	Output I OW/Vallage		0.25	0.4	V	$I_{OL} = 4.0 \text{ mA}$	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
	Innut HCH Current			20	μΑ	V _{CC} = MAX, V _{IN}	i = 2.7 V
Iн	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN}	_I = 7.0 V
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN}	ı = 0.4 V
Ios	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
Icc	Power Supply Current Total, Output HIGH			6.2	mA	V _{CC} = MAX	
	Total, Output LOW			9.8]		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Turn-Off Delay, Input to Output		14	22	ns	V _{CC} = 5.0 V
t _{PHL}	Turn-On Delay, Input to Output		14	22	ns	C _L = 15 pF

Quad 2-Input NAND Buffer



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GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
V _{OH}	Output Voltage – High			5.5	V
I _{OL}	Output Current – Low			24	mA



PLASTIC N SUFFIX CASE 646



SOIC D SUFFIX CASE 751A

Device	Package	Shipping
SN74LS38N	14 Pin DIP	2000 Units/Box
SN74LS38D	14 Pin	2500/Tape & Reel

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input All Inputs	HIGH Voltage for	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs		
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN$, $I_{IN} = -18 \text{ mA}$		
I _{OH}	Output HIGH Current			250	μΑ	V _{CC} = MIN, V _{OH} = MAX		
V	Output LOW Voltage		0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{II} \text{ or } V_{IH}$	
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 24 mA	per Truth Table	
	Innut HCH Current			20	μΑ	V _{CC} = MAX, V _{IN} =	= 2.4 V	
Iн	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} =	= 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	$V_{CC} = MAX$, $V_{IN} = 0.4 V$		
I _{CC}	Power Supply Current Total, Output HIGH			2.0	mA	V _{CC} = MAX		
	Total, Output LOW			12				

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Turn-Off Delay, Input to Output		20	32	ns	V_{CC} = 5.0 V, R_L = 667 Ω
t _{PHL}	Turn-On Delay, Input to Output		18	28	ns	$C_L = 45 \text{ pF}$

One-of-Ten Decoder

The LSTTL/MSI SN74LS42 is a Multipurpose Decoder designed to accept four BCD inputs and provide ten mutually exclusive outputs. The LS42 is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

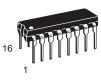
- Multifunction Capability
- Mutually Exclusive Outputs
- Demultiplexing Capability
- Input Clamp Diodes Limit High Speed Termination Effects



LOW POWER SCHOTTKY

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



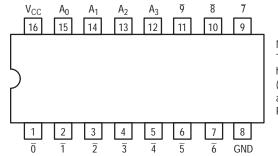
PLASTIC N SUFFIX CASE 648



D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS42N	16 Pin DIP	2000 Units/Box
SN74LS42D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



NOTE: The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

PIN NAMES

 $A_0 - A_3$ 0 to 9

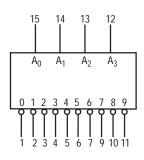
Address Inputs Outputs, Active LOW

LOADING	Note a)
HIGH	LOW
0.5 U.L. 10 U.L.	0.25 U.L. 5 U.L.

NOTES:

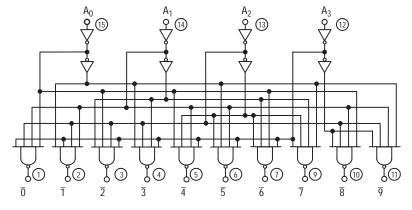
a) 1 TTL Unit Load (U.L.) = $40 \mu A HIGH/1.6 mA LOW$.

LOGIC SYMBOL



V_{CC} = PIN 16 GND = PIN 8

LOGIC DIAGRAM



 $V_{CC} = PIN 16$ GND = PIN 8

= PIN NUMBERS

FUNCTIONAL DESCRIPTION

The LS42 decoder accepts four active HIGH BCD inputs and provides ten mutually exclusive active LOW outputs, as shown by logic symbol or diagram. The active LOW outputs facilitate addressing other MSI units with LOW input enables.

The logic design of the LS42 ensures that all outputs are HIGH when binary codes greater than nine are applied to the inputs.

The most significant input A_3 produces a useful inhibit function when the LS42 is used as a one-of-eight decoder. The A_3 input can also be used as the Data input in an 8-output demultiplexer application.

TRUTH TABLE

A ₀	A ₁	A ₂	A ₃	ō	1	2	3	4	5	6	7	8	9
L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н
Н	L	L	L	Н	L	Н	Н	Н	Н	Н	Н	Н	Н
L	Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	Н
Н	Н	L	L	Н	Н	Н	L	Η	Н	Н	Н	Н	Н
L	L	Н	L	Н	Н	Н	Н	L	Н	Н	Н	Н	Н
Н	L	Н	L	Н	Н	Н	Н	Η	L	Η	Н	Η	Н
L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	Н
Н	Н	Н	L	Н	Н	Н	Н	Н	Н	Н	L	Н	Н
L	L	L	Η	Н	Н	Н	Н	Н	Н	Н	Н	L	Н
Н	L	L	Н	Н	Н	Н	Н	Η	Η	Η	Н	Η	L
L	Н	L	Н	Н	Н	Н	Н	Η	Η	Η	Н	Η	Н
Н	Н	L	Η	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
L	L	Н	Н	Н	Н	Н	Н	Η	Η	Η	Н	Η	Н
Н	L	Н	Н	Н	Н	Н	Н	Η	Η	Η	Н	Η	Н
L	Н	Н	Н	Н	Н	Н	Н	Η	Η	Η	Н	Η	Н
Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н

H = HIGH Voltage Level L = LOW Voltage Level

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

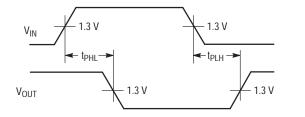
			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test C	onditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs		
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$		
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
.,	Outract LOW Valtages		0.25	0.4	V	$I_{OL} = 4.0 \text{ mA}$ $V_{CC} = V_{CC} \text{ MIN}$		
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table	
	least HIGH Correct			20	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V	
l I _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current			13	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions	
t _{PLH}	Propagation Delay (2 Levels)		15 15	25 25	ns	Figure 2	V _{CC} = 5.0 V
t _{PLH} t _{PHL}	Propagation Delay (3 Levels)		20 20	30 30	ns	Figure 1	C _L = 15 pF

AC WAVEFORMS



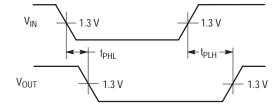


Figure 1. Figure 2.

BCD to 7-Segment Decoder/Driver

The SN74LS47 are Low Power Schottky BCD to 7-Segment Decoder/Drivers consisting of NAND gates, input buffers and seven AND-OR-INVERT gates. They offer active LOW, high sink current outputs for driving indicators directly. Seven NAND gates and one driver are connected in pairs to make BCD data and its complement available to the seven decoding AND-OR-INVERT gates. The remaining NAND gate and three input buffers provide lamp test, blanking input/ripple-blanking output and ripple-blanking input.

The circuits accept 4-bit binary-coded-decimal (BCD) and, depending on the state of the auxiliary inputs, decodes this data to drive a 7-segment display indicator. The relative positive-logic output levels, as well as conditions required at the auxiliary inputs, are shown in the truth tables. Output configurations of the SN74LS47 are designed to withstand the relatively high voltages required for 7-segment indicators.

These outputs will withstand 15 V with a maximum reverse current of 250 μ A. Indicator segments requiring up to 24 mA of current may be driven directly from the SN74LS47 high performance output transistors. Display patterns for BCD input counts above nine are unique symbols to authenticate input conditions.

The SN74LS47 incorporates automatic leading and/or trailing-edge zero-blanking control (RBI and RBO). Lamp test (LT) may be performed at any time which the BI/RBO node is a HIGH level. This device also contains an overriding blanking input (BI) which can be used to control the lamp intensity by varying the frequency and duty cycle of the BI input signal or to inhibit the outputs.

- Lamp Intensity Modulation Capability (BI/RBO)
- Open Collector Outputs
- Lamp Test Provision
- Leading/Trailing Zero Suppression
- Input Clamp Diodes Limit High-Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
ІОН	Output Current – High BI/RBO			-50	μΑ
l _{OL}	Output Current – Low BI/RBO BI/RBO			3.2	mA
V _{O(off)}	Off–State Output Voltage a to g			15	V
I _{O(on)}	On–State Output Current a to g			24	mA



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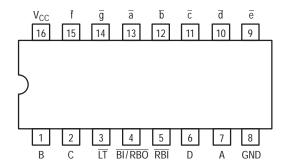
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS47N	16 Pin DIP	2000 Units/Box
SN74LS47D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



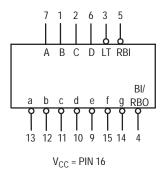
		LOADING	(Note a)
PIN NAMES		HIGH	LOW
A, B, C, D	BCD Inputs	0.5 U.L.	0.25 U.L.
RBI	Ripple-Blanking Input	0.5 U.L.	0.25 U.L.
LT	Lamp-Test Input	0.5 U.L.	0.25 U.L.
BI/RBO	Blanking Input or	0.5 U.L.	0.75 U.L.
	Ripple-Blanking Output	1.2 U.L.	2.0 U.L.
\overline{a} , to \overline{g}	Outputs	Open–Collector	15 U.L.

NOTES:

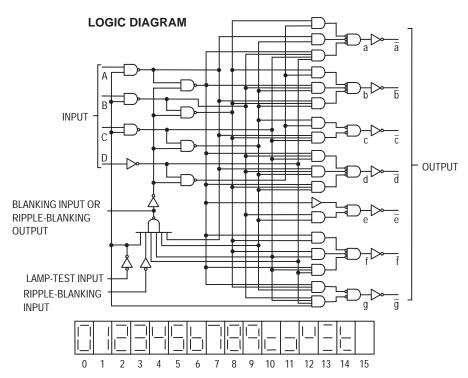
- a) 1 Unit Load (U.L.) = 40 μ A HIGH, 1.6 mA LOW.
- b) Output current measured at V_{OUT} = 0.5 V

The Output LOW drive factor is 15 U.L. for Commercial (74) Temperature Ranges.

LOGIC SYMBOL



GND = PIN 8



NUMERICAL DESIGNATIONS — RESULTANT DISPLAYS

TRUTH TABLE INPUTS OUTPUTS DECIMAL OR FUNCTION RBI D С BI/RBO NOTE g Н Α Н Н L L L Α 2 Н Χ L L Н L Н L L Н L Н L Н Х L Н Н Н L Н Н 3 L L L L Н Н Н Н L Н Н L Н L L Н Н Н 8 Н Χ Н 9 Н Χ Н Н L 10 Н L Н Н Н Х L Н Χ Н Н Н Н L 12 Н 13 Н Н Н L 14 Н Н L Н Н Н Н Н BI Χ Χ Х Х Х L Н Н Н Н Н Н Н В RRI Н Н Τ L L L L L Н Н Н Н Н Н С LT

H = HIGH Voltage Level

NOTES:

- (A) BI/RBO is wire-AND logic serving as blanking Input (BI) and/or ripple-blanking output (RBO). The blanking out (BI) must be open or held at a HIGH level when output functions 0 through 15 are desired, and ripple-blanking input (RBI) must be open or at a HIGH level if blanking of a decimal 0 is not desired. X = input may be HIGH or LOW.
- (B) When a LOW level is applied to the blanking input (forced condition) all segment outputs go to a LOW level regardless of the state of any other input condition.
- (C) When ripple-blanking input (RBI) and inputs A, B, C, and D are at LOW level, with the lamp test input at HIGH level, all segment outputs go to a HIGH level and the ripple-blanking output (RBO) goes to a LOW level (response condition).
- (D) When the blanking input/ripple-blanking output (BI/RBO) is open or held at a HIGH level, and a LOW level is applied to lamp test input, all segment outputs go to a LOW level.

L = LOW Voltage Level

X = Immaterial

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

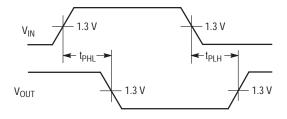
		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test	Conditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input for All Inputs	t HIGH Theshold Voltage
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input for All Inputs	t LOW Threshold Voltage
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = 0$	–18 mA
V _{OH}	Output HIGH Voltage, BI/RBO	2.4	4.2		٧	V_{CC} = MIN, I_{OH} = $-50 \mu A$, V_{IN} = V_{IN} or V_{IL} per Truth Table	
V	Output LOW Voltage		0.25	0.4	V	I _{OL} = 1.6 mA	$V_{CC} = MIN, V_{IN} = V_{IN}$
V _{OL}	BI/RBO		0.35	0.5	V	$I_{OL} = 3.2 \text{ mA}$	or V _{IL} per Truth Table
I _{O (off)}	Off-State Output Current a thru g			250	μА	$V_{CC} = MAX, V_{IN} = V_{CC}$ Table, $V_{O (off)} = 1$	= V _{IN} or V _{IL} per Truth 5 V
V	On-State Output Voltage		0.25	0.4	V	$I_{O (on)} = 12 \text{ mA}$	$V_{CC} = MAX, V_{IN} = V_{IH}$
V _{O (on)}	ā thru g		0.35	0.5	V	$I_{O (on)} = 24 \text{ mA}$	or V _{IL} per Truth Table
l	Input HIGH Current			20	μΑ	$V_{CC} = MAX, V_{IN} = V_{CC}$	= 2.7 V
IH	input riigi i Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current BI/RBO Any Input except BI/RBO			-1.2 -0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
I _{OS} BI/RBO	Output Short Circuit Current (Note 1)	-0.3		-2.0	mA	V _{CC} = MAX, V _{OUT} = 0 V	
Icc	Power Supply Current		7.0	13	mA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C)

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PHL} t _{PLH}	Propagation Delay, Address Input to Segment Output			100 100	ns ns	V _{CC} = 5.0 V
t _{PHL} t _{PLH}	Propagation Delay, RBI Input To Segment Output			100 100	ns ns	C _L = 15 pF

AC WAVEFORMS



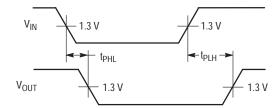


Figure 1. Figure 2.

Dual D-Type Positive Edge-Triggered Flip-Flop

The SN74LS74A dual edge-triggered flip-flop utilizes Schottky TTL circuitry to produce high speed D-type flip-flops. Each flip-flop has individual clear and set inputs, and also complementary Q and \overline{Q} outputs.

Information at input D is transferred to the Q output on the positive-going edge of the clock pulse. Clock triggering occurs at a voltage level of the clock pulse and is not directly related to the transition time of the positive-going pulse. When the clock input is at either the HIGH or the LOW level, the D input signal has no effect.



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MODE SELECT – TRUTH TABLE

OPERATING MODE		INPUTS	OUTPUTS		
OPERATING WIDDE	S _D	S _D	D	Q	Q
Set	L	Н	Х	Н	L
Reset (Clear)	Н	L	Χ	L	Н
*Undetermined	L	L	Χ	Н	Н
Load "1" (Set)	Н	Н	h	Н	L
Load "0" (Reset)	Н	Н	I	L	Н

* Both outputs will be HIGH while both \overline{S}_D and \overline{C}_D are LOW, but the output states are unpredictable if \overline{S}_D and \overline{C}_D go HIGH simultaneously. If the levels at the set and clear are near V_{IL} maximum then we cannot guarantee to meet the minimum level for V_{OH} .

H, h = HIGH Voltage Level

L, I = LOW Voltage Level

X = Don't Care

I, h (q) = Lower case letters indicate the state of the referenced input (or output) one set-up time prior to the HIGH to LOW clock transition.



PLASTIC N SUFFIX CASE 646



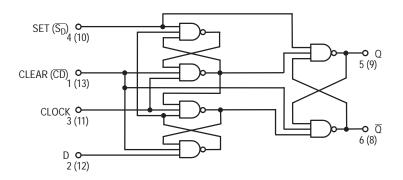
SOIC D SUFFIX CASE 751A

GUARANTEED OPERATING RANGES

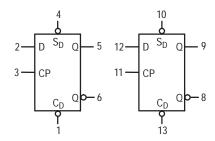
Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA

Device	Package	Shipping
SN74LS74AN	14 Pin DIP	2000 Units/Box
SN74LS74AD	14 Pin	2500/Tape & Reel

LOGIC DIAGRAM (Each Flip-Flop)



LOGIC SYMBOL



V_{CC} = PIN 14 GND = PIN 7

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Co	onditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input All Inputs	HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input All Inputs	LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -	–18 mA
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH}$ or V_{IL} per Truth Table	
.,			0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
l _{IH}	Input High Current Data, Clock Set, Clear			20 40	μΑ	$V_{CC} = MAX, V_{IN} = 2.7 V$	
""	Data, Clock Set, Clear			0.1 0.2	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
l _{IL}	Input LOW Current Data, Clock Set, Clear			-0.4 -0.8	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
I _{OS}	Output Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
I _{CC}	Power Supply Current			8.0	mA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

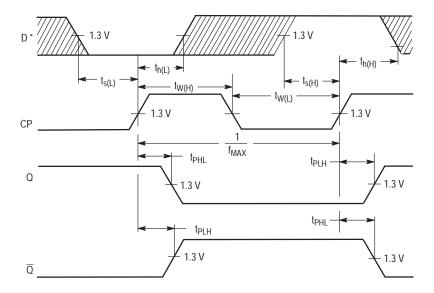
AC CHARACTERISTICS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Co	onditions
f _{MAX}	Maximum Clock Frequency	25	33		MHz	Figure 1	
t _{PLH}	Clock, Clear, Set to Output		13	25	ns	$V_{CC} = 5.0 \text{ V}$ Figure 1 $C_L = 15 \text{ pF}$	
t _{PHL}	Glock, Glear, Set to Gutput		25	40	ns	Figure i	- L

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Co	onditions
t _{W (H)}	Clock	25			ns	Figure 1	
t _{W (L)}	Clear, Set	25			ns	Figure 2	
	Data Setup Time — HIGH	20			ns	Figure 1	V _{CC} = 5.0 V
t _s	LOW	20			ns	rigule i	
t _h	Hold Time	5.0			ns	Figure 1	

AC WAVEFORMS



 $^{^{\}star}$ The shaded areas indicate when the input is permitted to change for predictable output performance.

Figure 1. Clock to Output Delays, Data Set-Up and Hold Times, Clock Pulse Width

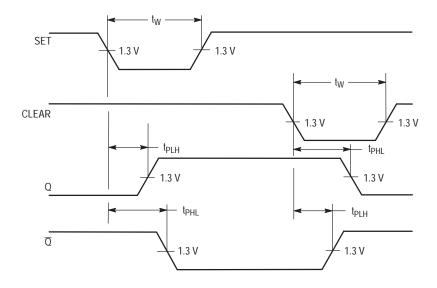


Figure 2. Set and Clear to Output Delays, Set and Clear Pulse Widths

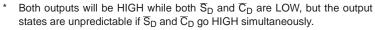
SN74LS76A

Dual JK Flip-Flop with Set and Clear

The SN74LS76A offers individual J, K, Clock Pulse, Direct Set and Direct Clear inputs. These dual flip-flops are designed so that when the clock goes HIGH, the inputs are enabled and data will be accepted. The Logic Level of the J and K inputs will perform according to the Truth Table as long as minimum set-up times are observed. Input data is transferred to the outputs on the HIGH-to-LOW clock transitions.

MODE SELECT – TRUTH TABLE

OPERATING		INP	OUTPUTS			
MODE	S _D	<u>C</u> D	J	K	Q	Q
Set Reset (Clear) *Undetermined Toggle Load "0" (Reset)	L H L H H	H	X X h	X X h	H L H q	L H H H
Load "1" (Set) Hold	H H	Η Η	h I	: — —	H q	 L q



H, h = HIGH Voltage Level

L, I = LOW Voltage Level

X = Immaterial

I, h (q) = Lower case letters indicate the state of the referenced input (or output) one setup time prior to the HIGH–to–LOW clock transition



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PLASTIC N SUFFIX CASE 648

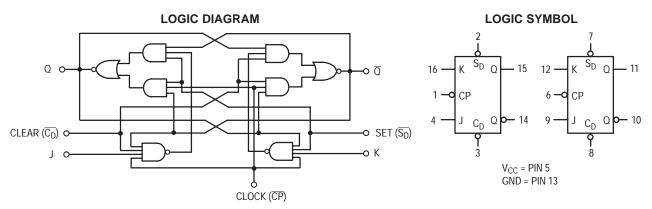


SOIC D SUFFIX CASE 751B

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA

Device	Package	Shipping		
SN74LS76AN	16 Pin DIP	2000 Units/Box		
SN74LS76AD	16 Pin	2500/Tape & Reel		



DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

				Limits				
Symbol	Parameter		Min	Тур	Max	Unit	Test Co	onditions
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Input LOW Voltage for All Inputs	
V _{IK}	Input Clamp Diode Voltage			-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA
V _{OH}	Output HIGH Voltage		2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
	Output LOW Voltage			0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}				0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
		J, K Clear Clock			20 60 80	μΑ	$V_{CC} = MAX$, $V_{IN} = 2.7 \text{ V}$ $V_{CC} = MAX$, $V_{IN} = 7.0 \text{ V}$	
IIH	Input HIGH Current	J, K Clear Clock			0.1 0.3 0.4	mA		
I _{IL}	Input LOW Current	J, K Clear, Clock			-0.4 -0.8	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
I _{OS}	Short Circuit Current (Note 1)		-20		-100	mA	V _{CC} = MAX	
I _{CC}	Power Supply Current				6.0	mA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
f _{MAX}	Maximum Clock Frequency	30	45		MHz	.,,		
t _{PLH}	Clock, Clear, Set to Output		15	20	ns	$V_{CC} = 5.0 \text{ V}$ $C_{L} = 15 \text{ pF}$		
t _{PHL}	Clock, Clear, Set to Output		15	20	ns	- '		

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
t _W	Clock Pulse Width High	20			ns			
t _W	Clear Set Pulse Width	25			ns	V 50V		
t _s	Setup Time	20			ns	$V_{CC} = 5.0 \text{ V}$		
t _h	Hold Time	0			ns			

4-Bit Magnitude Comparator

The SN74LS85 is a 4-Bit Magnitude Camparator which compares two 4-bit words (A, B), each word having four Parallel Inputs (A $_0$ -A $_3$, B $_0$ -B $_3$); A $_3$, B $_3$ being the most significant inputs. Operation is not restricted to binary codes, the device will work with any monotonic code. Three Outputs are provided: "A greater than B" (O $_A$ >B), "A less than B" (O $_A$ <B), "A equal to B" (O $_A$ =B). Three Expander Inputs, I $_A$ >B, I $_A$ <B, I $_A$ =B, allow cascading without external gates. For proper compare operation, the Expander Inputs to the least significant position must be connected as follows: I $_A$ <B I $_A$ B = L, I $_A$ =B = H. For serial (ripple) expansion, the O $_A$ >B, O $_A$ <B and O $_A$ =B Outputs are connected respectively to the I $_A$ >B, I $_A$ <B, and I $_A$ =B Inputs of the next most significant comparator, as shown in Figure 1. Refer to Applications section of data sheet for high speed method of comparing large words.

The Truth Table on the following page describes the operation of the SN74LS85 under all possible logic conditions. The upper 11 lines describe the normal operation under all conditions that will occur in a single device or in a series expansion scheme. The lower five lines describe the operation under abnormal conditions on the cascading inputs. These conditions occur when the parallel expansion technique is used.

- Easily Expandable
- Binary or BCD Comparison
- $O_{A>B}$, $O_{A<B}$, and $O_{A=B}$ Outputs Available

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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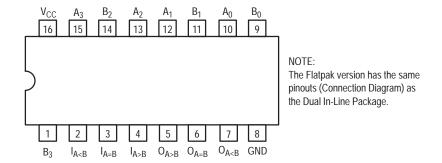
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS85N	16 Pin DIP	2000 Units/Box
SN74LS85D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)

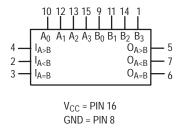


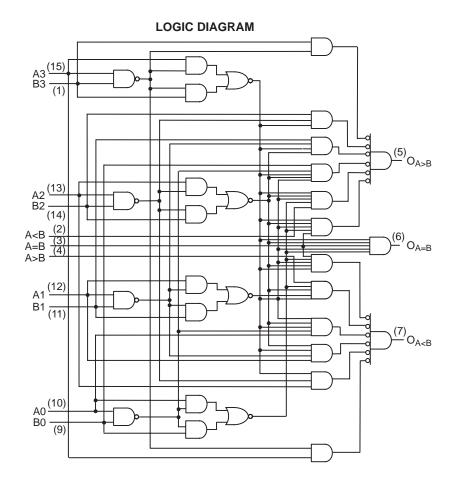
	_	LOADING (Note a)			
PIN NAMES		HIGH	LOW		
$A_0 - A_3$, $B_0 - B_3$ $I_{A = B}$	Parallel Inputs A = B Expander Inputs	1.5 U.L. 1.5 U.L.	0.75 U.L. 0.75 U.L.		
$I_{A < B'} I_{A > B}$	A < B, A > B, Expander Inputs	0.5 U.L.	0.25 U.L.		
$O_{A > B}$	A Greater than B Output	10 U.L.	5 U.L.		
$O_{A < B}$	B Greater than A Output	10 U.L.	5 U.L.		
$O_A = B$	A Equal to B Output	10 U.L.	5 U.L.		

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL





TRUTH TABLE

	III IABEL									
COMPARING INPUTS			_	SCADII INPUTS		OUTPUTS				
A ₃ ,B ₃	A_2,B_2	A ₁ ,B ₁	A_0,B_0	I _{A>B}	I _{A<b< sub=""></b<>}	I _{A=B}	O _{A>B}	O _{A<b< sub=""></b<>}	O _{A=B}	
A ₃ >B ₃	Χ	Х	Χ	Х	Х	Χ	Н	L	L	
A ₃ <b<sub>3</b<sub>	Χ	X	Χ	Х	Χ	X	L	Н	L	
$A_3=B_3$	$A_2>B_2$	Χ	X	Х	Χ	Χ	Н	L	L	
A ₃ =B ₃	$A_2 < B_2$	X	Χ	Х	Χ	X	L	Н	L	
A ₃ =B ₃	$A_2=B_2$	$A_1>B_1$	Χ	Х	Χ	X	Н	L	L	
A ₃ =B ₃	$A_2=B_2$	$A_1 < B_1$	Χ	Х	X	X	L	Н	L	
$A_3=B_3$	$A_2=B_2$	A ₁ =B1	$A_0 > B_0$	Х	X	X	Н	L	L	
$A_3=B_3$	$A_2=B_2$	$A_1=B_1$	$A_0 < B_0$	Х	X	X	L	Н	L	
$A_3=B_3$	$A_2=B_2$	$A_1=B_1$	$A_0=B_0$	Н	L	L	Н	L	L	
A ₃ =B ₃	$A_2=B_2$	$A_1=B_1$	$A_0=B_0$	L	Н	L	L	Н	L	
A ₃ =B ₃	$A_2=B_2$	$A_1=B_1$	$A_0=B_0$	Х	Χ	Н	L	L	Н	
A ₃ =B ₃	$A_2=B_2$	$A_1=B_1$	$A_0=B_0$	Н	Н	L	L	L	L	
$A_3=B_3$	$A_2=B_2$	$A_1=B_1$	$A_0=B_0$	L	L	L	Н	Н	L	

H = HIGH Level L = LOW Level X = IMMATERIAL

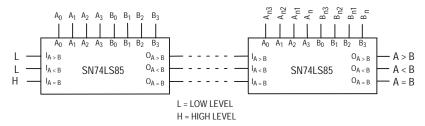


Figure 1. Comparing Two n-Bit Words

APPLICATIONS

Figure 2 shows a high speed method of comparing two 24-bit words with only two levels of device delay. With the technique shown in Figure 1, six levels of device delay result

when comparing two 24-bit words. The parallel technique can be expanded to any number of bits, see Table 1.

Table 1

WORD LENGTH	NUMBER OF PKGS.
1-4 Bits	1
5-24 Bits	2-6
25-120 Bits	8-31

NOTE:

The SN74LS85 can be used as a 5-bit comparator only when the outputs are used to drive the A_0 – A_3 and B_0 – B_3 inputs of another SN74LS85 as shown in Figure 2 in positions #1, 2, 3, and 4.

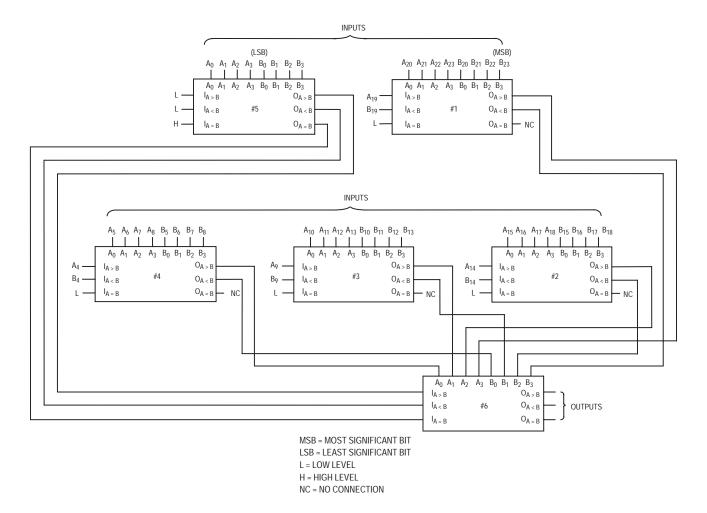


Figure 2. Comparison of Two 24-Bit Words

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input All Inputs	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN$, $I_{OH} = MAX$, $V_{IN} = V_{IH}$ or V_{IL} per Truth Table		
.,	0		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V _{OL}	Output LOW Voltage		0.35	0.5	٧	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table	
l _{IH}	Input HIGH Current A < B, A > B Other Inputs			20 60	μΑ	V _{CC} = MAX, V _{IN} :	= 2.7 V	
•••	A < B, A > B Other Inputs			0.1 0.3	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current A < B, A > B Other Inputs			-0.4 -1.2	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Output Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current			20	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25° C, V_{CC} = 5.0 V)

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Any A or B to A < B, A > B		24 20	36 30	ns	
t _{PLH} t _{PHL}	Any A or B to A = B		27 23	45 45	ns	
t _{PLH} t _{PHL}	A < B or A = B to A > B		14 11	22 17	ns	$V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$
t _{PLH} t _{PHL}	A = B to $A = B$		13 13	20 26	ns	
t _{PLH} t _{PHL}	A > B or A = B to A < B		14 11	22 17	ns	

AC WAVEFORMS

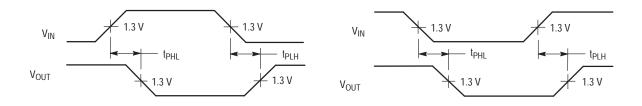
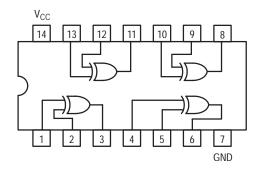


Figure 3. Figure 4.

Quad 2-Input Exclusive OR Gate



TRUTH TABLE

ll.	IN			
Α	В	Z		
L	L	L		
L	Н	Н		
Н	L	Н		
Н	Н	L		



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> LOW POWER SCHOTTKY



PLASTIC N SUFFIX CASE 646

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



SOIC D SUFFIX CASE 751A

Device	Package	Shipping
SN74LS86N	14 Pin DIP	2000 Units/Box
SN74LS86D	14 Pin	2500/Tape & Reel

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Co	onditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input All Inputs	HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input All Inputs	LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
V	Output I OW/Veltage		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table
	January I II Cl I Comment			40	μΑ	V _{CC} = MAX, V _{IN} =	2.7 V
Iн	Input HIGH Current			0.2	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current			-0.8	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
Ios	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
Icc	Power Supply Current			10	mA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay, Other Input LOW		12 10	23 17	ns	V _{CC} = 5.0 V C _L = 15 pF
t _{PLH}	Propagation Delay, Other Input HIGH		20 13	30 22	ns	C _L = 15 pF

SN74LS109A

Dual JK Positive Edge-Triggered Flip-Flop

The SN74LS109A consists of two high speed completely independent transition clocked $J\overline{K}$ flip-flops. The clocking operation is independent of rise and fall times of the clock waveform. The $J\overline{K}$ design allows operation as a D flip-flop by simply connecting the J and \overline{K} pins together.

MODE SELECT – TRUTH TABLE

OPERATING MODE		INP	OUTPUTS			
OPERATING MODE	S _D	<u>C</u> D	J	K	Q	Q
Set	L	Н	Х	Х	Н	L
Reset (Clear)	Н	L	Х	Х	L	н
*Undetermined	L	L	Х	Х	Н	Н
Load "1" (Set)	Н	Н	h	h	Н	L
Hold	Н	Н	1	h	q	q
Toggle	Н	Н	h	- 1	q	q
Load "0" (Reset)	Н	Н	ı	ı	L	Н

^{*} Both outputs will be HIGH while both \overline{S}_D and \overline{C}_D are LOW, but the output states are unpredictable if \overline{S}_D and \overline{C}_D go HIGH simultaneously.

H, h = HIGH Voltage Level

L, I = LOW Voltage Level

X = Don't Care

I, h (q) = Lower case letters indicate the state of the referenced input (or output) one set-up time prior to the LOW to HIGH clock transition.

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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PLASTIC N SUFFIX CASE 648

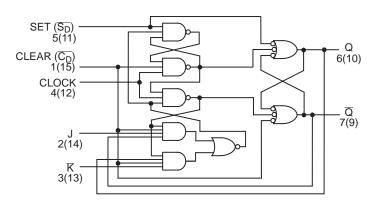


SOIC D SUFFIX CASE 751B

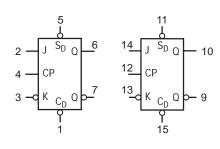
Device	Package	Shipping
SN74LS109AN	16 Pin DIP	2000 Units/Box
SN74LS109AD	16 Pin	2500/Tape & Reel

SN74LS109A

LOGIC DIAGRAM



LOGIC SYMBOL



V_{CC} = PIN 16 GND = PIN 8

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input All Inputs	t HIGH Voltage for	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input All Inputs	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH}$ or V_{IL} per Truth Table		
V	Output I OW Valence		0.25	0.4	٧	$I_{OL} = 4.0 \text{ mA}$ $V_{CC} = V_{CC} \text{ MIN},$		
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table	
I _{IH}	Input HIGH Current J, K, Clock Set, Clear			20 40	μА	$V_{CC} = MAX$, $V_{IN} = 2.7 V$		
	J, K, Clock Set, Clear			0.1 0.2	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current J, K, Clock Set, Clear			-0.4 -0.8	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Output Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current			8.0	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

SN74LS109A

AC CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)

		Limits		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
f _{MAX}	Maximum Clock Frequency	25	33		MHz			
t _{PLH}	Clock, Clear, Set to Output		13	25	ns	$V_{CC} = 5.0 \text{ V}$ $C_1 = 15 \text{ pF}$		
t _{PHL}	Clock, Clear, Set to Output		25	40	ns	of sob.		

AC SETUP REQUIREMENTS (T_A = 25°C, V_{CC} = 5.0 V)

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
t _W	Clock High Clear, Set Pulse Width	25			ns			
	Data Setup Time — HIGH	20			ns	V50V		
ı _s	LOW	20			ns	V _{CC} = 5.0 V		
t _h	Hold time	5.0			ns			

SN74LS122 SN74LS123

Retriggerable Monostable Multivibrators

These dc triggered multivibrators feature pulse width control by three methods. The basic pulse width is programmed by selection of external resistance and capacitance values. The LS122 has an internal timing resistor that allows the circuits to be used with only an external capacitor. Once triggered, the basic pulse width may be extended by retriggering the gated low-level-active (A) or high-level-active (B) inputs, or be reduced by use of the overriding clear.

- Overriding Clear Terminates Output Pulse
- Compensated for V_{CC} and Temperature Variations
- DC Triggered from Active-High or Active-Low Gated Logic Inputs
- Retriggerable for Very Long Output Pulses, up to 100% Duty Cycle
- Internal Timing Resistors on LS122

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA
R _{ext}	External Timing Resistance	5.0		260	kΩ
C _{ext}	External Capacitance	No Restriction			
R _{ext} /C _{ext}	Wiring Capacitance at R _{ext} /C _{ext} Terminal			50	pF



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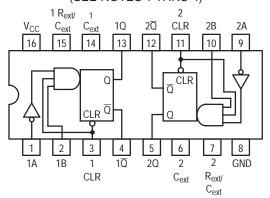




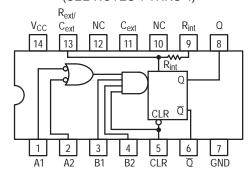
Device	Package	Shipping
SN74LS122N	14 Pin DIP	2000 Units/Box
SN74LS122D	14 Pin	2500/Tape & Reel
SN74LS123N	16 Pin DIP	2000 Units/Box
SN74LS123D	16 Pin	2500/Tape & Reel

SN74LS122 SN74LS123

SN74LS123 (TOP VIEW) (SEE NOTES 1 THRU 4)



SN74LS122 (TOP VIEW) (SEE NOTES 1 THRU 4)



NC — NO INTERNAL CONNECTION.

NOTES:

- 1. An external timing capacitor may be connected between C_{ext} and R_{ext} (positive).
- 2. To use the internal timing resistor of the LS122, connect R_{int} to $V_{\text{CC}}.$
- 3. For improved pulse width accuracy connect an external resistor between R_{ext}/C_{ext} and V_{CC} with R_{int} open-circuited. 4. To obtain variable pulse widths, connect an external variable resistance between R_{int}/C_{ext} and V_{CC} .

LS122 FUNCTIONAL TABLE

	INPUTS								
CLEAR	A1	A2	B1	B2	Q	Q			
L	Х	Х	Χ	Х	L	Н			
X	Н	Н	Χ	Χ	L	Н			
X	Х	Χ	L	Χ	L	Н			
X	Х	Χ	Χ	L	L	Н			
Н	L	Χ	\uparrow	Н	л	ъ			
Н	L	X	Н	\uparrow	л	ъ			
Н	Х	L	\uparrow	Н		ъ			
Н	Х	L	Н	\uparrow	1	T			
Н	Н	\downarrow	Н	Н	л	T			
Н	\downarrow	\downarrow	Н	Н	л	ъ			
Н	\downarrow	Н	Н	Н	л	T			
1	L	X	Н	Н	л	ъ			
1	Х	L	Н	Н	Л	ъ			

TYPICAL APPLICATION DATA

The output pulse t_W is a function of the external components, C_{ext} and R_{ext} or C_{ext} and R_{int} on the LS122. For values of $C_{ext} \ge 1000$ pF, the output pulse at $V_{CC} = 5.0$ V and $V_{RC} = 5.0$ V (see Figures 1, 2, and 3) is given by

$$t_W = K R_{ext} C_{ext}$$
 where K is nominally 0.45

If C_{ext} is on pF and R_{ext} is in $k\Omega$ then t_W is in nanoseconds. The C_{ext} terminal of the LS122 and LS123 is an internal connection to ground, however for the best system performance C_{ext} should be hard-wired to ground.

Care should be taken to keep R_{ext} and C_{ext} as close to the monostable as possible with a minimum amount of inductance between the R_{ext}/C_{ext} junction and the R_{ext}/C_{ext} pin. Good groundplane and adequate bypassing should be designed into the system for optimum performance to ensure that no false triggering occurs.

It should be noted that the C_{ext} pin is internally connected to ground on the LS122 and LS123, but not on the LS221. Therefore, if C_{ext} is hard-wired externally to ground, substitution of a LS221 onto a LS123 socket will cause the LS221 to become non-functional.

The switching diode is not needed for electrolytic capacitance application and should not be used on the LS122 and LS123.

To find the value of K for $C_{ext} \ge 1000$ pF, refer to Figure 4. Variations on V_{CC} or V_{RC} can cause the value of K to change, as can the temperature of the LS123, LS122.

LS123 FUNCTIONAL TABLE

INPUTS			OUTPUTS	
CLEAR	Α	В	Q	Q
L	Х	Х	L	Н
X	Н	Χ	L	Н
X	Х	L	L	Н
Н	L	\uparrow	л	ъ
Н	\downarrow	Н	л	ъ
<u> </u>	L	Н	л	ъ

Figures 5 and 6 show the behavior of the circuit shown in Figures 1 and 2 if separate power supplies are used for V_{CC} and V_{RC} . If V_{CC} is tied to V_{RC} , Figure 7 shows how K will vary with V_{CC} and temperature. Remember, the changes in R_{ext} and C_{ext} with temperature are not calculated and included in the graph.

As long as $C_{ext} \ge 1000$ pF and $5K \le R_{ext} \le 260K$, the change in K with respect to R_{ext} is negligible.

If $C_{ext} \le 1000 \, pF$ the graph shown on Figure 8 can be used to determine the output pulse width. Figure 9 shows how K will change for $C_{ext} \le 1000 \, pF$ if V_{CC} and V_{RC} are connected to the same power supply. The pulse width t_W in nanoseconds is approximated by

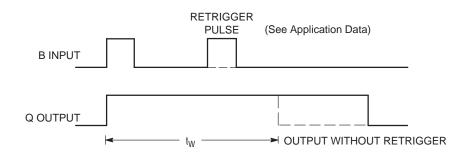
$$t_W = 6 + 0.05 C_{ext} (pF) + 0.45 R_{ext} (k\Omega) C_{ext} + 11.6 R_{ext}$$

In order to trim the output pulse width, it is necessary to include a variable resistor between V_{CC} and the R_{ext}/C_{ext} pin or between V_{CC} and the R_{ext} pin of the LS122. Figure 10, 11, and 12 show how this can be done. R_{ext} remote should be kept as close to the monostable as possible.

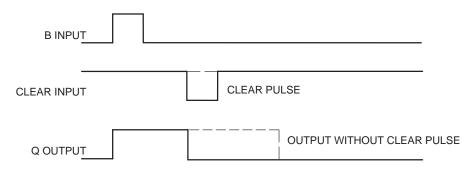
Retriggering of the part, as shown in Figure 3, must not occur before C_{ext} is discharged or the retrigger pulse will not have any effect. The discharge time of C_{ext} in nanoseconds is guaranteed to be less than 0.22 C_{ext} (pF) and is typically 0.05 C_{ext} (pF).

For the smallest possible deviation in output pulse widths from various devices, it is suggested that C_{ext} be kept $\geq 1000 \ pF$.

WAVEFORMS



EXTENDING PULSE WIDTH



OVERRIDING THE OUTPUT PULSE

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

				Limits				
Symbol	Parameter		Min	Тур	Max	Unit	Test C	onditions
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Inp All Inputs	ut LOW Voltage for
V _{IK}	Input Clamp Diode Voltage			-0.65	-1.5	V	V _{CC} = MIN, I _{IN} :	= –18 mA
V _{OH}	Output HIGH Voltage		2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
	a			0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$
V _{OL}	Output LOW Voltage			0.35	0.5	V	$I_{OL} = 8.0 \text{ mA}$	per Truth Table
	lament I II Cl. I. Commant				20	μΑ	V _{CC} = MAX, V _{IN}	i = 2.7 V
I _{IH}	Input HIGH Current				0.1	mA	$V_{CC} = MAX, V_{IN} = 7.0 V$	
I _{IL}	Input LOW Current				-0.4	mA	$V_{CC} = MAX$, $V_{IN} = 0.4 V$	
Ios	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
l	Power Supply Current	LS122			11	mA	LV MANY	
Icc	Power Supply Current				20	IIIA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)

		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions	
t _{PLH}	Propagation Delay, A to Q		23	33	20		
t _{PHL}	Propagation Delay, A to $\overline{\mathbb{Q}}$		32	45	ns	$C_{\text{ext}} = 0$	
t _{PLH}	Propagation Delay, B to Q		23	44		$C_{\text{ext}} = 0$ $C_{\text{L}} = 15 \text{ pF}$	
t _{PHL}	Propagation Delay, B to $\overline{\mathbb{Q}}$		34	56	ns	$R_{\text{ext}} = 5.0 \text{ k}\Omega$	
t _{PLH}	Propagation Delay, Clear to Q		28	45	20	$R_L = 2.0 \text{ k}\Omega$	
t _{PHL}	Propagation Delay, Clear to Q		20	27	ns		
t _{W min}	A or B to Q		116	200	ns	$C_{\text{ext}} = 1000 \text{ pF}, R_{\text{ext}} = 10 \text{ k}\Omega,$	
t _W Q	A to B to Q	4.0	4.5	5.0	μs	$C_L = 15 \text{ pF}, R_L = 2.0 \text{ k}\Omega$	

AC SETUP REQUIREMENTS (TA = 25° C, V_{CC} = 5.0 V)

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	Pulse Width	40			ns	

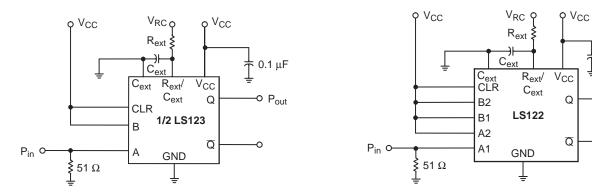


Figure 1.

Figure 2.

 $0.1~\mu F$

-O P_{out}

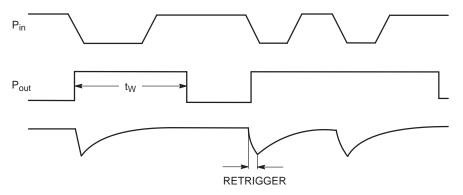


Figure 3.

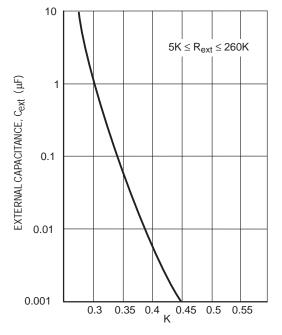
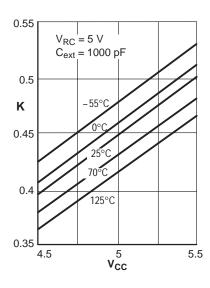
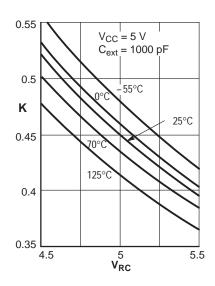


Figure 4.





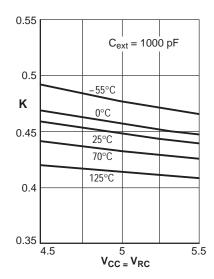


Figure 5. K versus V_{CC}

Figure 6. K versus V_{RC}

Figure 7. K versus V_{CC} and V_{RC}

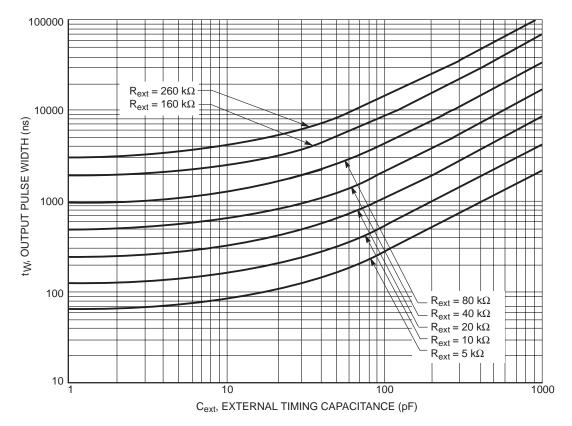


Figure 8.

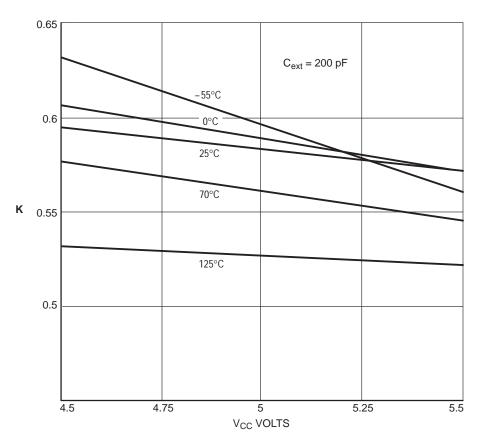


Figure 9.

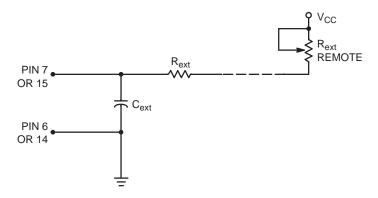


Figure 10. LS123 Remote Trimming Circuit

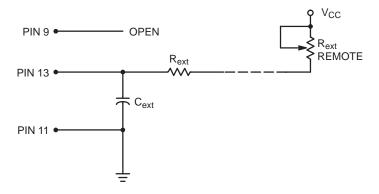


Figure 11. LS122 Remote Trimming Circuit Without Rext

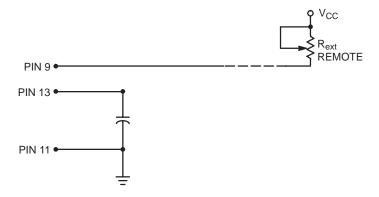
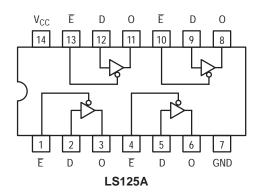
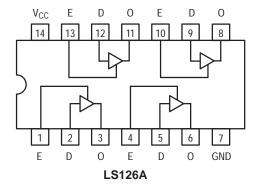


Figure 12. LS122 Remote Trimming Circuit with R_{int}

SN74LS125A SN74LS126A

Quad 3-State Buffers





TRUTH TABLES

LS125A

UTS	
D	OUTPUT
L	L
Н	Н
Х	(Z)
	D L H

LS126A

INP	UTS	
Е	D	OUTPUT
Н	L	L
Н	Н	Н
L	Χ	(Z)

L = LOW Voltage Level H = HIGH Voltage Level X = Don't Care

(Z) = High Impedance (off)

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-2.6	mA
I _{OL}	Output Current – Low			24	mA



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N SUFFIX CASE 646



SOIC **D SUFFIX CASE 751A**

Device	Package	Shipping
SN74LS125AN	14 Pin DIP	2000 Units/Box
SN74LS125AD	14 Pin	2500/Tape & Reel
SN74LS126AN	14 Pin DIP	2000 Units/Box
SN74LS126AD	14 Pin	2500/Tape & Reel

SN74LS125A SN74LS126A

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

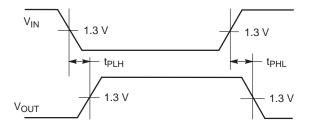
			Limits					
Symbol	Parameter		Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Ir All Inputs	nput HIGH Voltage for
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Ir All Inputs	nput LOW Voltage for
V _{IK}	Input Clamp Diode Voltage			-0.65	-1.5	V	V _{CC} = MIN, I _{II}	_N = -18 mA
V _{OH}	Output HIGH Voltage		2.4			V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
.,	0			0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage			0.35	0.5	V	I _{OL} = 24 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
I _{OZH}	Output Off Current HIGH				20	μΑ	V _{CC} = MAX, V	/ _{OUT} = 2.4 V
I _{OZL}	Output Off Current LOW				-20	μΑ	V _{CC} = MAX, \	/ _{OUT} = 0.4 V
	Innut IIICI I Current				20	μΑ	V _{CC} = MAX, \	/ _{IN} = 2.7 V
t _{IH}	Input HIGH Current				0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current				-0.4	mA	$V_{CC} = MAX, V_{IN} = 0.4 V$	
Ios	Short Circuit Current (Note	1)	-40		-225	mA	V _{CC} = MAX	
,	Dower Supply Current	LS125A	·		20	mA	\/ _ MA\	$V_{IN} = 0 \text{ V}, V_{E} = 4.5 \text{ V}$
Icc	Power Supply Current	LS126A			22	IIIA	V _{CC} = MAX	V _{IN} = 0 V, V _E = 0 V

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits						
Symbol	Parameter		Min	Тур	Max	Unit	Tes	st Conditions	
t _{PLH}		LS125A		9.0	15				
t _{PLH}	Propagation Delay,	LS126A		9.0	15		Figure 0		
t _{PHL}	Data to Output	LS125A		7.0	18	ns	Figure 2	V_{CC} = 5.0 V C_L = 45 pF R_L = 667 Ω	
t _{PHL}		LS126A		8.0	18				
	Output Enable Time	LS125A		12	20		Figures 4, 5		
t _{PZH}	to HIGH Level	LS126A		16	25	ns			
	Output Enable Time	LS125A		15	25		Fig		
t _{PZL}	to LOW Level	LS126A		21	35	ns	Figures 3, 5		
	Output Disable Time	LS125A			20		Figure 4 5		
t _{PHZ}	from HIGH Level	LS126A			25	ns	Figures 4, 5	V_{CC} = 5.0 V C_L = 5.0 pF R_L = 667 Ω	
	Output Disable Time	LS125A			20				
t _{PLZ}	from LOW Level	LS126A			25	ns	Figures 3, 5		

SN74LS125A SN74LS126A



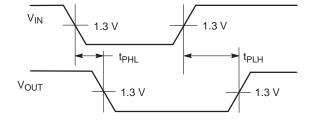


Figure 1.

Figure 2.

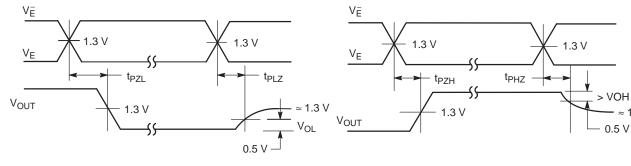


Figure 3.

Figure 4.

≈ 1.3 V

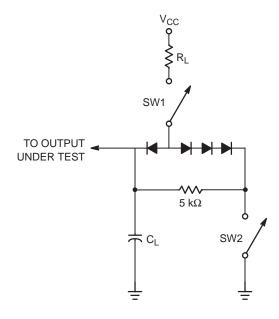


Figure 5.

SWITCH POSITIONS

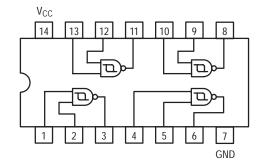
SYMBOL	SW1	SW2
t _{PZH}	Open	Closed
t _{PZL}	Closed	Open
t _{PLZ}	Closed	Closed
t _{PHZ}	Closed	Closed

Quad 2-Input Schmitt Trigger NAND Gate

The SN74LS132 contains four 2-Input NAND Gates which accept standard TTL input signals and provide standard TTL output levels. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. Additionally, they have greater noise margin than conventional NAND Gates.

Each circuit contains a 2-input Schmitt trigger followed by a Darlington level shifter and a phase splitter driving a TTL totem pole output. The Schmitt trigger uses positive feedback to effectively speed-up slow input transitions, and provide different input threshold voltages for positive and negative-going transitions. This hysteresis between the positive-going and negative-going input thresholds (typically 800 mV) is determined internally by resistor ratios and is essentially insensitive to temperature and supply voltage variations. As long as one input remains at a more positive voltage than V_{T+} (MAX), the gate will respond to the transitions of the other input as shown in Figure 1.

LOGIC AND CONNECTION DIAGRAM **DIP (TOP VIEW)**



GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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N SUFFIX CASE 646



SOIC **D SUFFIX CASE 751A**

Device	Package	Shipping		
SN74LS132N	14 Pin DIP	2000 Units/Box		
SN74LS132D	14 Pin	2500/Tape & Reel		

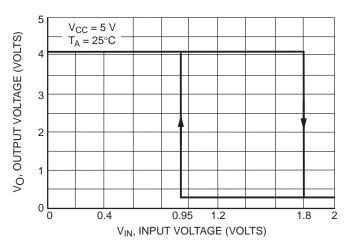


Figure 1. V_{IN} versus V_{OUT} Transfer Function

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
V _{T+}	Positive-Going Threshold Voltage	1.5		2.0	V	V _{CC} = 5.0 V
V_{T-}	Negative-Going Threshold Voltage	0.6		1.1	V	V _{CC} = 5.0 V
$V_{T+} - V_{T-}$	Hysteresis	0.4	0.8		V	V _{CC} = 5.0 V
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN$, $I_{IN} = -18 \text{ mA}$
V _{OH}	Output HIGH Voltage	2.7	3.4		V	$V_{CC} = MIN$, $I_{OH} = -400 \mu A$, $V_{IN} = V_{IL}$
M	Output I OW Voltage		0.25	0.4	V	V_{CC} = MIN, I_{OL} = 4.0 mA, V_{IN} = 2.0 V
V_{OL}	OL Output LOW Voltage		0.35	0.5	V	$V_{CC} = MIN, I_{OL} = 8.0 \text{ mA}, V_{IN} = 2.0 \text{ V}$
I _{T+}	Input Current at Positive-Going Threshold		-0.14		mA	V _{CC} = 5.0 V, V _{IN} = V _{T+}
I _T	Input Current at Negative-Going Threshold		-0.18		mA	V _{CC} = 5.0 V, V _{IN} = V _T
	Learned HOLL Owners			20	μΑ	$V_{CC} = MAX, V_{IN} = 2.7 V$
I _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V
I _{IL}	Input LOW Current			-0.4	mA	$V_{CC} = MAX, V_{IN} = 0.4 V$
I _{OS}	Output Short Circuit Current (1)	-20		-100	mA	V _{CC} = MAX, V _{OUT} = 0 V
Icc	Power Supply Current Total, Output HIGH		5.9	11	mA	V _{CC} = MAX, V _{IN} = 0 V
	Total, Output LOW		8.2	14	mA	$V_{CC} = MAX, V_{IN} = 4.5 V$

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Turn-Off Delay, Input to Output			22	ns	V _{CC} = 5.0 V
t _{PHL}	Turn-On Delay, Input to Output		·	22	ns	C _L = 15 pF

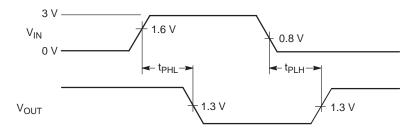


Figure 2. AC Waveforms

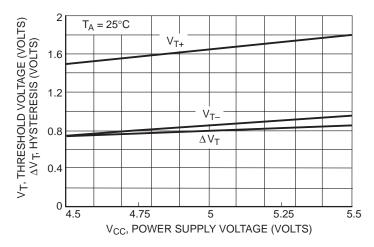


Figure 3. Threshold Voltage and Hysteresis versus Power Supply Voltage

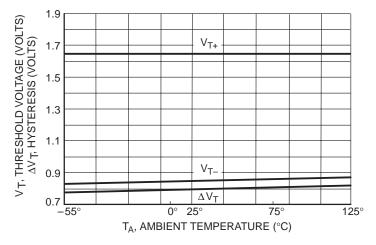


Figure 4. Threshold Voltage and Hysteresis versus Temperature

1-of-8 Decoder/ Demultiplexer

The LSTTL/MSI SN74LS138 is a high speed 1-of-8 Decoder/Demultiplexer. This device is ideally suited for high speed bipolar memory chip select address decoding. The multiple input enables allow parallel expansion to a 1-of-24 decoder using just three LS138 devices or to a 1-of-32 decoder using four LS138s and one inverter. The LS138 is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Demultiplexing Capability
- Multiple Input Enable for Easy Expansion
- Typical Power Dissipation of 32 mW
- Active Low Mutually Exclusive Outputs
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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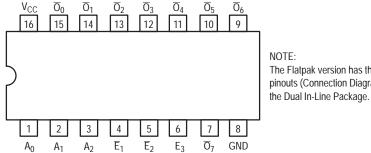
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS138N	16 Pin DIP	2000 Units/Box
SN74LS138D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



NOTE: The Flatpak version has the same pinouts (Connection Diagram) as

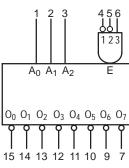
		LOADING	(Note a)
PIN NAMES		HIGH	LOW
$\underline{A}_0 - \underline{A}_2$	Address Inputs	0.5 U.L.	0.25 U.L.

 \overline{E}_1 , \overline{E}_2 Enable (Active LOW) Inputs 0.5 U.L. 0.25 U.L. Enable (Active HIGH) Input E_3 0.5 U.L. 0.25 U.L. $\overline{O}_0 - \overline{O}_7$ Active LOW Outputs 10 U.L. 5 U.L.

NOTES:

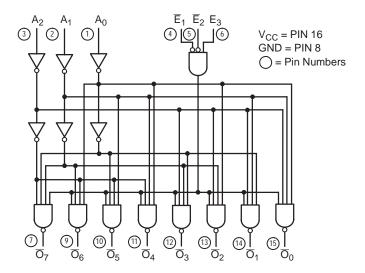
a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



V_{CC} = PIN 16 GND = PIN 8

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS138 is a high speed 1-of-8 Decoder/Demultiplexer fabricated with the low power Schottky barrier diode process. The decoder accepts three binary weighted inputs (A_0, A_1, A_2) and when enabled provides eight mutually exclusive active LOW Outputs $(\overline{O}_0 - \overline{O}_7)$. The LS138 features three Enable inputs, two active LOW $(\overline{E}_1, \overline{E}_2)$ and one active HIGH (E_3) . All outputs will be HIGH unless \overline{E}_1 and \overline{E}_2 are LOW and E_3 is HIGH. This multiple enable

function allows easy parallel expansion of the device to a 1-of-32 (5 lines to 32 lines) decoder with just four LS138s and one inverter. (See Figure a.)

The LS138 can be used as an 8-output demultiplexer by using one of the active LOW Enable inputs as the data input and the other Enable inputs as strobes. The Enable inputs which are not used must be permanently tied to their appropriate active HIGH or active LOW state.

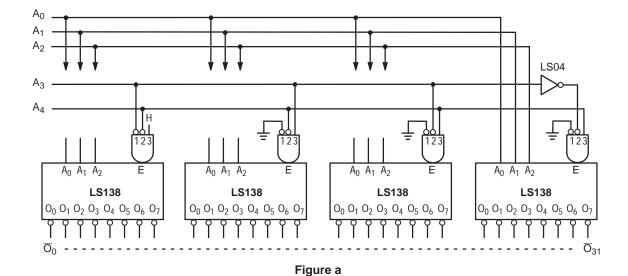
TRUTH TABLE

		INP	UTS						OU ⁻	TPUTS			
E ₁	E ₂	E ₃	A ₀	A ₁	A ₂	Ō ₀	<u>0</u> 1	\overline{O}_2	\overline{O}_3	\overline{O}_{4}	\overline{O}_5	0 6	0 ₇
Н	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н
Х	Н	Χ	Х	X	Χ	Н	Н	Н	Н	Н	Н	Н	н
Х	Χ	L	Х	X	Χ	Н	Н	Н	Н	Н	Н	Н	н
L	L	Н	L	L	L	L	Н	Н	Н	Н	Н	Н	Н
L	L	Н	Н	L	L	Н	L	Н	Н	Н	Н	Н	н
L	L	Н	L	Н	L	Н	Н	L	Н	Н	Н	Н	н
L	L	Н	Н	Н	L	Н	Н	Н	L	Н	Н	Н	н
L	L	Н	L	L	Н	Н	Н	Н	Н	L	Н	Н	н
L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	н
L	L	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	L	н
L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care



DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs		
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN$, $I_{OH} = MAX$, $V_{IN} = V_{IH}$ or V_{IL} per Truth Table		
N/	Outrot I OWA Valtage		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$	
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	per Truth Table	
	lanut HCH Current			20	μΑ	V _{CC} = MAX, V _{IN} :	= 2.7 V	
I _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
Ios	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
Icc	Power Supply Current			10	mA	V _{CC} = MAX	_	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Levels of	Limits				
Symbol	Parameter	Delay	Min Typ Max		Unit	Test Conditions	
t _{PLH} t _{PHL}	Propagation Delay Address to Output	2 2		13 27	20 41	ns	
t _{PLH} t _{PHL}	Propagation Delay Address to Output	3 3		18 26	27 39	ns	V _{CC} = 5.0 V C _L = 15 pF
t _{PLH} t _{PHL}	Propagation Delay \overline{E}_1 or \overline{E}_2 Enable to Output	2 2		12 21	18 32	ns	C _L = 15 pF
t _{PLH} t _{PHL}	Propagation Delay E ₃ Enable to Output	3 3		17 25	26 38	ns	

AC WAVEFORMS

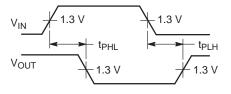


Figure 1.

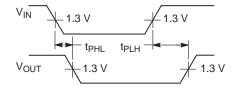


Figure 2.

Dual 1-of-4 Decoder/ Demultiplexer

The LSTTL/MSI SN74LS139 is a high speed Dual 1-of-4 Decoder/Demultiplexer. The device has two independent decoders, each accepting two inputs and providing four mutually exclusive active LOW Outputs. Each decoder has an active LOW Enable input which can be used as a data input for a 4-output demultiplexer. Each half of the LS139 can be used as a function generator providing all four minterms of two variables. The LS139 is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Schottky Process for High Speed
- Multifunction Capability
- Two Completely Independent 1-of-4 Decoders
- Active Low Mutually Exclusive Outputs
- Input Clamp Diodes Limit High Speed Termination Effects
- ESD > 3500 Volts

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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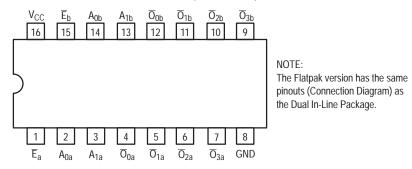
N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS139N	16 Pin DIP	2000 Units/Box
SN74LS139D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



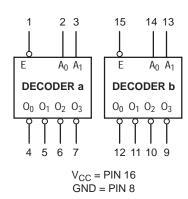
LOADING (Note a)

PIN NAMES		HIGH	LOW
A ₀ , A ₁	Address Inputs	0.5 U.L.	0.25 U.L.
E	Enable (Active LOW) Input	0.5 U.L.	0.25 U.L.
$\overline{O}_0 - \overline{O}_3$	Active LOW Outputs	10 U.L.	5 U.L.

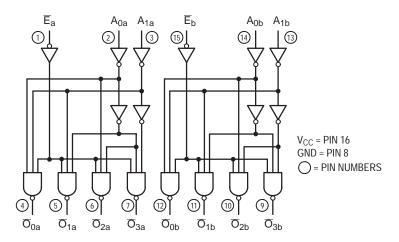
NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS139 is a high speed dual 1-of-4 decoder/demultiplexer fabricated with the Schottky barrier diode process. The device has two independent decoders, each of which accept two binary weighted inputs (A_0, A_1) and provide four mutually exclusive active LOW outputs $(\overline{O}_0-\overline{O}_3)$. Each decoder has an active LOW Enable (\overline{E}) . When E is HIGH all outputs are forced HIGH. The enable

can be used as the data input for a 4-output demultiplexer application.

Each half of the LS139 generates all four minterms of two variables. These four minterms are useful in some applications, replacing multiple gate functions as shown in Fig. a, and thereby reducing the number of packages required in a logic network.

TRUTH TABLE

	INPUTS	.		OUTI	PUTS	
Ē	A ₀	A ₁	Ō ₀	<u>0</u> 1	\overline{O}_2	\overline{O}_3
Н	Х	Χ	Н	Н	Н	Н
L	L	L	L	Н	Н	Н
L	Н	L	Н	L	Н	Н
L	L	Н	Н	Н	L	Н
L	Н	Н	Н	Н	Н	L

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

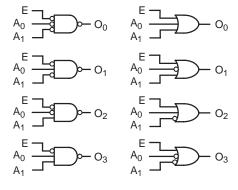


Figure a

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs			
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA			
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table			
V	Output LOW/Valtage		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$		
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	per Truth Table		
,	Input HICH Current			20	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V		
Т ІН	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN}	= 7.0 V		
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V			
Ios	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX			
Icc	Power Supply Current			11	mA	V _{CC} = MAX			

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Levels of	Limits				
Symbol	Parameter	Delay	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay Address to Output	2 2		13 22	20 33	ns	
t _{PLH} t _{PHL}	Propagation Delay Address to Output	3 3		18 25	29 38	ns	$V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$
t _{PLH} t _{PHL}	Propagation Delay Enable to Output	2 2		16 21	24 32	ns	

AC WAVEFORMS

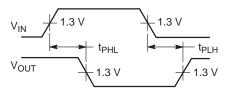


Figure 1.

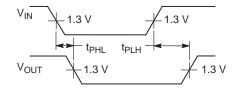


Figure 2.

1-of-10 Decoder/Driver Open-Collector

The SN74LS145, 1-of-10 Decoder/Driver, is designed to accept BCD inputs and provide appropriate outputs to drive 10-digit incandescent displays. All outputs remain off for all invalid binary input conditions. It is designed for use as indicator/relay drivers or as an open-collector logic circuit driver. Each of the high breakdown output transistors will sink up to 80 mA of current. Typical power dissipation is 35 mW. This device is fully compatible with all TTL families.

- Low Power Version of 74145
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
V _{OH}	Output Voltage – High			15	V
I _{OL}	Output Current – Low			24	mA



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> LOW POWER SCHOTTKY



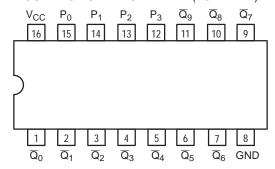
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS145N	16 Pin DIP	2000 Units/Box
SN74LS145D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



LOADING (Note a)

PIN NAMES

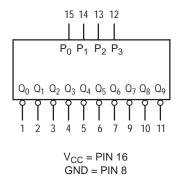
 $\begin{array}{ll} \underline{P_0}, \, \underline{P_1}, \, \underline{P_2}, \, \underline{P_3} & \quad \text{BCD Inputs} \\ \overline{Q_0} - \overline{Q_9} & \quad \text{Outputs} \end{array}$

HIGH	LOW
0.5 U.L.	0.25 U.L.
Open Collector	15 U.L.

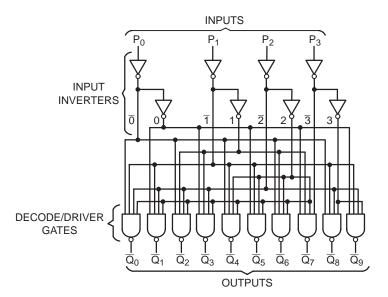
NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



LOGIC DIAGRAM



TRUTH TABLE

	INP	UTS						OUT	PUTS				
P ₃	P ₂	P ₁	P ₀	\overline{Q}_0	\overline{Q}_1	\overline{Q}_2	\overline{Q}_3	\overline{Q}_4	\overline{Q}_{5}	\overline{Q}_6	\overline{Q}_7	Q ₈	\overline{Q}_9
L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н
L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	Н	Н
L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	Н	Н
L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	Н	Н
L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	Н	Н
L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	Н	н
L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	н
L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	Н	Н
Н	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	L	Н
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L
Н	L	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	н
Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	н
Н	Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	н
Н	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	н
Н	Н	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н

H = HIGH Voltage Level L = LOW Voltage Level

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs			
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA			
I _{OH}	Output HIGH Current			250	μΑ	V _{CC} = MIN, V _{OH} = MAX			
			0.25	0.4	V	I _{OL} = 12 mA	V _{CC} = V _{CC} MIN,		
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 24 mA	$V_{IN} = V_{IL}$ or V_{IH}		
			2.3	3.0	V	I _{OL} = 80 mA	per Truth Table		
	Input HICH Current			20	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V		
l _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V			
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V			
I _{CC}	Power Supply Current			13	mA	V _{CC} = MAX, V _{IN}	= GND		

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

				Limits			
l	Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
	t _{PHL} t _{PLH}	Propagation Delay P _n Input to Q _n Output			50 50	ns	$V_{CC} = 5.0 \text{ V}$ $C_{L} = 45 \text{ pF}$

AC WAVEFORMS

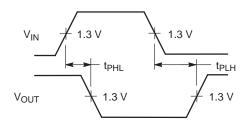


Figure 1.

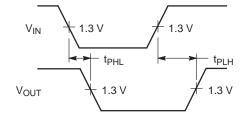


Figure 2.

10-Line-to-4-Line and 8-Line-to-3-Line Priority Encoders

The SN74LS147 and the SN74LS148 are Priority Encoders. They provide priority decoding of the inputs to ensure that only the highest order data line is encoded. Both devices have data inputs and outputs which are active at the low logic level.

The LS147 encodes nine data lines to four-line (8-4-2-1) BCD. The implied decimal zero condition does not require an input condition because zero is encoded when all nine data lines are at a high logic level.

The LS148 encodes eight data lines to three-line (4-2-1) binary (octal). By providing cascading circuitry (Enable Input EI and Enable Output EO) octal expansion is allowed without needing external circuitry.

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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LOW POWER SCHOTTKY



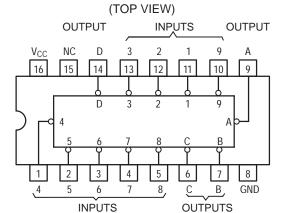
N SUFFIX CASE 648



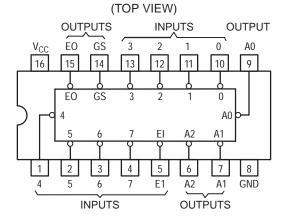
SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS147N	16 Pin DIP	2000 Units/Box
SN74LS147D	16 Pin	2500/Tape & Reel
SN74LS148N	16 Pin DIP	2000 Units/Box
SN74LS148D	16 Pin	2500/Tape & Reel

SN74LS147



SN74LS148



SN74LS147 FUNCTION TABLE

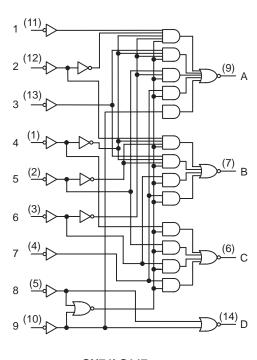
			II.	NPUT	s					OUTI	PUTS	5
1	2	3	4	5	6	7	8	9	D	С	В	Α
Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	L	L	Н	Н	L
Χ	Χ	Χ	Χ	Χ	Χ	Χ	L	Н	L	Н	Н	Н
Χ	Χ	Χ	Χ	Χ	Χ	L	Н	Н	Н	L	L	L
Х	Χ	Χ	Χ	Χ	L	Н	Н	Н	Н	L	L	Н
Χ	Χ	Χ	Χ	L	Н	Н	Н	Н	Н	L	Н	L
Χ	Χ	Χ	L	Н	Н	Н	Н	Н	Н	L	Н	Н
Χ	Χ	L	Н	Н	Н	Н	Н	Н	Н	Н	L	L
Χ	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	Н
L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L

H = HIGH Logic Level, L = LOW Logic Level, X = Irrelevant

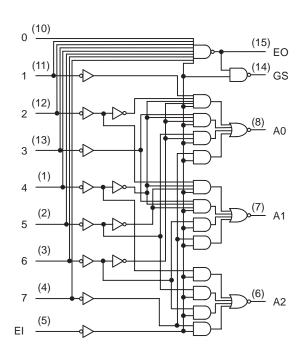
SN74LS148 FUNCTION TABLE

			IN	PU	rs					0	UTPL	JTS	
ΕI	0	1	2	3	4	5	6	7	A2	A1	A0	GS	EO
Н	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Н	Н	Н	Н	Н
L	Н	Н	Η	Н	Н	Н	Н	Н	Н	Н	Н	Н	L
L	Χ	Χ	Χ	Χ	Χ	Χ	Χ	L	L	L	L	L	Н
L	Χ	Χ	Χ	Χ	Χ	Χ	L	Н	L	L	Н	L	Н
L	Χ	Χ	Χ	Χ	Χ	L	Н	Н	L	Н	L	L	Н
L	Χ	Χ	Χ	Χ	L	Н	Н	Н	L	Н	Н	L	Н
L	Χ	Χ	Χ	L	Н	Н	Н	Н	Н	L	L	L	Н
L	Χ	Χ	L	Н	Н	Н	Η	Н	Н	L	Н	L	Н
L	Χ	L	Н	Н	Н	Н	Н	Н	Н	Н	L	L	Н
L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	Н

FUNCTIONAL BLOCK DIAGRAMS



SN74LS147



SN74LS148

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
M	Outrot I OM Valtage		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V_{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table	
l _{IH}	Input HIGH Current All Others Inputs 1-7 (LS148)			20 40	μΑ	$V_{CC} = MAX, V_{IN} = 2.7 V$		
	All Others Inputs 1-7 (LS148)			0.1 0.2	mA	V _{CC} = MAX, V _{IN}	= 7.0 V	
I _{IL}	Input LOW Current All Others Inputs 1–7 (LS148)			-0.4 -0.8	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CCH}	Power Supply Current Output HIGH			17	mA	V _{CC} = MAX, All Inputs = 4.5 V		
I _{CCL}	Output LOW			20	mA	V _{CC} = MAX, Inpu All Other Inputs =		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (V $_{CC}$ = 5.0 V, T_{A} = $25^{\circ}C)$ SN74LS147

	From	То			Limits						
Symbol	(Input)	(Output)	Waveform	Min	Тур	Max	Unit	Test Conditions			
t _{PLH}	A m) (Amir	In-phase		12	18					
t _{PHL}	Any	Any	output		12	18	ns	$C_L = 15 \text{ pF},$ $R_L = 2.0 \text{ k}\Omega$			
t _{PLH}	Any	Any	Out-of-phase		21	33	no	$R_L = 2.0 \text{ k}\Omega$			
t _{PHL}	Any	Any	output		15	23	ns				

SN74LS148

_	From	То			Limits	•				
Symbol	(Input)	(Output)	Waveform	Min	Тур	Max	Unit	Test Conditions		
t _{PLH}	4 46 7	AO A4 07 A2	In-phase		14	18				
t _{PHL}	1 thru 7	A0, A1, or A2	output		15	25	ns			
t _{PLH}	4 45 7	AO AA AO	Out-of-phase		20	36				
t _{PHL}	1 thru 7	A0, A1, or A2	output		16	29	ns			
t _{PLH}	0.45	50	Out-of-phase		7.0	18		C_L = 15 pF, R_L = 2.0 kΩ		
t _{PHL}	0 thru 7	EO	output		25	40	ns			
t _{PLH}	0.45	00	In-phase		35	55				
t _{PHL}	0 thru 7	GS	output		9.0	21	ns			
t _{PLH}	EI	AO A4 07 A2	In-phase		16	25				
t _{PHL}] [A0, A1, or A2	output		12	25	ns			
t _{PLH}		CS.	In-phase		12	17				
t _{PHL}	EI	GS	output		14	36	ns			
t _{PLH}			la abasa	la abasa	la abasa		12	21		
t _{PHL}	EI	EO	In-phase output		28 30	40 45	ns	(LS148)		

8-Input Multiplexer

The TTL/MSI SN74LS151 is a high speed 8-input Digital Multiplexer. It provides, in one package, the ability to select one bit of data from up to eight sources. The LS151 can be used as a universal function generator to generate any logic function of four variables. Both assertion and negation outputs are provided.

- Schottky Process for High Speed
- Multifunction Capability
- On-Chip Select Logic Decoding
- Fully Buffered Complementary Outputs
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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LOW POWER SCHOTTKY



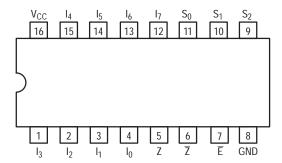
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS151N	16 Pin DIP	2000 Units/Box
SN74LS151D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)

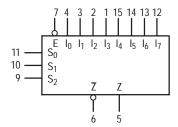


		LOADING (Note a)		
PIN NAMES		HIGH	LOW	
$S_0 - S_2$	Select Inputs	0.5 U.L.	0.25 U.L.	
Ē	Enable (Active LOW) Input	0.5 U.L.	0.25 U.L.	
$I_0 - I_7$	Multiplexer Inputs	0.5 U.L.	0.25 U.L.	
Z	Multiplexer Output	10 U.L.	5 U.L.	
Z	Complementary Multiplexer Output	10 U.L.	5 U.L.	

NOTES:

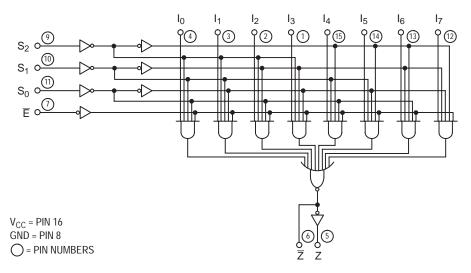
- a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.
- b) The Output LOW drive factor is 5 U.L. for Commercial (74) Temperature Ranges.

LOGIC SYMBOL



V_{CC} = PIN 16 GND = PIN 8

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS151 is a logical implementation of a single pole, 8-position switch with the switch position controlled by the state of three Select inputs, S_0 , S_1 , S_2 . Both assertion and negation outputs are provided. The Enable input (E) is active LOW. When it is not activated, the negation output is HIGH and the assertion output is LOW regardless of all other inputs. The logic function provided at the output is:

$$\begin{split} Z &= \overline{E} \cdot (I_0 \cdot \overline{S}_0 \cdot \overline{S}_1 \cdot \overline{S}_2 + \cdot I_1 \cdot S_0 \cdot \overline{S}_1 \cdot \overline{S}_2 + I_2 \cdot \overline{S}_0 \cdot S_1 \cdot \overline{S}_2 \\ &+ I_3 \cdot S_0 \cdot S_1 \cdot \overline{S}_2 + I_4 \cdot \overline{S}_0 \cdot \overline{S}_1 \cdot S_2 + I_5 \cdot S_0 \cdot \overline{S}_1 \cdot S_2 + I_6 \cdot \\ &\overline{S}_0 \cdot S_1 \cdot S_2 + I_7 \cdot S_0 \cdot S_1 \cdot S_2). \end{split}$$

The LS151 provides the ability, in one package, to select from eight sources of data or control information. By proper manipulation of the inputs, the LS151 can provide any logic function of four variables and its negation.

TRUTH TABLE

Ē	S ₂	S ₁	S ₀	I ₀	I ₁	I ₂	I ₃	I ₄	I ₅	I ₆	I ₇	Z	Z
Н	Х	Χ	Х	Х	Χ	Х	Х	Х	Х	Х	Х	Н	L
L	L	L	L	L	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Н	L
L	L	L	L	Н	Χ	Χ	Χ	Χ	Χ	Χ	Χ	L	Н
L	L	L	Н	Х	L	Χ	Χ	Χ	Χ	Χ	Χ	Н	L
L	L	L	Н	Х	Н	Χ	Χ	Χ	Χ	Χ	Χ	L	Н
L	L	Н	L	Х	Χ	L	Χ	Χ	Χ	Χ	Χ	Н	L
L	L	Н	L	Х	Χ	Н	Χ	Χ	Χ	Χ	Χ	L	Н
L	L	Н	Н	Χ	Χ	Χ	L	Χ	Χ	Χ	Χ	Н	L
L	L	Н	Н	Х	Χ	Χ	Н	Χ	Χ	Χ	Χ	L	Н
L	Н	L	L	Χ	Χ	Χ	Χ	L	Χ	Χ	Χ	Н	L
L	Н	L	L	Х	Χ	Χ	Χ	Н	Χ	Χ	Χ	L	Н
L	Н	L	Н	Х	Χ	Χ	Χ	Χ	L	Χ	Χ	Н	L
L	Н	L	Н	Χ	Χ	Χ	Χ	Χ	Н	Χ	Χ	L	Н
L	Н	Н	L	Х	Χ	Χ	Χ	Χ	Χ	L	Χ	Н	L
L	Н	Н	L	Х	Χ	Χ	Χ	Χ	Χ	Н	Χ	L	Н
L	Н	Н	Н	Х	Χ	Χ	Χ	Χ	Χ	Χ	L	Н	L
L	Н	Н	Н	Х	Χ	Χ	Χ	Χ	Χ	Χ	Н	L	Н

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs		
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA		
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
W	Output I OW Valtage		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table	
	Input HICH Current			20	μΑ	V _{CC} = MAX, V _{IN} :	= 2.7 V	
Iн	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} :	C = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
Ios	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
Icc	Power Supply Current			10	mA	$V_{CC} = MAX$		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay Select to Output Z		27 18	43 30	ns	
t _{PLH} t _{PHL}	Propagation Delay Select to Output Z		14 20	23 32	ns	
t _{PLH} t _{PHL}	Propagation Delay Enable to Output Z		26 20	42 32	ns	V _{CC} = 5.0 V
t _{PLH} t _{PHL}	Propagation Delay Enable to Output Z		15 18	24 30	ns	$V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$
t _{PLH} t _{PHL}	Propagation Delay Data to Output Z		20 16	32 26	ns	
t _{PLH} t _{PHL}	Propagation Delay Data to Output Z		13 12	21 20	ns	

AC WAVEFORMS

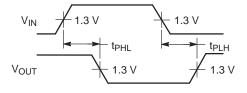


Figure 1.

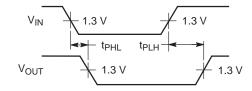


Figure 2.

Dual 4-Input Multiplexer

The LSTTL/MSI SN74LS153 is a very high speed Dual 4-Input Multiplexer with common select inputs and individual enable inputs for each section. It can select two bits of data from four sources. The two buffered outputs present data in the true (non-inverted) form. In addition to multiplexer operation, the LS153 can generate any two functions of three variables. The LS153 is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Multifunction Capability
- Non-Inverting Outputs
- Separate Enable for Each Multiplexer
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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LOW POWER SCHOTTKY



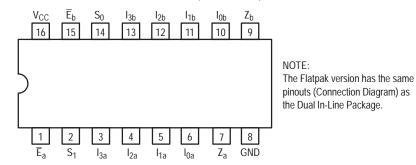
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping	
SN74LS153N	16 Pin DIP	2000 Units/Box	
SN74LS153D	16 Pin	2500/Tape & Reel	

CONNECTION DIAGRAM DIP (TOP VIEW)

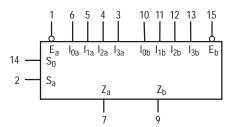


		LOADING (Note a)		
PIN NAMES		HIGH	LOW	
S ₀ E I ₀ , I ₁ Z	Common Select Input Enable (Active LOW) Input Multiplexer Inputs Multiplexer Output	0.5 U.L. 0.5 U.L. 0.5 U.L. 10 U.L.	0.25 U.L. 0.25 U.L. 0.25 U.L. 5 U.L.	

NOTES:

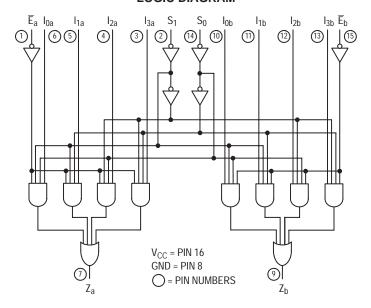
a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



V_{CC} = PIN 16 GND = PIN 8

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS153 is a Dual 4-input Multiplexer fabricated with Low Power, Schottky barrier diode process for high speed. It can select two bits of data from up to four sources under the control of the common Select Inputs (S_0, S_1) . The two 4-input multiplexer circuits have individual active LOW Enables $(\overline{E}_a, \overline{E}_b)$ which can be used to strobe the outputs independently. When the Enables $(\overline{E}_a, \overline{E}_b)$ are HIGH, the corresponding outputs (Z_a, Z_b) are forced LOW.

The LS153 is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels supplied to the two Select Inputs. The logic equations for the outputs are shown below.

$$\begin{split} Z_a = \overline{E}_a \cdot (I_{0a} \cdot \overline{S}_1 \cdot \overline{S}_0 + I_{1a} \cdot \overline{S}_1 \cdot S_0 + I_{2a} \cdot S_1 \cdot \overline{S}_0 + \\ I_{3a} \cdot S_1 \cdot S_0) \end{split}$$

$$\begin{split} Z_b = \overline{E}_b \cdot (I_{0b} \cdot \overline{S}_1 \cdot \overline{S}_0 + I_{1b} \cdot \overline{S}_1 \cdot S_0 + I_{2b} \cdot S_1 \cdot \overline{S}_0 + \\ I_{3b} \cdot S_1 \cdot S_0) \end{split}$$

The LS153 can be used to move data from a group of registers to a common output bus. The particular register from which the data came would be determined by the state of the Select Inputs. A less obvious application is a function generator. The LS153 can generate two functions of three variables. This is useful for implementing highly irregular random logic.

TRUTH TABLE

SELECT	INPUTS	INPUTS (a or b)					OUTPUT
S ₀	S ₁	Ē	I ₀	I ₁	l ₂	l ₃	Z
Х	Х	Н	Х	Х	Х	Χ	L
L	L	L	L	X	X	Χ	L
L	L	L	Н	X	X	Χ	Н
Н	L	L	Χ	L	X	Χ	L
Н	L	L	Χ	Н	Χ	X	Н
L	Н	L	Χ	X	L	Χ	L
L	Н	L	Χ	X	Н	Χ	Н
Н	Н	L	Χ	Χ	Χ	L	L
Н	Н	L	Χ	Χ	Χ	Н	Н

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs		
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN$, $I_{OH} = MAX$, $V_{IN} = V_{IH}$ or V_{IL} per Truth Table		
W	Output I OW/ Valtage		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$	
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	per Truth Table	
	Innut I IICI I Current			20	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V	
Iн	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current			10	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
t _{PLH} t _{PHL}	Propagation Delay Data to Output		10 17	15 26	ns	Figure 2		
t _{PLH} t _{PHL}	Propagation Delay Select to Output		19 25	29 38	ns	Figure 1	$V_{CC} = 5.0 \text{ V}$ $C_{L} = 15 \text{ pF}$	
t _{PLH} t _{PHL}	Propagation Delay Enable to Output		16 21	24 32	ns	Figure 2		

AC WAVEFORMS

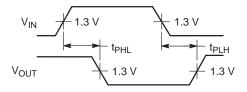


Figure 1.

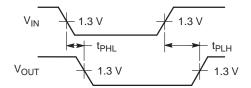


Figure 2.

Dual 1-of-4 Decoder/ Demultiplexer

The SN74LS156 is a high speed Dual 1-of-4 Decoder/Demultiplexer. This device has two decoders with common 2-bit Address inputs and separate gated Enable inputs. Decoder "a" has an Enable gate with one active HIGH and one active LOW input. Decoder "b" has two active LOW Enable inputs. If the Enable functions are satisfied, one output of each decoder will be LOW as selected by the address inputs. The LS156 has open collector outputs for wired-OR (DOT-AND) decoding and function generator applications.

The LS156 is fabricated with the Schottky barrier diode process for high speed and are completely compatible with all ON Semiconductor TTL families.

- Schottky Process for High Speed
- Multifunction Capability
- Common Address Inputs
- True or Complement Data Demultiplexing
- Input Clamp Diodes Limit High Speed Termination Effects
- ESD > 3500 Volts

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
V _{OH}	Output Voltage – High			5.5	V
I _{OL}	Output Current – Low			8.0	mA



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LS156-OPEN-COLLECTOR LOW POWER SCHOTTKY



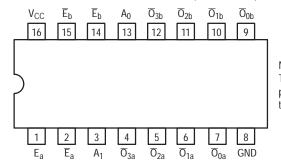
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping		
SN74LS156N	16 Pin DIP	2000 Units/Box		
SN74LS156D	16 Pin	2500/Tape & Reel		

CONNECTION DIAGRAM DIP (TOP VIEW)



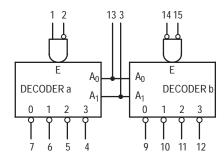
NOTE: The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

		LOADING (Note a)		
PIN NAMES		HIGH	LOW	
A ₀ , A ₁	Address Inputs	0.5 U.L.	0.25 U.L.	
\overline{E}_a , \overline{E}_b	Enable (Active LOW) Inputs	0.5 U.L.	0.25 U.L.	
$\frac{E_a}{O_0} - \overline{O}_3$	Enable (Active HIGH) Input	0.5 U.L.	0.25 U.L.	
$\overline{O}_0 - \overline{O}_3$	Active LOW Outputs	10 U.L.	5 U.L.	

NOTES:

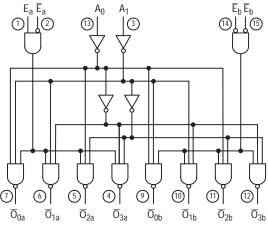
a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



V_{CC} = PIN 16 GND = PIN 8

LOGIC DIAGRAM



V_{CC} = PIN 16 GND = PIN 8 = PIN NUMBERS

FUNCTIONAL DESCRIPTION

The LS156 is a Dual 1-of-4 Decoder/Demultiplexer with common Address inputs and separate gated Enable inputs. When enabled, each decoder section accepts the binary weighted Address inputs (A₀, A₁) and provides four mutually exclusive active LOW outputs $(\overline{O}_0 - \overline{O}_3)$. If the Enable requirements of each decoder are not met, all outputs of that decoder are HIGH.

Each decoder section has a 2-input enable gate. The enable gate for Decoder "a" requires one active HIGH input and one active LOW input $(E_a \bullet \overline{E}_a)$. In demultiplexing applications, Decoder "a" can accept either true or complemented data by using the \overline{E}_a or E_a inputs respectively. The enable gate for Decoder "b" requires two active LOW inputs $(\overline{E}_b \bullet \overline{E}_b)$. The LS155 or LS156 can be used as a 1-of-8 Decoder/Demultiplexer by tying E_a to \overline{E}_b and relabeling the common connection as (A_2) . The other \overline{E}_b and \overline{E}_a are connected together to form the common enable.

The LS156 can be used to generate all four minterms of two variables. These four minterms are useful in some applications replacing multiple gate functions as shown in Fig. a. The LS156 has the further advantage of being able to AND the minterm functions by tying outputs together. Any number of terms can be wired-AND as shown below.

$$\begin{array}{l} f = (E + A_0 + A_1) \cdot (E + \overline{A}_0 + A_1) \cdot (E + A_0 + \overline{A}_1) \cdot \\ (E + \overline{A}_0 + \overline{A}_1) \end{array}$$

where
$$E = E_a + \overline{E}_a$$
; $E = E_b + E_b$

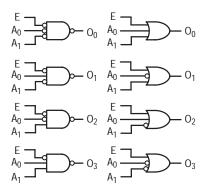


Figure a

TRUTH TABLE

ADDR	RESS	ENAB	LE "a"		OUTPU	JT "a"		ENAB	LE "b"		OUTP	JT "b"	
A ₀	A ₁	Ea	Ea	\overline{O}_0	<u>0</u> 1	\overline{O}_2	\overline{O}_3	Ē _b	E _b	O ₀	<u>0</u> 1	O ₂	\overline{O}_3
Х	Х	L	Х	Н	Н	Н	Н	Н	Х	Н	Н	Н	Н
Х	Х	Х	Н	Н	Н	Н	Н	Х	Н	Н	Н	Н	Н
L	L	Н	L	L	Н	Н	Н	L	L	L	Н	Н	Н
Н	L	Н	L	Н	L	Н	Н	L	L	Н	L	Н	Н
L	Н	Н	L	Н	Н	L	Н	L	L	Н	Н	L	Н
Н	Н	Н	L	Н	Н	Н	L	L	L	Н	Н	Н	L

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs		
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$		
Іон	Output HIGH Current			100	μА	V _{CC} = MIN, V _{OH} = MAX		
V	Output LOW Voltage		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$	
V _{OL}	Output LOW Voltage		0.35	0.5	٧	I _{OL} = 8.0 mA	per Truth Table	
	Innut HCH Current			20	μΑ	V _{CC} = MAX, V _{IN} = 2.7 V		
l _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN}	= 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
Icc	Power Supply Current			10	mA	V _{CC} = MAX		

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test	Conditions
t _{PLH} t _{PHL}	Propagation Delay Address, \overline{E}_a or \overline{E}_b to Output		25 34	40 51	ns	Figure 1	
t _{PLH} t _{PHL}	Propagation Delay Address to Output		31 34	46 51	ns	Figure 2	$V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$ $R_L = 2.0 \text{ k}\Omega$
t _{PLH} t _{PHL}	Propagation Delay E _a to Output		32 32	48 48	ns	Figure 1	1

AC WAVEFORMS

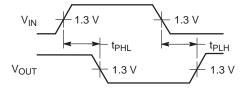


Figure 1.

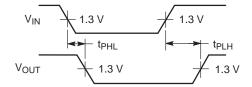


Figure 2.

Quad 2-Input Multiplexer

The LSTTL/MSI SN74LS157 is a high speed Quad 2-Input Multiplexer. Four bits of data from two sources can be selected using the common Select and Enable inputs. The four buffered outputs present the selected data in the true (non-inverted) form. The LS157 can also be used to generate any four of the 16 different functions of two variables. The LS157 is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Schottky Process for High Speed
- Multifunction Capability
- Non-Inverting Outputs
- Input Clamp Diodes Limit High Speed Termination Effects
- Special Circuitry Ensures Glitch Free Multiplexing
- ESD > 3500 Volts

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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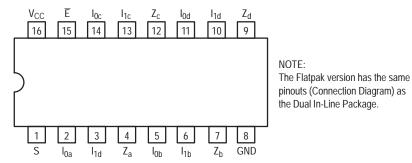
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS157N	16 Pin DIP	2000 Units/Box
SN74LS157D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)

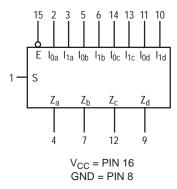


		LOADING (Note a)		
PIN NAMES		HIGH	LOW	
S E	Common Select Input Enable (Active LOW) Input	1.0 U.L. 1.0 U.L.	0.5 U.L. 0.5 U.L.	
$I_{0a} - I_{0d}$ $I_{1a} - I_{1d}$ $Z_a - Z_d$	Data Inputs from Source 0 Data Inputs from Source 1 Multiplexer Outputs	0.5 U.L. 0.5 U.L. 10 U.L.	0.25 U.L. 0.25 U.L. 5 U.L.	

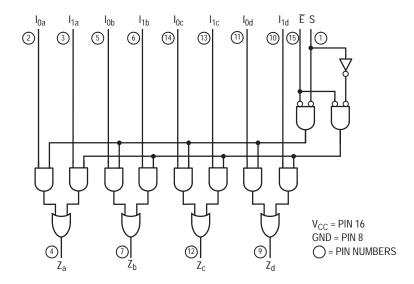
NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS157 is a Quad 2-Input Multiplexer fabricated with the Schottky barrier diode process for high speed. It selects four bits of data from two sources under the control of a common Select Input (S). The Enable Input (\overline{E}) is active LOW. When \overline{E} is HIGH, all of the outputs (Z) are forced LOW regardless of all other inputs.

The LS157 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select Input. The logic equations for the outputs are:

$$\begin{split} Z_a &= \overline{E} \cdot (I_{1a} \cdot S + \ I_{0a} \cdot \overline{S}) & Z_b &= \overline{E} \cdot (I_{1b} \cdot S + I_{0b} \cdot \overline{S}) \\ Z_c &= \overline{E} \cdot (I_{1c} \cdot S + I_{0c} \cdot \overline{S}) & Z_d &= \overline{E} \cdot (I_{1d} \cdot S + I_{0d} \cdot \overline{S}) \end{split}$$

A common use of the LS157 is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select Input. A less obvious use is as a function generator. The LS157 can generate any four of the 16 different functions of two variables with one variable common. This is useful for implementing highly irregular logic.

TRUTH TABLE

ENABLE	SELECT INPUT	INPUTS		OUTPUT
Ē	S	I ₀	I ₁	Z
Н	Х	Х	Х	L
L	Н	Х	L	L
L	Н	Х	Н	Н
L	L	L	Χ	L
L	L	Н	Χ	Н

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH}$ or V_{IL} per Truth Table		
M	Output I OW Valtage		0.25	0.4	٧	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V _{OL}	Output LOW Voltage		0.35	0.5	٧	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table	
I _{IH}	Input HIGH Current I ₀ , I ₁ E, S			20 40	μΑ	V _{CC} = MAX, V _{IN} = 2.7 V		
	I ₀ , I ₁ E, S			0.1 0.2	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current I ₀ , I ₁ E, S			-0.4 -0.8	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current			16	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
t _{PLH} t _{PHL}	Propagation Delay Data to Output		9.0 9.0	14 14	ns	Figure 2		
t _{PLH} t _{PHL}	Propagation Delay Enable to Output		13 14	20 21	ns	Figure 1	$V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$	
t _{PLH} t _{PHL}	Propagation Delay Select to Output		15 18	23 27	ns	Figure 2		

AC WAVEFORMS

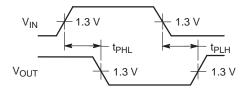


Figure 1.

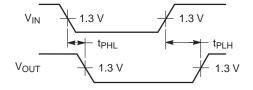


Figure 2.

BCD Decade Counters/ 4-Bit Binary Counters

The LS161A/163A are high-speed 4-bit synchronous counters. They are edge-triggered, synchronously presettable, and cascadable MSI building blocks for counting, memory addressing, frequency division and other applications. The LS161A and LS163A count modulo 16 (binary).

The LS161A has an asynchronous Master Reset (Clear) input that overrides, and is independent of, the clock and all other control inputs. The LS163A has a Synchronous Reset (Clear) input that overrides all other control inputs, but is active only during the rising clock edge.

	Binary (Modulo 16)
Asynchronous Reset	LS161A
Synchronous Reset	LS163A

- Synchronous Counting and Loading
- Two Count Enable Inputs for High Speed Synchronous Expansion
- Terminal Count Fully Decoded
- Edge-Triggered Operation
- Typical Count Rate of 35 MHz
- ESD > 3500 Volts

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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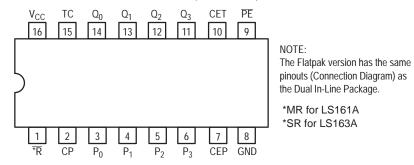
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS161AN	16 Pin DIP	2000 Units/Box
SN74LS161AD	16 Pin	2500/Tape & Reel
SN74LS163AN	16 Pin DIP	2000 Units/Box
SN74LS163AD	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)

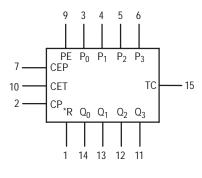


		LOADING	(Note a)
PIN NAMES		HIGH	LOW
PE	Parallel Enable (Active LOW) Input	1.0 U.L.	0.5 U.L.
$P_0 - P_3$	Parallel Inputs	0.5 U.L.	0.25 U.L.
CEP	Count Enable Parallel Input	0.5 U.L.	0.25 U.L.
CET	Count Enable Trickle Input	1.0 U.L.	0.5 U.L.
CP	Clock (Active HIGH Going Edge) Input	0.5 U.L.	0.25 U.L.
MR	Master Reset (Active LOW) Input	0.5 U.L.	0.25 U.L.
SR	Synchronous Reset (Active LOW) Input	1.0 U.L.	0.5 U.L.
$Q_0 - Q_3$	Parallel Outputs	10 U.L.	5 U.L.
TC	Terminal Count Output	10 U.L.	5 U.L.

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

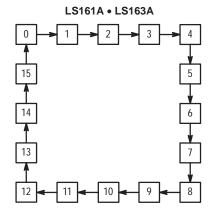
LOGIC SYMBOL



 $V_{CC} = PIN 16$ GND = PIN 8

*MR for LS161A *SR for LS163A

STATE DIAGRAM



LOGIC EQUATIONS

Count Enable = CEP • CET • PE

TC for LS161A & LS163A = CET • $Q_0 • Q_1 • Q_2 • Q_3$ Preset = $\overline{PE} • CP +$ (rising clock edge)

Reset = \overline{MR} (LS161A)

Reset = $\overline{SR} • CP +$ (rising clock edge)

(LS163A)

FUNCTIONAL DESCRIPTION

The LS161A/163A are 4-bit synchronous counters with a synchronous Parallel Enable (Load) feature. The counters consist of four edge-triggered D flip-flops with the appropriate data routing networks feeding the D inputs. All changes of the Q outputs (except due to the asynchronous Master Reset in the LS161A) occur as a result of, and synchronous with, the LOW to HIGH transition of the Clock input (CP). As long as the set-up time requirements are met, there are no special timing or activity constraints on any of the mode control or data inputs.

Three control inputs — Parallel Enable (\overline{PE}), Count Enable Parallel (CEP) and Count Enable Trickle (CET) — select the mode of operation as shown in the tables below. The Count Mode is enabled when the CEP, CET, and \overline{PE} inputs are HIGH. When the \overline{PE} is LOW, the counters will synchronously load the data from the parallel inputs into the flip-flops on the LOW to HIGH transition of the clock. Either the CEP or CET can be used to inhibit the count sequence. With the \overline{PE} held HIGH, a LOW on either the CEP or CET inputs at least one set-up time prior to the LOW to HIGH clock transition will cause the existing output states to be retained. The AND feature of the two Count Enable inputs (CET \bullet CEP) allows synchronous cascading without external gating and without delay accumulation over any practical number of bits or digits.

The Terminal Count (TC) output is HIGH when the Count Enable Trickle (CET) input is HIGH while the counter is in its maximum count state (HLLH for the BCD counters, HHHH for the Binary counters). Note that TC is fully decoded and will, therefore, be HIGH only for one count state.

The LS161A and LS163A count modulo 16 following a binary sequence. They generate a TC when the CET input is HIGH while the counter is in state 15 (HHHH). From this state they increment to state 0 (LLLL).

The Master Reset (\overline{MR}) of the LS161A is asynchronous. When the \overline{MR} is LOW, it overrides all other input conditions and sets the outputs LOW. The \overline{MR} pin should never be left open. If not used, the \overline{MR} pin should be tied through a resistor to V_{CC} , or to a gate output which is permanently set to a HIGH logic level.

The active LOW Synchronous Reset (\overline{SR}) input of the LS163A acts as an edge-triggered control input, overriding CET, CEP and \overline{PE} , and resetting the four counter flip-flops on the LOW to HIGH transition of the clock. This simplifies the design from race-free logic controlled reset circuits, e.g., to reset the counter synchronously after reaching a predetermined value.

MODE SELECT TABLE

*SR	PE	CET	CEP	Action on the Rising Clock Edge (-
L	Χ	Χ	Х	RESET (Clear)
Н	L	Χ	Х	LOAD (P _n Q _n)
Н	Н	Н	Н	COUNT (Increment)
Н	Н	L	Х	NO CHANGE (Hold)
Н	Н	Χ	L	NO CHANGE (Hold)

*For the LS163A only.

H = HIGH Voltage Level L = LOW Voltage Level

X = Don't Care

LS161A
DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN$, $I_{OH} = MAX$, $V_{IN} = V_{IH}$ or V_{IL} per Truth Table	
.,	Output I OW/Vallance		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
I _{IH}	Input HIGH Current MR, Data, CEP, Clock PE, CET			20 40	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V
	MR, Data, CEP, Clock PE, CET			0.1 0.2	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current MR, Data, CEP, Clock PE, CET			-0.4 -0.8	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
I _{CC}	Power Supply Current Total, Output HIGH Total, Output LOW			31 32	mA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

LS163A

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu	t HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu	t LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN$, $I_{OH} = MAX$, $V_{IN} = V_{IH}$ or V_{IL} per Truth Table	
.,			0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table
l _{IH}	Input HIGH Current Data, CEP, Clock PE, CET, SR			20 40	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V
	Data, CEP, Clock PE, CET, SR			0.1 0.2	mA	V _{CC} = MAX, V _{IN}	= 7.0 V
I _{IL}	Input LOW Current Data, CEP, Clock, PE, SR CET			-0.4 -0.8	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
Icc	Power Supply Current Total, Output HIGH Total, Output LOW			31 32	mA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C)

			Limits		Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
f _{MAX}	Maximum Clock Frequency	25	32		MHz			
t _{PLH} t _{PHL}	Propagation Delay Clock to TC		20 18	35 35	ns			
t _{PLH} t _{PHL}	Propagation Delay Clock to Q		13 18	24 27	ns	$V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$		
t _{PLH} t _{PHL}	Propagation Delay CET to TC		9.0 9.0	14 14	ns			
t _{PHL}	MR or SR to Q		20	28	ns			

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W CP	Clock Pulse Width Low	25			ns	
t _W	MR or SR Pulse Width	20			ns	
t _s	Setup Time, other*	20			ns	
t _s	Setup Time PE or SR	25			ns	V _{CC} = 5.0 V
t _h	Hold Time, data	3			ns	
t _h	Hold Time, other	0			ns	
t _{rec}	Recovery Time MR to CP	15			ns	

^{*}CEP, CET, or DATA

DEFINITION OF TERMS

SETUP TIME (t_s) — is defined as the minimum time required for the correct logic level to be present at the logic input prior to the clock transition from LOW to HIGH in order to be recognized and transferred to the outputs.

HOLD TIME (t_h) — is defined as the minimum time following the clock transition from LOW to HIGH that the logic level must be maintained at the input in order to ensure

continued recognition. A negative HOLD TIME indicates that the correct logic level may be released prior to the clock transition from LOW to HIGH and still be recognized.

RECOVERY TIME (t_{rec})—is defined as the minimum time required between the end of the reset pulse and the clock transition from LOW to HIGH in order to recognize and transfer HIGH Data to the Q outputs.

AC WAVEFORMS

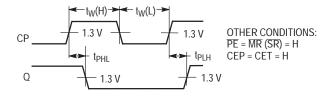


Figure 1. Clock to Output Delays, Count Frequency, and Clock Pulse Width

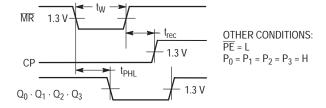


Figure 2. Master Reset to Output Delay, Master Reset Pulse Width, and Master Reset Recovery Time

AC WAVEFORMS (continued)

COUNT ENABLE TRICKLE INPUT TO TERMINAL COUNT OUTPUT DELAYS

The positive TC pulse occurs when the outputs are in the $(Q_0 \bullet Q_1 \bullet Q_2 \bullet Q_3)$ state for the LS161 and LS163.

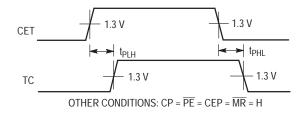


Figure 3.

CLOCK TO TERMINAL COUNT DELAYS

The positive TC pulse is coincident with the output state $(Q_0 \bullet Q_1 \bullet Q_2 \bullet Q_3)$ for the LS161 and LS163.

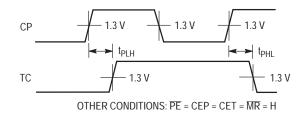


Figure 4.

SETUP TIME (t_s) AND HOLD TIME (t_h) FOR PARALLEL DATA INPUTS

The shaded areas indicate when the input is permitted to change for predictable output performance.

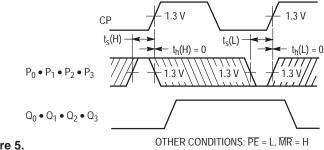


Figure 5.

SETUP TIME (t_s) AND HOLD TIME (t_h) FOR COUNT ENABLE (CEP) AND (CET) AND PARALLEL ENABLE (PE) INPUTS

The shaded areas indicate when the input is permitted to change for predictable output performance.

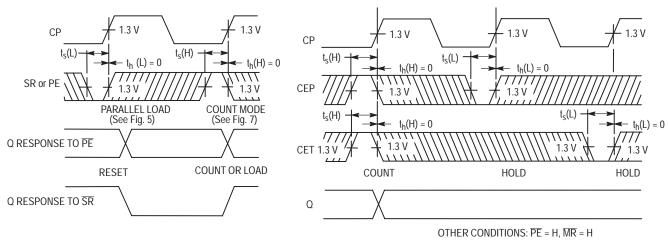


Figure 6. Figure 7.

Serial-In Parallel-Out Shift Register

The SN74LS164 is a high speed 8-Bit Serial-In Parallel-Out Shift Register. Serial data is entered through a 2-Input AND gate synchronous with the LOW to HIGH transition of the clock. The device features an asynchronous Master Reset which clears the register setting all outputs LOW independent of the clock. It utilizes the Schottky diode clamped process to achieve high speeds and is fully compatible with all ON Semiconductor TTL products.

- Typical Shift Frequency of 35 MHz
- Asynchronous Master Reset
- Gated Serial Data Input
- Fully Synchronous Data Transfers
- Input Clamp Diodes Limit High Speed Termination Effects
- ESD > 3500 Volts

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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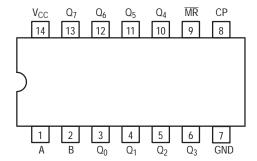
PLASTIC N SUFFIX CASE 646



SOIC D SUFFIX CASE 751A

Device	Package	Shipping		
SN74LS164N	14 Pin DIP	2000 Units/Box		
SN74LS164D	14 Pin	2500/Tape & Reel		

CONNECTION DIAGRAM DIP (TOP VIEW)



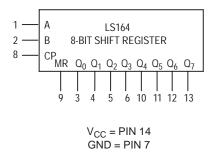
NOTE: The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

		LOADING	(Note a)
PIN NAMES		HIGH	LOW
A, B	Data Inputs	0.5 U.L.	0.25 U.L.
CP	Clock (Active HIGH Going Edge) Input	0.5 U.L.	0.25 U.L.
MR	Master Reset (Active LOW) Input	0.5 U.L.	0.25 U.L.
$Q_0 - Q_7$	Outputs	10 U.L.	5 U.L.

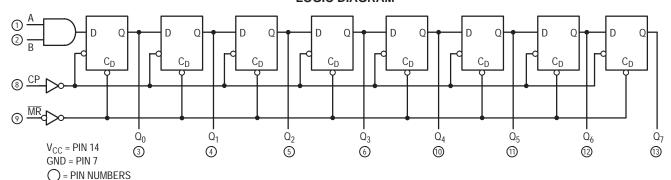
NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS164 is an edge-triggered 8-bit shift register with serial data entry and an output from each of the eight stages. Data is entered serially through one of two inputs (A or B); either of these inputs can be used as an active HIGH Enable for data entry through the other input. An unused input must be tied HIGH, or both inputs connected together.

Each LOW-to-HIGH transition on the Clock (CP) input shifts data one place to the right and enters into Q_0 the logical AND of the two data inputs (A•B) that existed before the rising clock edge. A LOW level on the Master Reset ($\overline{\text{MR}}$) input overrides all other inputs and clears the register asynchronously, forcing all Q outputs LOW.

MODE SELECT — TRUTH TABLE

OPERATING		INPUTS		OUTPUTS		
MODE	MR	Α	В	Q_0	Q ₁ –Q ₇	
Reset (Clear)	L	Х	Х	L	L – L	
Shift	H H H H	l h h	 h h	L L H	q ₀ – q ₆ q ₀ – q ₆ q ₀ – q ₆ q ₀ – q ₆	

L (I) = LOW Voltage Levels

H (h) = HIGH Voltage Levels

X = Don't Care

 q_{n} = Lower case letters indicate the state of the referenced input or output one set-up time prior to the LOW to HIGH clock transition.

DC CHARACTERISTICS OVER OPERATING

TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test C	onditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input All Inputs	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input All Inputs	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN$, $I_{IN} = -18 \text{ mA}$		
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
	0 / // 0 // // //		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V_{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IH}$ or V_{IL} per Truth Table	
	land HICH Company			20	μΑ	V _{CC} = MAX, V _{IN} :	= 2.7 V	
I _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} :	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	V _{CC} = MAX	
I _{CC}	Power Supply Current			27	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
f _{MAX}	Maximum Clock Frequency	25	36		MHz			
t _{PHL}	Propagation Delay MR to Output Q		24	36	ns	$V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$		
t _{PLH} t _{PHL}	Propagation Delay Clock to Output Q		17 21	27 32	ns			

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	CP, MR Pulse Width	20			ns	
t _s	Data Setup Time	15			ns	V 50V
t _h	Data Hold Time	5.0			ns	V _{CC} = 5.0 V
t _{rec}	MR to Clock Recovery Time	20			ns	

AC WAVEFORMS

*The shaded areas indicate when the input is permitted to change for predictable output performance.

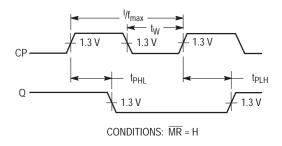


Figure 1. Clock to Output Delays and Clock Pulse Width

Figure 2. Master Reset Pulse Width, Master Reset to Output Delay and Master Reset to Clock Recovery Time

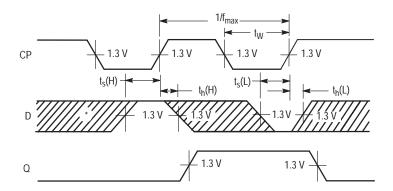


Figure 3. Data Setup and Hold Times

8-Bit Parallel-to-Serial **Shift Register**

The SN74LS165 is an 8-bit parallel load or serial-in register with complementary outputs available from the last stage. Parallel inputing occurs asynchronously when the Parallel Load (PL) input is LOW. With PL HIGH, serial shifting occurs on the rising edge of the clock; new data enters via the Serial Data (DS) input. The 2-input OR clock can be used to combine two independent clock sources, or one input can act as an active LOW clock enable.

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	H Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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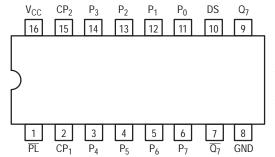
N SUFFIX CASE 648



SOIC **D SUFFIX CASE 751B**

Device	Package	Shipping
SN74LS165N	16 Pin DIP	2000 Units/Box
SN74LS165D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



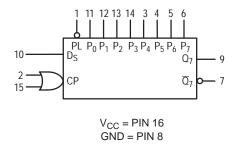
NOTE: The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

		LOADING	(Note a)
PIN NAMES		HIGH	LOW
CP ₁ , CP ₂ DS P L	Clock (LOW-to-HIGH Going Edge) Inputs Serial Data Input Asynchronous Parallel Load (Active LOW) Input	0.5 U.L. 0.5 U.L. 1.5 U.L.	0.25 U.L. 0.25 U.L. 0.75 U.L.
P ₀ – P ₇ Q ₇	Parallel Data Inputs Serial Output from Last State	0.5 U.L. 10 U.L.	0.75 U.L. 5 U.L.
$\overline{\mathbb{Q}}_7$	Complementary Output	10 U.L.	5 U.L.

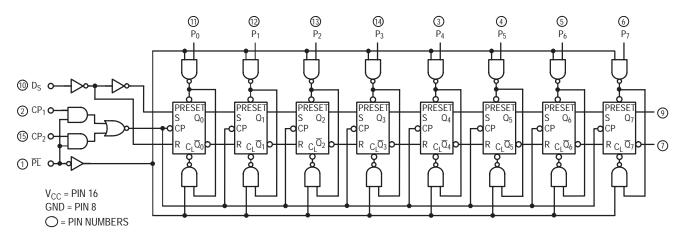
NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The SN74LS165 contains eight clocked master/slave RS flip-flops connected as a shift register, with auxiliary gating to provide overriding asynchronous parallel entry. Parallel data enters when the \overline{PL} signal is LOW. The parallel data can change while \overline{PL} is LOW, provided that the recommended setup and hold times are observed.

For clock operation, PL must be HIGH. The two clock inputs perform identically; one can be used as a clock inhibit

by applying a HIGH signal. To avoid double clocking, however, the inhibit signal should only go HIGH while the clock is HIGH. Otherwise, the rising inhibit signal will cause the same response as a rising clock edge. The flip-flops are edge-triggered for serial operations. The serial input data can change at any time, provided only that the recommended setup and hold times are observed, with respect to the rising edge of the clock.

TRUTH TABLE

PL	СР				RESPONSE							
	1	2	Q_0	Q ₁	Q ₂	Q_3	Q_4	Q_5	Q_6	Q ₇	RESPUNSE	
L	Х	Х	P ₀	P ₁	P ₂	P ₃	P_4	P ₅	P ₆	P ₇	Parallel Entry	
Н	L		Ds	Q_0	Q_1	Q_2	Q_3	Q_4	Q_5	Q_6	Right Shift	
Н	Н		Q_0	Q_1	Q_2	Q_3	Q_4	Q_5	Q_6	Q_7	No Change	
Н		L	Ds	Q_0	Q_1	Q_2	Q_3	Q_4	Q_5	Q_6	Right Shift	
Н		Н	Q_0	Q ₁	Q_2	Q_3	Q_4	Q_5	Q_6	Q ₇	No Change	

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input All Inputs	t HIGH Voltage for	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input All Inputs	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	٧	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
	Output I OW/Vallage		0.25	0.4	٧	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V_{OL}	Output LOW Voltage		0.35	0.5	٧	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table	
I _{IH}	Input HIGH Current Other Inputs PL Input			20 60	μΑ	V _{CC} = MAX, V _{IN} = 2.7 V		
	Other Inputs PE Input			0.1 0.3	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current Other Inputs PL Input			-0.4 -1.2	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
Icc	Power Supply Current			36	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
f _{MAX}	Maximum Input Clock Frequency	25	35		MHz	
t _{PLH}	Propagation Delay PL to Output		22 22	35 35	ns	
t _{PLH} t _{PHL}	Propagation Delay Clock to Output		27 28	40 40	ns	$V_{CC} = 5.0 \text{ V}$ $C_{L} = 15 \text{ pF}$
t _{PLH} t _{PHL}	Propagation Delay P ₇ to Q ₇		14 21	25 30	ns	12 1
t _{PLH} t _{PHL}	Propagation Delay P_7 to $\overline{\mathbb{Q}}_7$		21 16	30 25	ns	

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	CP Clock Pulse Width	25			ns	
t _W	PL Pulse Width	15			ns	
t _s	Parallel Data Setup Time	10			ns	
t _s	Serial Data Setup Time	20			ns	V _{CC} = 5.0 V
t _s	CP ₁ to CP ₂ Setup Time ¹	30			ns	
t _h	Hold Time	0			ns	
t _{rec}	Recovery Time, PL to CP	45			ns	

¹The role of CP₁ and CP₂ in an application may be interchanged.

DEFINITION OF TERMS:

SETUP TIME (t_s) — is defined as the minimum time required for the correct logic level to be present at the logic input prior to the clock transition from LOW-to-HIGH in order to be recognized and transferred to the outputs.

HOLD TIME (t_h) — is defined as the minimum time following the clock transition from LOW-to-HIGH that the logic level must be maintained at the input in order to ensure

continued recognition. A negative hold time indicates that the correct logic level may be released prior to the clock transition from LOW-to-HIGH and still be recognized.

RECOVERY TIME (t_{rec})—is defined as the minimum time required between the end of the \overline{PL} pulse and the clock transition from LOW-to-HIGH in order to recognize and transfer loaded Data to the Q outputs.

AC WAVEFORMS

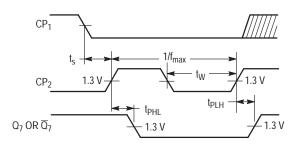


Figure 1.

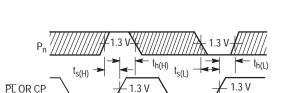


Figure 3.

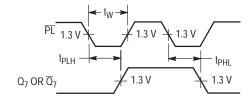


Figure 2.

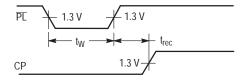


Figure 4.

8-Bit Shift Registers

The SN74LS166 is an 8-Bit Shift Register. Designed with all inputs buffered, the drive requirements are lowered to one 74LS standard load. By utilizing input clamping diodes, switching transients are minimized and system design simplified.

The LS166 is a parallel-in or serial-in, serial-out shift register and has a complexity of 77 equivalent gates with gated clock inputs and an overriding clear input. The shift/load input establishes the parallel-in or serial-in mode. When high, this input enables the serial data input and couples the eight flip-flops for serial shifting with each clock pulse. Synchronous loading occurs on the next clock pulse when this is low and the parallel data inputs are enabled. Serial data flow is inhibited during parallel loading. Clocking is done on the low-to-high level edge of the clock pulse via a two input positive NOR gate, which permits one input to be used as a clock enable or clock inhibit function. Clocking is inhibited when either of the clock inputs are held high, holding either input low enables the other clock input. This will allow the system clock to be free running and the register stopped on command with the other clock input. A change from low-to-high on the clock inhibit input should only be done when the clock input is high. A buffered direct clear input overrides all other inputs, including the clock, and sets all flip-flops to zero.

- Synchronous Load
- Direct Overriding Clear
- Parallel to Serial Conversion

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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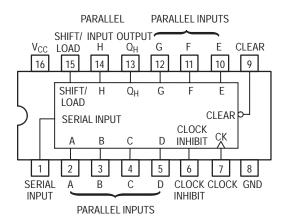


PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

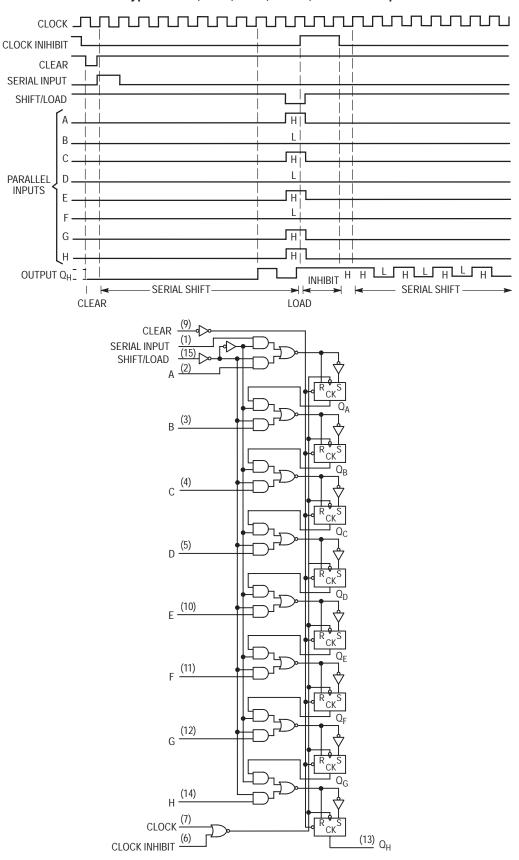
Device	Package	Shipping
SN74LS166N	16 Pin DIP	2000 Units/Box
SN74LS166D	16 Pin	2500/Tape & Reel



FUNCTION TABLE

INPUTS						INTER		
CLEAR	SHIFT/	CLOCK	CLOCK	SERIAL	PARALLEL	OUTF	PUTS	OUTPUT Q _H
CLEAR	LOAD	INHIBIT	CLOCK	SERIAL	A H	Q _A	Q _B	
L	Х	Х	Х	Х	Х	L	L	L
Н	Х	L	L	Х	X	Q_{A0}	Q _{B0}	Q _{H0}
Н	L	L	1	Х	ah	а	b	h
Н	Н	L	1	Н	X	Н	Q_{An}	Q_Gn
Н	Н	L	1	L	X	L	Q _{An}	Q_Gn
Н	Х	Н	1	Х	X	Q _{A0}	Q _{B0}	Q _{H0}

Typical Clear, Shift, Load, Inhibit, and Shift Sequences



DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

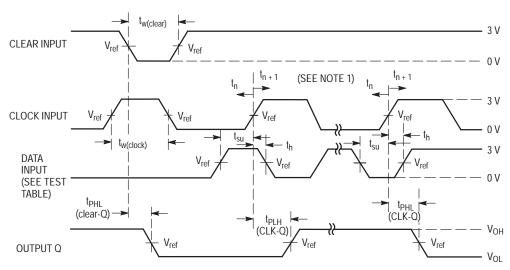
			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs		
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA		
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
M	Output I OW/ Valtage		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table	
	Innut I II CI I Coment			20	μΑ	$V_{CC} = MAX, V_{IN}$	= 2.7 V	
I _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current			38	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

TEST TABLE FOR SYNCHRONOUS INPUTS

DATA INPUT FOR TEST	SHIFT/LOAD	OUTPUT TESTED
Н	0 V	Q _H at t _{n+1}
Serial Input	4.5 V	Q _H at t _{n+8}

AC WAVEFORMS



NOTE 1. t_n = bit time before clocking transition

 t_{n+1} = bit time after one clocking transition

 t_{n+8} = bit time after eight clocking transition

LS166 $V_{ref} = 1.3 V$.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits		Limits		Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions				
f _{MAX}	Maximum Clock Frequency	25	35		MHz					
t _{PHL}	Clear to Output		19	30	ns	$V_{CC} = 5.0 \text{ V}$ $C_{L} = 15 \text{ pF}$				
t _{PLH} t _{PHL}	Clock to Output		23 24	35 35	ns	$C_L = 15 pF$				

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
t _W	Clock Clear Pulse Width	30			ns			
t _s	Mode Control Setup Time	30			ns	V 50V		
t _s	Data Setup Time	20			ns	V _{CC} = 5.0 V		
t _h	Hold Time, Any Input	15			ns			

Hex D Flip-Flop

The LSTTL/MSI SN74LS174 is a high speed Hex D Flip-Flop. The device is used primarily as a 6-bit edge-triggered storage register. The information on the D inputs is transferred to storage during the LOW to HIGH clock transition. The device has a Master Reset to simultaneously clear all flip-flops. The LS174 is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Edge-Triggered D-Type Inputs
- Buffered-Positive Edge-Triggered Clock
- Asynchronous Common Reset
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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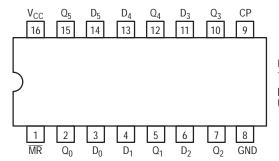
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS174N	16 Pin DIP	2000 Units/Box
SN74LS174D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



NOTE:

LOW

LOADING (Note a)

HIGH

The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

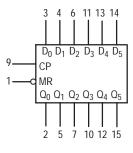
PIN NAMES

$D_0 - D_5$	Data Inputs	0.5 U.L.	0.25 U.L.
CP	Clock (Active HIGH Going Edge) Input	0.5 U.L.	0.25 U.L.
MR	Master Reset (Active LOW) Input	0.5 U.L.	0.25 U.L.
$Q_0 - Q_5$	Outputs	10 U.L.	5 U.L.

NOTES:

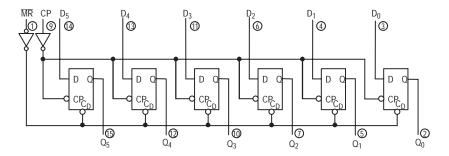
a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



V_{CC} = PIN 16 GND = PIN 8

LOGIC DIAGRAM



V_{CC} = PIN 16 GND = PIN 8

= PIN NUMBERS

FUNCTIONAL DESCRIPTION

The LS174 consists of six edge-triggered D flip-flops with individual D inputs and Q outputs. The Clock (CP) and Master Reset (\overline{MR}) are common to all flip-flops.

Each D input's state is transferred to the corresponding flip-flop's output following the LOW to HIGH Clock (CP) transition.

A LOW input to the Master Reset (\overline{MR}) will force all outputs LOW independent of Clock or Data inputs. The LS174 is useful for applications where the true output only is required and the Clock and Master Reset are common to all storage elements.

TRUTH TABLE

Inputs (t = n, MR = H)	Outputs (t = n+1) Note 1
D	Q
Н	Н
L	L

Note 1: t = n + 1 indicates conditions after next clock.

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = or V_{IL} per Truth T	
V	Output I OW Valtage		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table
	lament HCH Commant			20	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V
Iн	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN}	= 7.0 V
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
Ios	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
Icc	Power Supply Current			26	mA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

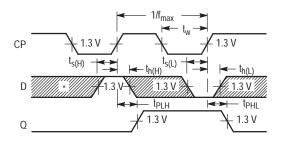
AC CHARACTERISTICS (T_A = 25°C)

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
f _{MAX}	Maximum Input Clock Frequency	30	40		MHz	
t _{PHL}	Propagation Delay, MR to Output		23	35	ns	$V_{CC} = 5.0 \text{ V}$
t _{PLH} t _{PHL}	Propagation Delay, Clock to Output		20 21	30 30	ns	C _L = 15 pF

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	Clock or MR Pulse Width	20			ns	
t _s	Data Setup Time	20			ns	V -50V
t _h	Data Hold Time	5.0			ns	V _{CC} = 5.0 V
t _{rec}	Recovery Time	25			ns	

AC WAVEFORMS



^{*}The shaded areas indicate when the input is permitted to change for predictable output performance.

Figure 1. Clock to Output Delays, Clock Pulse Width, Frequency, Setup and Hold Times Data to Clock

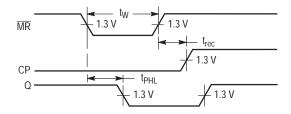


Figure 2. Master Reset to Output Delay, Master Reset Pulse Width, and Master Reset Recovery Time

DEFINITIONS OF TERMS

SETUP TIME (t_s) — is defined as the minimum time required for the correct logic level to be present at the logic input prior to the clock transition from LOW to HIGH in order to be recognized and transferred to the outputs.

 $HOLD\ TIME\ (t_h)$ — is defined as the minimum time following the clock transition from LOW to HIGH that the logic level must be maintained at the input in order to ensure

continued recognition. A negative HOLD TIME indicates that the correct logic level may be released prior to the clock transition from LOW to HIGH and still be recognized.

RECOVERY TIME (t_{rec})—is defined as the minimum time required between the end of the reset pulse and the clock transition from LOW to HIGH in order to recognize and transfer HIGH Data to the Q outputs.

Quad D Flip-Flop

The LSTTL/MSI SN74LS175 is a high speed Quad D Flip-Flop. The device is useful for general flip-flop requirements where clock and clear inputs are common. The information on the D inputs is stored during the LOW to HIGH clock transition. Both true and complemented outputs of each flip-flop are provided. A Master Reset input resets all flip-flops, independent of the Clock or D inputs, when LOW.

The LS175 is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Edge-Triggered D-Type Inputs
- Buffered-Positive Edge-Triggered Clock
- Clock to Output Delays of 30 ns
- Asynchronous Common Reset
- True and Complement Output
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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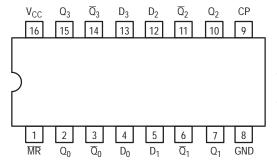
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS175N	16 Pin DIP	2000 Units/Box
SN74LS175D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)

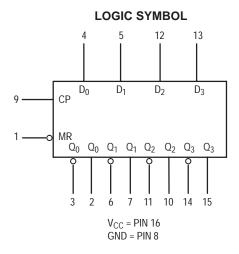


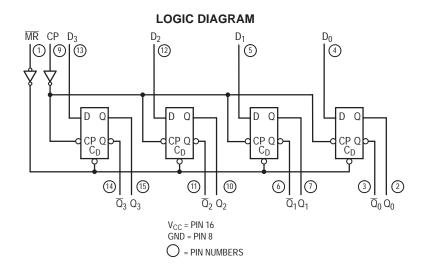
NOTE: The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

		LOADING	(Note a)
PIN NAMES		HIGH	LOW
$D_0 - D_3$	Data Inputs	0.5 U.L.	0.25 U.L.
CP	Clock (Active HIGH Going Edge) Input	0.5 U.L.	0.25 U.L.
MR	Master Reset (Active LOW) Input	0.5 U.L.	0.25 U.L.
$Q_0 - Q_3$	True Outputs	10 U.L.	5 U.L.
$\overline{Q}_0 - \overline{Q}_3$	Complemented Outputs	10 U.L.	5 U.L.

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.





FUNCTIONAL DESCRIPTION

The LS175 consists of four edge-triggered D flip-flops with individual D inputs and Q and \overline{Q} outputs. The Clock and Master Reset are common. The four flip-flops will store the state of their individual D inputs on the LOW to HIGH Clock (CP) transition, causing individual Q and \overline{Q} outputs to

follow. A LOW input on the Master Reset (\overline{MR}) will force all Q outputs LOW and \overline{Q} outputs HIGH independent of Clock or Data inputs.

The LS175 is useful for general logic applications where a common Master Reset and Clock are acceptable.

TRUTH TABLE

Inputs (t = n, MR = H)	Outputs (t =	n+1) Note 1
D	Q	Q
L	L H	H

Note 1: t = n + 1 indicates conditions after next clock.

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input All Inputs	t HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input All Inputs	t LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
V	Output I OW Voltage		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	per Truth Table
	Innut HCH Current			20	μΑ	V _{CC} = MAX, V _{IN} :	= 2.7 V
l t _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
I _{CC}	Power Supply Current			18	mA	$V_{CC} = MAX$	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

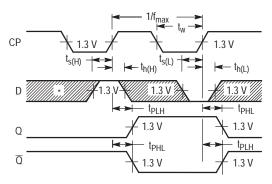
AC CHARACTERISTICS (T_A = 25°C)

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
f _{MAX}	Maximum Input Clock Frequency	30	40		MHz	
t _{PLH} t _{PHL}	Propagation Delay, MR to Output		20 20	30 30	ns	$V_{CC} = 5.0 \text{ V}$ $C_{L} = 15 \text{ pF}$
t _{PLH} t _{PHL}	Propagation Delay, Clock to Output		13 16	25 25	ns	2 1

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	Clock or MR Pulse Width	20			ns	
t _s	Data Setup Time	20			ns	V 50V
t _h	Data Hold Time	5.0			ns	V _{CC} = 5.0 V
t _{rec}	Recovery Time	25			ns	

AC WAVEFORMS



^{*}The shaded areas indicate when the input is permitted to change for predictable output performance.

The state of the s

Figure 2. Master Reset to Output Delay, Master Reset Pulse Width, and Master Reset Recovery Time

Figure 1. Clock to Output Delays, Clock Pulse Width, Frequency, Setup and Hold Times Data to Clock

DEFINITIONS OF TERMS

SETUP TIME (t_s) — is defined as the minimum time required for the correct logic level to be present at the logic input prior to the clock transition from LOW to HIGH in order to be recognized and transferred to the outputs.

HOLD TIME (t_h) — is defined as the minimum time following the clock transition from LOW to HIGH that the logic level must be maintained at the input in order to ensure

continued recognition. A negative HOLD TIME indicates that the correct logic level may be released prior to the clock transition from LOW to HIGH and still be recognized.

RECOVERY TIME (t_{rec})—is defined as the minimum time required between the end of the reset pulse and the clock transition from LOW to HIGH in order to recognize and transfer HIGH Data to the Q outputs.

Presettable 4-Bit Binary Up/Down Counter

The SN74LS193 is an UP/DOWN MODULO-16 Binary Counter. Separate Count Up and Count Down Clocks are used and the circuits can operate synchronously. The outputs change state synchronous with the LOW-to-HIGH transitions on the clock inputs.

Separate Terminal Count Up and Terminal Count Down outputs are provided which are used as the clocks for a subsequent stages without extra logic, thus simplifying multistage counter designs. Individual preset inputs allow the circuits to be used as programmable counters. Both the Parallel Load (\overline{PL}) and the Master Reset (MR) inputs asynchronously override the clocks.

- Low Power . . . 95 mW Typical Dissipation
- High Speed . . . 40 MHz Typical Count Frequency
- Synchronous Counting
- Asynchronous Master Reset and Parallel Load
- Individual Preset Inputs
- Cascading Circuitry Internally Provided
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
l _{OL}	Output Current – Low			8.0	mA



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PLASTIC N SUFFIX CASE 648

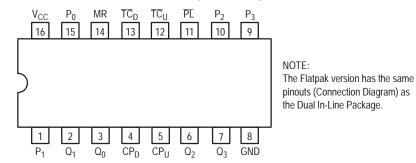


SOIC D SUFFIX CASE 751B

ORDERING INFORMATION

Device	Package	Shipping
SN74LS193N	16 Pin DIP	2000 Units/Box
SN74LS193D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)

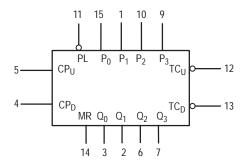


		LOADING	(Note a)
PIN NAMES		HIGH	LOW
CP_U	Count Up Clock Pulse Input	0.5 U.L.	0.25 U.L.
CPD	Count Down Clock Pulse Input	0.5 U.L.	0.25 U.L.
MR	Asynchronous Master Reset (Clear) Input	0.5 U.L.	0.25 U.L.
PL	Asynchronous Parallel Load (Active LOW) Input	0.5 U.L.	0.25 U.L.
P_n	Parallel Data Inputs	0.5 U.L.	0.25 U.L.
Qn	Flip–Flop Outputs	10 U.L.	5 U.L.
TCD	Terminal Count Down (Borrow) Output	10 U.L.	5 U.L.
TCII	Terminal Count Up (Carry) Output	10 U.L.	5 U.L.

NOTES:

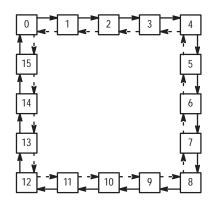
a) 1 TTL Unit Load (U.L.) = 40 μA HIGH/1.6 mA LOW.

LOGIC SYMBOL



V_{CC} = PIN 16 GND = PIN 8

STATE DIAGRAM

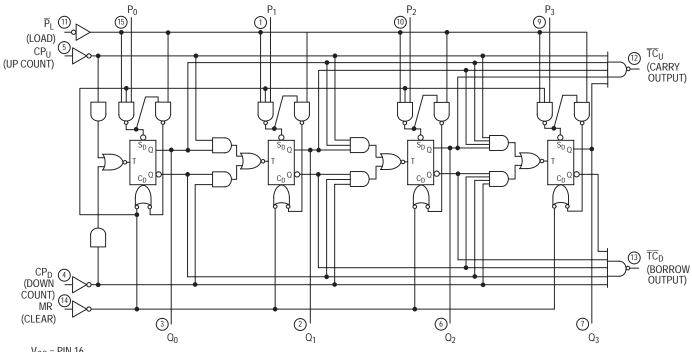


LOGIC EQUATIONS FOR TERMINAL COUNT

$$\begin{split} \overline{TC}_U &= \underline{Q}_0 \cdot \underline{Q}_1 \cdot \underline{Q}_2 \cdot \underline{Q}_3 \cdot \overline{CP}_U \\ \overline{TC}_D &= \overline{Q}_0 \cdot \overline{Q}_1 \cdot \overline{Q}_2 \cdot \overline{Q}_3 \cdot \overline{CP}_D \end{split}$$

COUNT UP COUNT DOWN

LOGIC DIAGRAM



V_{CC} = PIN 16 GND = PIN 8

= PIN NUMBERS

FUNCTIONAL DESCRIPTION

The LS193 is a 4-Bit Binary Synchronous UP/DOWN (Reversable) Counter. Each circuit contains four master/slave flip-flops, with internal gating and steering logic to provide master reset, individual preset, count up and count down operations.

Each flip-flop contains JK feedback from slave to master such that a LOW-to-HIGH transition on its T input causes the slave, and thus the Q output to change state. Synchronous switching, as opposed to ripple counting, is achieved by driving the steering gates of all stages from a common Count Up line and a common Count Down line, thereby causing all state changes to be initiated simultaneously. A LOW-to-HIGH transition on the Count Up input will advance the count by one; a similar transition on the Count Down input will decrease the count by one. While counting with one clock input, the other should be held HIGH. Otherwise, the circuit will either count by twos or not at all, depending on the state of the first flip-flop, which cannot toggle as long as either Clock input is LOW.

The Terminal Count Up (\overline{TC}_U) and Terminal Count Down (\overline{TC}_D) outputs are normally HIGH. When a circuit has

reached the maximum count state of 15, the next HIGH-to-LOW transition of the Count Up Clock will cause \overline{TC}_U to go LOW. \overline{TC}_U will stay LOW until CP_U goes HIGH again, thus effectively repeating the Count Up Clock, but delayed by two gate delays. Similarly, the \overline{TC}_D output will go LOW when the circuit is in the zero state and the Count Down Clock goes LOW. Since the TC outputs repeat the clock waveforms, they can be used as the clock input signals to the next higher order circuit in a multistage counter.

Each circuit has an asynchronous parallel load capability permitting the counter to be preset. When the Parallel Load (\overline{PL}) and the Master Reset (MR) inputs are LOW, information present on the Parallel Data inputs (P_0, P_3) is loaded into the counter and appears on the outputs regardless of the conditions of the clock inputs. A HIGH signal on the Master Reset input will disable the preset gates, override both Clock inputs, and latch each Q output in the LOW state. If one of the Clock inputs is LOW during and after a reset or load operation, the next LOW-to-HIGH transition of that Clock will be interpreted as a legitimate signal and will be counted.

MODE SELECT TABLE

MR	PL	CPU	CPD	MODE
Н	Х	Х	Х	Reset (Asyn.)
L	L	Χ	X	Preset (Asyn.)
L	Н	Н	Н	No Change
L	Н	Г	Н	Count Up
L	Н	H		Count Down

L = LOW Voltage Level

H = HIGH Voltage Level

X = Don't Care

 \int = LOW-to-HIGH Clock Transition

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN$, $I_{OH} = MAX$, $V_{IN} = V_{IH}$ or V_{IL} per Truth Table	
.,	Outrant LOW Vallance		0.25	0.4	٧	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table
1	January I II Cl. I. Command			20	μΑ	$V_{CC} = MAX, V_{IN}$	= 2.7 V
l _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
Icc	Power Supply Current			34	mA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
f _{MAX}	Maximum Clock Frequency	25	32		MHz	
t _{PLH} t _{PHL}	CP _U Input to TC _U Output		17 18	26 24	ns	
t _{PLH} t _{PHL}	CP _D Input to TC _D Output		16 15	24 24	ns	V _{CC} = 5.0 V C _L = 15 pF
t _{PLH} t _{PHL}	Clock to Q		27 30	38 47	ns	C _L = 15 pF
t _{PLH} t _{PHL}	PL to Q		24 25	40 40	ns	
t _{PHL}	MR Input to Any Output		23	35	ns	

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	Any Pulse Width	20			ns	
t _s	Data Setup Time	20			ns	V 50V
t _h	Data Hold Time	5.0			ns	$V_{CC} = 5.0 \text{ V}$
t _{rec}	Recovery Time	40			ns	

DEFINITIONS OF TERMS

SETUP TIME (t_s) is defined as the minimum time required for the correct logic level to be present at the logic input prior to the \overline{PL} transition from LOW-to-HIGH in order to be recognized and transferred to the outputs.

HOLD TIME (t_h) is defined as the minimum time following the \overline{PL} transition from LOW-to-HIGH that the logic level must be maintained at the input in order to ensure continued

recognition. A negative HOLD TIME indicates that the correct logic level may be released prior to the \overline{PL} transition from LOW-to-HIGH and still be recognized.

RECOVERY TIME (t_{rec}) is defined as the minimum time required between the end of the reset pulse and the clock transition from LOW-to-HIGH in order to recognize and transfer HIGH data to the Q outputs.

AC WAVEFORMS

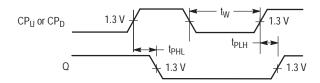


Figure 1.

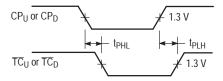


Figure 2.

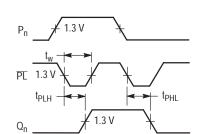
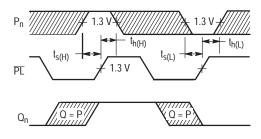
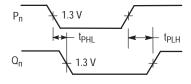


Figure 4.



* The shaded areas indicate when the input is permitted to change for predictable output performance

Figure 6.



NOTE: $\overline{PL} = LOW$ Figure 3.

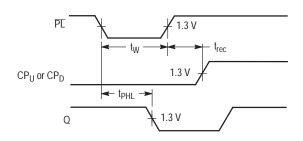


Figure 5.

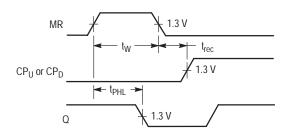


Figure 7.

4-Bit Bidirectional Universal Shift Register

The SN74LS194A is a High Speed 4-Bit Bidirectional Universal Shift Register. As a high speed multifunctional sequential building block, it is useful in a wide variety of applications. It may be used in serial-serial, shift left, shift right, serial-parallel, parallel-serial, and parallel-parallel data register transfers. The LS194A is similar in operation to the LS195A Universal Shift Register, with added features of shift left without external connections and hold (do nothing) modes of operation. It utilizes the Schottky diode clamped process to achieve high speeds and is fully compatible with all ON Semiconductor TTL families.

- Typical Shift Frequency of 36 MHz
- Asynchronous Master Reset
- Hold (Do Nothing) Mode
- Fully Synchronous Serial or Parallel Data Transfers
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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LOW POWER SCHOTTKY



PLASTIC N SUFFIX CASE 648

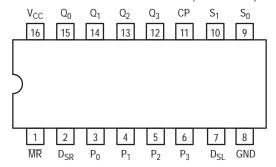


SOIC D SUFFIX CASE 751B

ORDERING INFORMATION

Device	Package	Shipping
SN74LS194AN	16 Pin DIP	2000 Units/Box
SN74LS194AD	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)

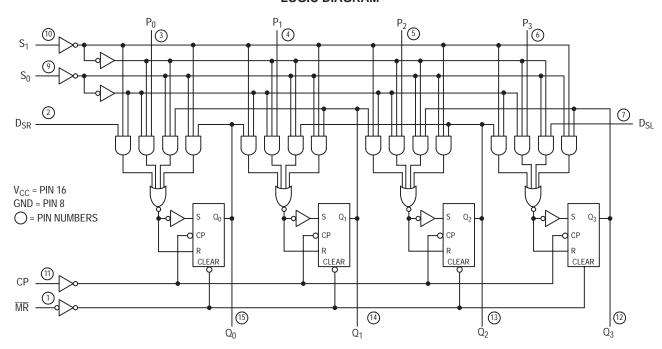


		LOADING (Note a)				
PIN NAMES		HIGH	LOW			
S ₀ , S ₁	Mode Control Inputs	0.5 U.L.	0.25 U.L.			
$P_0 - P_3$	Parallel Data Inputs	0.5 U.L.	0.25 U.L.			
D_SR	Serial (Shift Right) Data Input	0.5 U.L.	0.25 U.L.			
D_SL	Serial (Shift Left) Data Input	0.5 U.L.	0.25 U.L.			
CP	Clock (Active HIGH Going Edge) Input	0.5 U.L.	0.25 U.L.			
MR	Master Reset (Active LOW) Input	0.5 U.L.	0.25 U.L.			
$Q_0 - Q_3$	Parallel Outputs	10 U.L.	5 U.L.			

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The Logic Diagram and Truth Table indicate the functional characteristics of the LS194A 4-Bit Bidirectional Shift Register. The LS194A is similar in operation to the ON Semiconductor LS195A Universal Shift Register when used in serial or parallel data register transfers. Some of the common features of the two devices are described below:

All data and mode control inputs are edge-triggered, responding only to the LOW to HIGH transition of the Clock (CP). The only timing restriction, therefore, is that the mode control and selected data inputs must be stable one set-up time prior to the positive transition of the clock pulse.

The register is fully synchronous, with all operations taking place in less than 15 ns (typical) making the device especially useful for implementing very high speed CPUs, or the memory buffer registers.

The four parallel data inputs (P_0, P_1, P_2, P_3) are D-type inputs. When both S_0 and S_1 are HIGH, the data appearing on P_0 , P_1 , P_2 , and P_3 inputs is transferred to the Q_0 , Q_1 , Q_2 , and Q_3 outputs respectively following the next LOW to HIGH transition of the clock.

The asynchronous Master Reset (\overline{MR}) , when LOW, overrides all other input conditions and forces the Q outputs LOW.

Special logic features of the LS194A design which increase the range of application are described below:

Two mode control inputs (S_0, S_1) determine the synchronous operation of the device. As shown in the Mode Selection Table, data can be entered and shifted from left to right (shift right, $Q_0 \rightarrow Q_1$, etc.) or right to left (shift left, $Q_3 \rightarrow Q_2$, etc.), or parallel data can be entered loading all four bits of the register simultaneously. When both S_0 and S_1 , are LOW, the existing data is retained in a "do nothing" mode without restricting the HIGH to LOW clock transition.

D-type serial data inputs (D_{SR} , D_{SL}) are provided on both the first and last stages to allow multistage shift right or shift left data transfers without interfering with parallel load operation.

MODE SELECT — TRUTH TABLE

OPERATING MODE	INPUTS							OUTPUTS				
OPERATING MODE	MR	S ₁	S ₀	D _{SR}	D _{SL}	P _n	Q_0	Q_1	Q_2	Q_3		
Reset	L	Х	Х	Х	Х	Х	L	L	L	L		
Hold	Н	I	I	Х	Х	Х	q_0	q ₁	q_2	q_3		
Shift Left	H H	h h	I I	X X	l h	X X	9 ₁ 9 ₁	q ₂ q ₂	q ₃ q ₃	L H		
Shift Right	H H	I I	h h	l h	X X	X	L H	q ₀	9 ₁ 9 ₁	q ₂ q ₂		
Parallel Load	Н	h	h	Х	Х	P _n	P ₀	P ₁	P ₂	P ₃		

L = LOW Voltage Level

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits							
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions				
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for			
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for			
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$				
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH}$ or V_{IL} per Truth Table				
.,			0.25	0.4	٧	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$			
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table			
	Innut HCH Current			20	μΑ	V _{CC} = MAX, V _{IN} = 2.7 V				
IН	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V				
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V				
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX				
I _{CC}	Power Supply Current			23	mA	V _{CC} = MAX				

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
f _{MAX}	Maximum Clock Frequency	25	36		MHz	
t _{PLH} t _{PHL}	Propagation Delay, Clock to Output		14 17	22 26	ns	$V_{CC} = 5.0 \text{ V}$ $C_{I} = 15 \text{ pF}$
t _{PHL}	Propagation Delay, MR to Output		19	30	ns	1

H = HIGH Voltage Level

X = Don't Care

I = LOW voltage level one set-up time prior to the LOW to HIGH clock transition

h = HIGH voltage level one set-up time prior to the LOW to HIGH clock transition

 $p_n(q_n) = Lower$ case letters indicate the state of the referenced input (or output) one set-up time prior to the LOW to HIGH clock transition.

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

		Limits		Limits		
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	Clock or MR Pulse Width	20			ns	
t _s	Mode Control Setup Time	30			ns	
t _s	Data Setup Time	20			ns	V _{CC} = 5.0 V
t _h	Hold time, Any Input	0			ns	
t _{rec}	Recovery Time	25			ns	

DEFINITIONS OF TERMS

SETUP TIME(t_s) —is defined as the minimum time required for the correct logic level to be present at the logic input prior to the clock transition from LOW to HIGH in order to be recognized and transferred to the outputs.

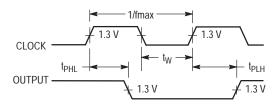
HOLD TIME (t_h) — is defined as the minimum time following the clock transition from LOW to HIGH that the logic level must be maintained at the input in order to ensure

continued recognition. A negative HOLD TIME indicates that the correct logic level may be released prior to the clock transition from LOW to HIGH and still be recognized.

RECOVERY TIME (t_{rec}) — is defined as the minimum time required between the end of the reset pulse and the clock transition from LOW to HIGH in order to recognize and transfer HIGH Data to the Q outputs.

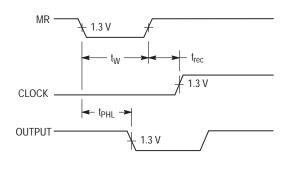
AC WAVEFORMS

The shaded areas indicate when the input is permitted to change for predictable output performance.



OTHER CONDITIONS: $S_1 = L$, $\overline{MR} = H$, $S_0 = H$

Figure 1. Clock to Output Delays Clock Pulse Width and f_{max}



OTHER CONDITIONS: S_0 , $S_1 = H$ $P_0 = P_1 = P_2 = P_3 = H$

Figure 2. Master Reset Pulse Width, Master Reset to Output Delay and Master Reset to Clock Recovery Time

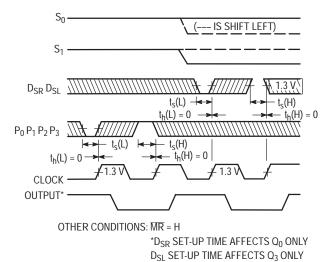


Figure 3. Setup (t_s) and Hold (t_h) Time for Serial Data (D_{SR}, D_{SL}) and Parallel Data (P_0, P_1, P_2, P_3)

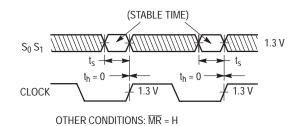


Figure 4. Setup (t_s) and Hold (t_h) Time for S Input

Universal 4-Bit Shift Register

The SN74LS195A is a high speed 4-Bit Shift Register offering typical shift frequencies of 39 MHz. It is useful for a wide variety of register and counting applications. It utilizes the Schottky diode clamped process to achieve high speeds and is fully compatible with all ON Semiconductor TTL products.

- Typical Shift Right Frequency of 39 MHz
- Asynchronous Master Reset
- J, K Inputs to First Stage
- Fully Synchronous Serial or Parallel Data Transfers
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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PLASTIC N SUFFIX CASE 648

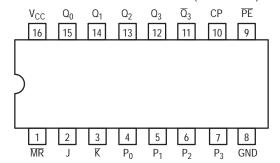


SOIC D SUFFIX CASE 751B

ORDERING INFORMATION

Device	Package	Shipping
SN74LS195AN	16 Pin DIP	2000 Units/Box
SN74LS195AD	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



NOTE:

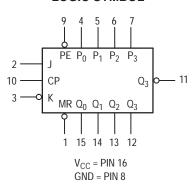
The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

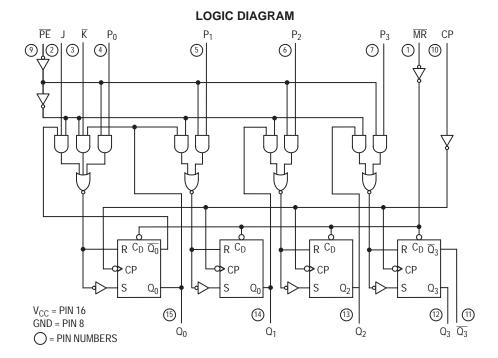
		LOADING	(Note a)
PIN NAMES		HIGH	LOW
PE	Parallel Enable (Active LOW) Input	0.5 U.L.	0.25 U.L.
$P_0 - P_3$	Parallel Data Inputs	0.5 U.L.	0.25 U.L.
J	First Stage J (Active HIGH) Input	0.5 U.L.	0.25 U.L.
K	First Stage K (Active LOW) Input	0.5 U.L.	0.25 U.L.
CP	Clock (Active HIGH Going Edge) Input	0.5 U.L.	0.25 U.L.
MR	Master Reset (Active LOW) Input	0.5 U.L.	0.25 U.L.
$Q_0 - Q_3$	Parallel Outputs	10 U.L.	5 U.L.
\overline{Q}_3	Complementary Last Stage Output	10 U.L.	5 U.L.

NOTES:

a) 1 TTL Unit Load (U.L.) = $40 \mu A HIGH/1.6 mA LOW$.

LOGIC SYMBOL





FUNCTIONAL DESCRIPTION

The Logic Diagram and Truth Table indicate the functional characteristics of the LS195A 4-Bit Shift Register. The device is useful in a wide variety of shifting, counting and storage applications. It performs serial, parallel, serial to parallel, or parallel to serial data transfers at very high speeds.

The LS195A has two primary modes of operation, shift right $(Q_0 \rightarrow Q_1)$ and parallel load which are controlled by the state of the Parallel Enable (\overline{PE}) input. When the PE input is HIGH, serial data enters the first flip-flop Q_0 via the J and \overline{K} inputs and is shifted one bit in the direction $Q_0 \rightarrow Q_1 \rightarrow Q_2 \rightarrow Q_3$ following each LOW to HIGH clock transition. The \overline{JK} inputs provide the flexibility of the JK type input for special applications, and the simple D type input for general applications by tying the two pins together. When the \overline{PE}

input is LOW, the LS195A appears as four common clocked D flip-flops. The data on the parallel inputs $P_0,\,P_1,\,P_2,\,P_3$ is transferred to the respective $Q_0,\,Q_1,\,Q_2,\,Q_3$ outputs following the LOW to HIGH clock transition. Shift left operations $(Q_3\to Q_2)$ can be achieved by tying the Q_n Outputs to the P_{n-1} inputs and holding the \overline{PE} input LOW.

All serial and parallel data transfers are synchronous, occurring after each LOW to HIGH clock transition. Since the LS195A utilizes edge-triggering, there is no restriction on the activity of the J, \overline{K} , P_n and \overline{PE} inputs for logic operation — except for the set-up and release time requirements.

A LOW on the asynchronous Master Reset (\overline{MR}) input sets all Q outputs LOW, independent of any other input condition.

MODE SELECT — TRUTH TABL	
WICH SELECT — IRLIE IARI	_

OPERATING MODES	INPUTS					OUTPUTS				
OI ERATING MODES	MR	PE	J	K	Pn	Q_0	Q ₁	Q_2	Q ₃	\overline{Q}_3
Asynchronous Reset	L	Х	Х	Х	Х	L	L	L	L	Н
Shift, Set First Stage	Н	h	h	h	Х	Н	q ₀	q ₁	q_2	\overline{q}_2
Shift, Reset First	Н	h	1	1	Х	L	q_0	q_1	q_2	\overline{q}_2
Shift, Toggle First Stage	Н	h	h	1	Х	\overline{q}_0	q_0	q_1	q_2	\overline{q}_2
Shift, Retain First Stage	Н	h	ı	h	Х	q_0	q_0	q_1	q_2	$\overline{q_2}$
Parallel Load	Н	I	Х	Χ	p _n	p ₀	p ₁	p ₂	p ₃	\overline{p}_3

L = LOW voltage levels

H = HIGH voltage levels

X = Don't Care

I = LOW voltage level one set-up time prior to the LOW to HIGH clock transition.

h = HIGH voltage level one set-up time prior to the LOW to HIGH clock transition.

 p_n (q_n) = Lower case letters indicate the state of the referenced input (or output) one set-up time prior to the LOW to HIGH clock transition.

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
W	Outrot I OW Valtage		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	per Truth Table
	January I II Cold Command			20	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V
Iн	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
Icc	Power Supply Current			21	mA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
f _{MAX}	Maximum Clock Frequency	30	39		MHz	
t _{PLH} t _{PHL}	Propagation Delay, Clock to Output		14 17	22 26	ns	V _{CC} = 5.0 V C _L = 15 pF
t _{PHL}	Propagation Delay, MR to Output		19	30	ns	2 1

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	CP Clock Pulse Width	16			ns	
t _W	MR Pulse Width	12			ns	
t _s	PE Setup Time	25			ns	
t _s	Data Setup Time	15			ns	V _{CC} = 5.0 V
t _{rec}	Recovery Time	25			ns	
t _{rel}	PE Release Time			10	ns	
t _h	Data Hold Time	0			ns	

DEFINITIONS OF TERMS

SETUP $\text{TIME}(t_s)$ —is defined as the minimum time required for the correct logic level to be present at the logic input prior to the clock transition from LOW to HIGH in order to be recognized and transferred to the outputs.

HOLD TIME (t_h) — is defined as the minimum time following the clock transition from LOW to HIGH that the logic level must be maintained at the input in order to ensure

continued recognition. A negative HOLD TIME indicates that the correct logic level may be released prior to the clock transition from LOW to HIGH and still be recognized.

RECOVERY TIME (t_{rec}) —is defined as the minimum time required between the end of the reset pulse and the clock transition from LOW to HIGH in order to recognize and transfer HIGH Data to the Q outputs.

AC WAVEFORMS

The shaded areas indicate when the input is permitted to change for predictable output performance.

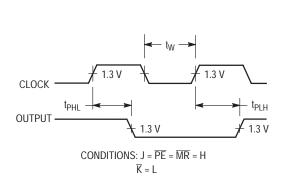


Figure 1. Clock to Output Delays and Clock Pulse Width

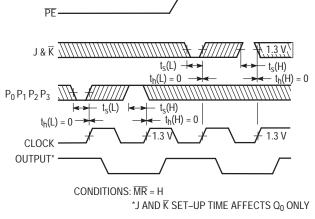


Figure 3. Setup (t_s) and Hold (t_h) Time for Serial Data $(J \& \overline{K})$ and Parallel Data (P_0, P_1, P_2, P_3)

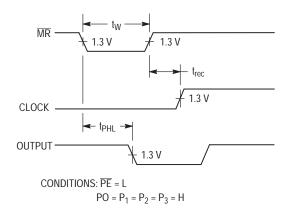


Figure 2. Master Reset Pulse Width, Master Reset to Output Delay and Master Reset to Clock Recovery Time

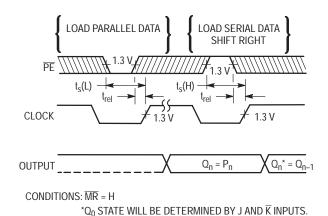


Figure 4. Setup (t_s) and Hold (t_h) Time for \overline{PE} Input

Dual Monostable Multivibrators with Schmitt-Trigger Inputs

Each multivibrator of the LS221 features a negative-transition-triggered input and a positive-transition-triggered input either of which can be used as an inhibit input.

Pulse triggering occurs at a voltage level and is not related to the transition time of the input pulse. Schmitt-trigger input circuitry for B input allows jitter-free triggering for inputs as slow as 1 volt/second, providing the circuit with excellent noise immunity. A high immunity to V_{CC} noise is also provided by internal latching circuitry.

Once triggered, the outputs are independent of further transitions of the inputs and are a function of the timing components. The output pulses can be terminated by the overriding clear. Input pulse width may be of any duration relative to the output pulse width. Output pulse width may be varied from 35 nanoseconds to a maximum of 70 s by choosing appropriate timing components. With $R_{ext} = 2.0 \text{ k}\Omega$ and $C_{ext} = 0$, a typical output pulse of 30 nanoseconds is achieved. Output rise and fall times are independent of pulse length.

Pulse width stability is achieved through internal compensation and is virtually independent of V_{CC} and temperature. In most applications, pulse stability will only be limited by the accuracy of external timing components.

Jitter-free operation is maintained over the full temperature and V_{CC} ranges for greater than six decades of timing capacitance (10 pF to 10 μF), and greater than one decade of timing resistance (2.0 to 100 $k\Omega$ for the SN74LS221). Pulse width is defined by the relationship: $t_w(\text{out}) = C_{ext} R_{ext} \ln 2.0 \approx 0.7 \, C_{ext} \, R_{ext};$ where t_W is in ns if C_{ext} is in pF and R_{ext} is in $k\Omega$. If pulse cutoff is not critical, capacitance up to 1000 μF and resistance as low as 1.4 $k\Omega$ may be used. The range of jitter-free pulse widths is extended if V_{CC} is 5.0 V and 25°C temperature.

- SN74LS221 is a Dual Highly Stable One-Shot
- Overriding Clear Terminates Output Pulse
- Pin Out is Identical to SN74LS123

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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N SUFFIX CASE 648

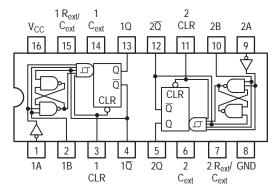


SOIC D SUFFIX CASE 751B

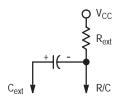
ORDERING INFORMATION

Device	Package	Shipping
SN74LS221N	16 Pin DIP	2000 Units/Box
SN74LS221D	16 Pin	2500/Tape & Reel

(TOP VIEW)



Positive logic: Low input to clear resets Q low and $\overline{\mathbf{Q}}$ high regardless of dc levels at A or B inputs.



FUNCTION TABLE (EACH MONOSTABLE)

INP	UTS		OUTPUTS		
CLEAR	Α	В	Q	Q	
L	Х	Χ	L	Н	
Х	Н	Χ	L	Н	
Х	Х	L	L	Н	
Н	L	1		□	
Н	↓	Н	厂		
*↑	L	Н	几	디	

^{*}See operational notes — Pulse Trigger Modes

	TYPICAL	MAXIMUM
TYPE	POWER	OUTPUT PULSE
	DISSIPATION	LENGTH
SN74LS221	23 mW	70 s

OPERATIONAL NOTES

Once in the pulse trigger mode, the output pulse width is determined by $t_W = R_{ext}C_{ext}In2$, as long as R_{ext} and C_{ext} are within their minimum and maximum valves and the duty cycle is less than 50%. This pulse width is essentially independent of V_{CC} and temperature variations. Output pulse widths varies typically no more than ±0.5% from device to device.

If the duty cycle, defined as being $100 \cdot \frac{t_W}{T}$ where T is the period of the input pulse, rises above 50%, the output pulse width will become shorter. If the duty cycle varies between low and high valves, this causes the output pulse width to vary in length, or jitter. To reduce jitter to a minimum, Rext should be as large as possible. (Jitter is independent of C_{ext}). With $R_{ext} = 100K$, jitter is not appreciable until the duty cycle approaches 90%.

Although the LS221 is pin-for-pin compatible with the LS123, it should be remembered that they are not functionally identical. The LS123 is retriggerable so that the output is dependent upon the input transitions once it is high. This is not the case for the LS221. Also note that it is recommended to externally ground the LS123 Cext pin. However, this cannot be done on the LS221.

The SN74LS221 is a dual, monolithic, non-retriggerable, high-stability one shot. The output pulse width, tw can be varied over 9 decades of timing by proper selection of the external timing components, Rext and Cext.

Pulse triggering occurs at a voltage level and is, therefore, independent of the input slew rate. Although all three inputs have this Schmitt-trigger effect, only the B input should be used for very long transition triggers ($\geq 1.0 \mu V/s$). High immunity to V_{CC} noise (typically 1.5 V) is achieved by internal latching circuitry. However, standard V_{CC} bypassing is strongly recommended.

The LS221 has four basic modes of operation.

Clear Mode: If the clear input is held low, irregardless of

the previous output state and other input

states, the Q output is low.

Inhib-If either the A input is high or the B input is it Mode:

low, once the Q output goes low, it cannot

be retriggered by other inputs.

Pulse Trigger

Mode: A transition of the A or B inputs as indicated in the functional truth table will trigger the Q output to go high for a duration determined

by the t_W equation described above; Q will go low for a corresponding length of time.

The Clear input may also be used to trigger an output pulse, but special logic preconditioning on the A or B inputs must be done

Following any output triggering action using the A or B inputs, the A input must be set high OR the B input must be set low to allow Clear to be used as a trigger. Inputs should then be set up per the truth table (without triggering the output) to allow Clear to be used a trigger for the

If the Clear pin is routinely being used to trigger the output pulse, the A or B inputs must be toggled as described above before and between each Clear trigger

event.

output pulse.

as follows:

Once triggered, as long as the output remains high, all input transitions (except

overriding Clear) are ignored.

Overriding

Clear Mode: If the Q output is high, it may be forced low

by bringing the clear input low.

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Tes	st Conditions
V _{T+}	Positive-Going Threshold Voltage at C Input		1.0	2.0	V	V _{CC} = MIN	
V _{T-}	Negative-Going Threshold Voltage at C Input	0.7	0.8		V	V _{CC} = MIN	
V _{T+}	Positive-Going Threshold Voltage at B Input		1.0	2.0	V	V _{CC} = MIN	
V _{T-}	Negative-Going Threshold Voltage at B Input	0.8	0.9		V	V _{CC} = MIN	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu A Input	t HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for A Input	
V _{IK}	Input Clamp Voltage			-1.5	٧	V _{CC} = MIN, I _{IN} = -18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.4		٧	V _{CC} = MIN, I _{OH} =	= MAX
V _{OL}	Output LOW Voltage		0.35	0.5	٧	I _{OL} = 8.0 mA	V _{CC} = MIN
1	In most I II Cl I Commont			20	μΑ	$V_{CC} = MAX, V_{IN}$	= 2.7 V
Iн	Input HIGH Current			0.1	mA	$V_{CC} = MAX, V_{IN}$	= 7.0 V
I _{IL}	Input LOW Current Input A Input B Clear			-0.4 -0.8 -0.8	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
Icc	Power Supply Current Quiescent		4.7	11	mA	V _{CC} = MAX	
	Triggered		19	27]		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (V $_{CC}$ = 5.0 V, T_A = 25°C)

	From	То	Limits		Limits						
Symbol	(Input)	(Output)	Min	Тур	Max	Unit	Test Conditions				
	А	Q		45	70						
t _{PLH}	В	Q		35	55	ns					
	А	Q		50	80			C 90 × E D 20 O			
t _{PHL}	В	Q		40	65	ns	ris	115	115		C_{ext} = 80 pF, R_{ext} = 2.0 Ω
t _{PHL}	Clear	Q		35	55	ns	$C_{L} = 15 \text{ pF},$				
t _{PLH}	Clear	Q		44	65	ns	See Figure 1				
			70	120	150			C_{ext} = 80 pF, R_{ext} = 2.0 Ω			
	A 0.5 D	Q or $\overline{\mathbb{Q}}$	20	47	70	ns		$C_{\text{ext}} = 0$, $R_{\text{ext}} = 2.0 \text{ k}\Omega$			
t _{W(out)}	A or B	Q OF Q	600	670	750			C_{ext} = 100 pF, R_{ext} = 10 k Ω			
			6.0	6.9	7.5	ms		$C_{ext} = 1.0 \mu F, R_{ext} = 10 k\Omega$			

AC SETUP REQUIREMENTS (V_{CC} = 5.0 V, T_A = $25^{\circ}C$)

				Limits				
Symbol	Parameter	Parameter				Unit		
	Rate of Rise or Fall of Input Pulse							
dv/dt		Schmitt, B	1.0			V/s		
		Logic Input, A	1.0			V/μs		
	Input Pulse Width							
t _W		A or B, t _{W(in)}	40			ns		
		Clear, t _W (clear)	40					
t _s	Clear-Inactive-State Setup Time		15			ns		
R _{ext}	External Timing Resistance		1.4		100	kΩ		
C _{ext}	External Timing Capacitance		0		1000	μF		
	Output Duty Cycle							
		$RT = 2.0 \text{ k}\Omega$			50	%		
		$R_T = MAX R_{ext}$			90			

AC WAVEFORMS

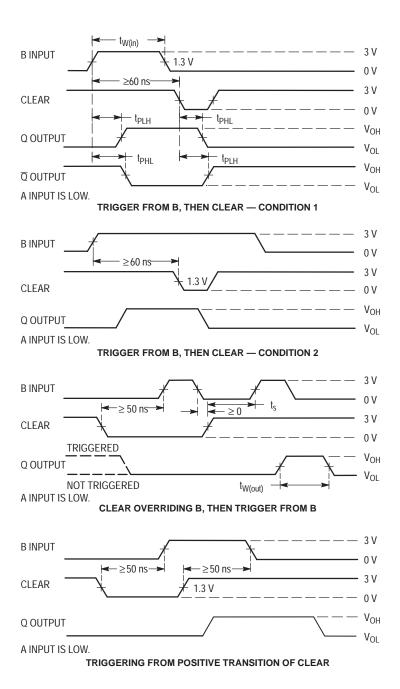


Figure 1.

SN74LS240 SN74LS244

Octal Buffer/Line Driver with 3-State Outputs

The SN74LS240 and SN74LS244 are Octal Buffers and Line Drivers designed to be employed as memory address drivers, clock drivers and bus-oriented transmitters/receivers which provide improved PC board density.

- Hysteresis at Inputs to Improve Noise Margins
- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Input Clamp Diodes Limit High-Speed Termination Effects

GUARANTEED OPERATING RANGES

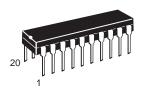
Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-3.0	mA
				-15	mA
I _{OL}	Output Current – Low			24	mA



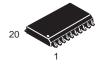
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PLASTIC N SUFFIX CASE 738



SOIC DW SUFFIX CASE 751D

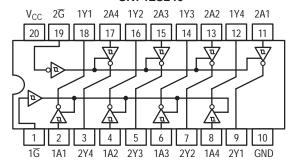
ORDERING INFORMATION

Device	Package	Shipping
SN74LS240N	16 Pin DIP	1440 Units/Box
SN74LS240DW	16 Pin	2500/Tape & Reel
SN74LS244N	16 Pin DIP	1440 Units/Box
SN74LS244DW	16 Pin	2500/Tape & Reel

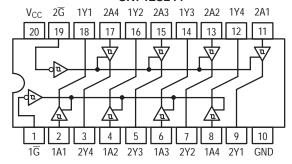
SN74LS240 SN74LS244

LOGIC AND CONNECTION DIAGRAMS DIP (TOP VIEW)

SN74LS240



SN74LS244



TRUTH TABLES

SN74LS240

INP	OUTPUT	
1 G , 2 G	D	001101
L	L	Н
L	Н	L
Н	Χ	(Z)

SN74LS244

INP	OUTPUT	
1G, 2G	D	001701
L	L	L
L	Н	Н
Н	Х	(Z)

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial Z = HIGH Impedance

SN74LS240 SN74LS244

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	•	Min	Тур	Max	Unit	Test	Conditions
V _{IH}	Input HIGH Voltage		2.0			٧	Guaranteed Inpu All Inputs	t HIGH Voltage for
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for
$V_{T+}-V_{T-}$	Hysteresis		0.2	0.4		V	V _{CC} = MIN	
V _{IK}	Input Clamp Diode Volt	age		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA
V _{OH}	Output HIGH Voltage		2.4	3.4		V	V _{CC} = MIN, I _{OH} =	= -3.0 mA
VOH	Output HIGH Voltage		2.0			V	V _{CC} = MIN, I _{OH} = MAX	
	Output LOW Voltage			0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}				0.35	0.5	V	I _{OL} = 24 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table
l _{OZH}	Output Off Current HIGH				20	μΑ	V _{CC} = MAX, V _{OUT} = 2.7 V	
I _{OZL}	Output Off Current LOW				-20	μА	$V_{CC} = MAX, V_{OUT} = 0.4 V$	
l	Input HIGH Current				20	μΑ	$V_{CC} = MAX, V_{IN} = 2.7 V$	
t _{IH}	input riiGri Curient				0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current				-0.2	mA	$V_{CC} = MAX, V_{IN}$	= 0.4 V
los	Output Short Circuit Cu	rrent (Note 1)	-40		-225	mA	V _{CC} = MAX	
	Power Supply Current Total, Output HIGH				27			
	Total, Output LOW	LS240			44	1		
I _{CC}		LS244			46	mA	$V_{CC} = MAX$	
	Total at HIGH Z	LS240			50	1		
		LS244			54	1		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay, Data to Output LS240		9.0 12	14 18	ns	
t _{PLH} t _{PHL}	Propagation Delay, Data to Output LS244		12 12	18 18	ns	$C_L = 45 \text{ pF},$ $R_L = 667 \Omega$
t _{PZH}	Output Enable Time to HIGH Level		15	23	ns	
t _{PZL}	Output Enable Time to LOW Level		20	30	ns	
t _{PLZ}	Output Disable Time from LOW Level		15	25	ns	C _L = 5.0 pF,
t _{PHZ}	Output Disable Time from HIGH Level		10	18	ns	$R_L = 667 \Omega$

AC WAVEFORMS

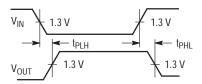


Figure 1.

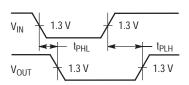


Figure 2.

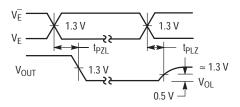


Figure 3.

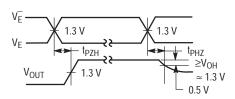
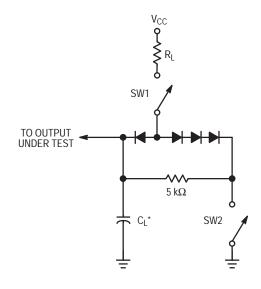


Figure 4.



SWITCH POSITIONS

SYMBOL	SW1	SW2
t _{PZH}	Open	Closed
t _{PZL}	Closed	Open
t _{PLZ}	Closed	Closed
t _{PHZ}	Closed	Closed

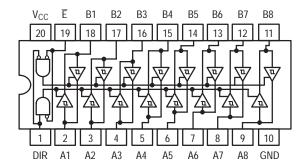
Figure 5.

Octal Bus Transceiver

The SN74LS245 is an Octal Bus Transmitter/Receiver designed for 8-line asynchronous 2-way data communication between data buses. Direction Input (DR) controls transmission of Data from bus A to bus B or bus B to bus A depending upon its logic level. The Enable input $(\overline{\bf E})$ can be used to isolate the buses.

- Hysteresis Inputs to Improve Noise Immunity
- 2-Way Asynchronous Data Bus Communication
- Input Diodes Limit High-Speed Termination Effects
- ESD > 3500 Volts

LOGIC AND CONNECTION DIAGRAMS DIP (TOP VIEW)



TRUTH TABLE

INP	UTS	OUTPUT
Ē	DIR	001701
L	L	Bus B Data to Bus A
L	Н	Bus A Data to Bus B
Н	Χ	Isolation

H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-3.0	mA
				-15	mA
I _{OL}	Output Current – Low			24	mA



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PLASTIC N SUFFIX CASE 738



SOIC DW SUFFIX CASE 751D

ORDERING INFORMATION

Device	Package	Shipping
SN74LS245N	16 Pin DIP	1440 Units/Box
SN74LS245DW	16 Pin	2500/Tape & Reel

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

		Parameter Min Typ Max Unit						
Symbol	Parame			Unit	Te	est Conditions		
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Ir All Inputs	nput HIGH Voltage for
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Ir All Inputs	nput LOW Voltage for
$V_{T+}-V_{T-}$	Hysteresis		0.2	0.4		V	V _{CC} = MIN	
V _{IK}	Input Clamp Diode Vol	tage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN}	_N = −18 mA
V	Output HICH Materia		2.4	3.4		V	V _{CC} = MIN, I _O	_{oH} = -3.0 mA
V _{OH}	Output HIGH Voltage		2.0			V	V _{CC} = MIN, I _{OH} = MAX	
	Output I OW/Vallage			0.25	0.4	٧	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$
V_{OL}	Output LOW Voltage			0.35	0.5	V	I _{OL} = 24 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
I _{OZH}	Output Off Current HIGH				20	μΑ	V _{CC} = MAX, V	_{OUT} = 2.7 V
I _{OZL}	Output Off Current LO	W			-200	μΑ	V _{CC} = MAX, V	_{OUT} = 0.4 V
		A or B, DR or E			20	μΑ	V _{CC} = MAX, V	′ _{IN} = 2.7 V
I _{IH}	Input HIGH Current	DR or E			0.1	mA	V _{CC} = MAX, V	_{IN} = 7.0 V
		A or B			0.1	mA	V _{CC} = MAX, V	_{IN} = 5.5 V
I _{IL}	Input LOW Current	-			-0.2	mA	V _{CC} = MAX, V	' _{IN} = 0.4 V
I _{OS}	Output Short Circuit C	urrent (Note 1)	-40		-225	mA	$V_{CC} = MAX$	
	Power Supply Current Total, Output HIGH				70			
Icc	Total, Output LOW				90	mA	$V_{CC} = MAX$	
	Total at HIGH Z				95	1		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V, T_{RISE}/T_{FALL} \leq 6.0 ns)

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay, Data to Output		8.0 8.0	12 12	ns	C ₁ = 45 pF,
t _{PZH}	Output Enable Time to HIGH Level		25	40	ns	$R_L = 667 \Omega$
t _{PZL}	Output Enable Time to LOW Level		27	40	ns	
t _{PLZ}	Output Disable Time from LOW Level		15	25	ns	$C_L = 5.0 \text{ pF},$
t _{PHZ}	Output Disable Time from HIGH Level		15	25	ns	$R_L = 667 \Omega$

BCD-to-Seven-Segment Decoders/Drivers

The SN74LS247 is a BCD-to-Seven-Segment Decoder/Drivers.

The LS247 composes the \Box and \Box with the tails. The LS247 has active-low outputs for direct drive of indicators.

The LS247 features a lamp test input and have full ripple-blanking input/output controls. An automatic leading and/or trailing-edge zero-blanking control (RBI and RBO) is incorporated and an overriding blanking input (BI) is contained which may be used to control the lamp intensity by pulsing or to inhibit the output's lamp test may be performed at any time when the BI/RBO node is at high level. Segment identification and resultant displays are shown below. Display pattern for BCD input counts above 9 are unique symbols to authenticate input conditions.

- Open-Collector Outputs Drive Indicators Directly
- Lamp-Test Provision
- Leading/Trailing Zero Suppression

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
ІОН	Output Current – High BI/RBO			-50	μΑ
l _{OL}	Output Current – Low BI/RBO			3.2	mA
V _{O(off)}	Off–State Output Voltage a – g			15	V
I _{O(on)}	On–State Output Current a – g			24	mA



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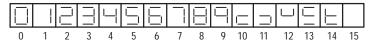
N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

ORDERING INFORMATION

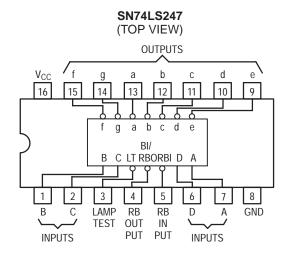
Device	Package	Shipping
SN74LS247N	16 Pin DIP	2000 Units/Box
SN74LS247D	16 Pin	2500/Tape & Reel



NUMERICAL DESIGNATIONS AND RESULTANT DISPLAYS



SEGMENT IDENTIFICATION

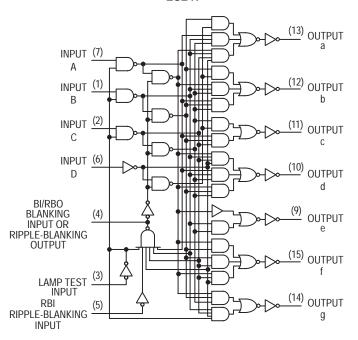


CIRCUIT FEATURES LAMP INTENSITY MODULATION CAPABILITY

		TYPICAL			
TYPE	ACTIVE LEVEL	OUTPUT CONFIGURATION	SINK CURRENT	MAX VOLTAGE	POWER DISSIPATION
SN74LS247	low	open-collector	24 mA	15 V	35 mW

LOGIC DIAGRAM

LS247



LS247 **FUNCTION TABLE**

DECIMAL	ECIMAL INPUTS			BI/RBO [†]	оитритѕ					NOTE						
FUNCTION	LT	RBI	D	С	В	Α	DI/KBO*	а	b	С	d	е	f	g		
0	Н	Н	L	L	L	L	Н	ON	ON	ON	ON	ON	ON	OFF		
1	Н	X	L	L	L	Н	Н	OFF	ON	ON	OFF	OFF	OFF	OFF		
2	Н	X	L	L	Н	L	Н	ON	ON	OFF	ON	ON	OFF	ON		
3	Н	X	L	L	Н	Н	Н	ON	ON	ON	ON	OFF	OFF	ON		
4	Н	Х	L	Н	L	L	Н	OFF	ON	ON	OFF	OFF	ON	ON		
5	Н	X	L	Н	L	Н	Н	ON	OFF	ON	ON	OFF	ON	ON		
6	Н	X	L	Н	Н	L	Н	ON	OFF	ON	ON	ON	ON	ON		
7	Н	X	L	Н	Н	Н	Н	ON	ON	ON	OFF	OFF	OFF	OFF	1	
8	Н	Х	Н	L	L	L	Н	ON	ON	ON	ON	ON	ON	ON		
9	Н	X	Н	L	L	Н	Н	ON	ON	ON	ON	OFF	ON	ON		
10	Н	X	Н	L	Н	L	Н	OFF	OFF	OFF	ON	ON	OFF	ON		
11	Н	Х	Н	L	Н	Н	Н	OFF	OFF	ON	ON	OFF	OFF	ON		
12	Н	Х	Н	Н	L	L	Н	OFF	ON	OFF	OFF	OFF	ON	ON		
13	Н	X	Н	Н	L	Н	Н	ON	OFF	OFF	ON	OFF	ON	ON		
14	Н	X	Н	Н	Н	L	Н	OFF	OFF	OFF	ON	ON	ON	ON		
15	Н	Х	Н	Н	Н	Н	Н	OFF	OFF	OFF	OFF	OFF	OFF	OFF		
BI	Х	Х	Х	Х	Х	Х	L	OFF	OFF	OFF	OFF	OFF	OFF	OFF	2	
RBI	Н	L	L	L	L	L	L	OFF	OFF	OFF	OFF	OFF	OFF	OFF	3	
LT	L	X	Х	Χ	Χ	Χ	Н	ON	ON	ON	ON	ON	ON	ON	4	

H = HIGH Level, L = LOW Level, X = Irrelevant

NOTES: 1. The blanking input (BI) must be open or held at a high logic level when output functions 0 through 15 are desired. The ripple-blanking input (RBI) must be open or high if blanking of a decimal zero is not desired.

^{2.} When a low logic level is applied directly to the blanking input (BI), all segment outputs are off regardless of the level of any other input.

3. When ripple-blanking input (RBI) and inputs A, B, C, and D are at a low level with the lamp test input high, all segment outputs go off and the ripple-blanking output (RBO) goes to a low level (response condition).

4. When the blanking input/ripple blanking output (BI/RBO) is open or held high and a low is applied to the lamp-test input, all segment outputs are on.

† BI/RBO is wire-AND logic serving as blanking input (BI) and/or ripple-blanking output (RBO).

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs		
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA		
V _{OH}	Output HIGH Voltage BI/RBO	2.4	4.2		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
V _{OL}	Output LOW Voltage		0.25	0.4	V	I _{OL} = 1.6 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$	
	BI/RBO		0.35	0.5	٧	I _{OL} = 3.2 mA	per Truth Table	
I _{O(off)}	Off-State Output Current a-g			250	μΑ	V _{CC} = MAX, V _{IH} = 2.0 V, V _{O(off)} = 15 V, V _{IL} = MAX		
V	On-State Output Voltage		0.25	0.4	V	I _{O(on)} = 12 mA	$V_{CC} = MIN, V_{IH} = 2.0 V,$	
V _{O(on)}	a-g		0.35	0.5	V	I _{O(on)} = 24 mA	V _{IL} per Truth Table	
	Innut HICH Current			20	μΑ	$V_{CC} = MAX, V_{IN} = 2.7 V$		
I _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current Any Input, except BI/RBO			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
	BI/RBO			-1.2]			
I _{OS}	Short Circuit Current BI/RBO (Note 1)	-0.3		-2.0	mA	V _{CC} = MAX		
Icc	Power Supply Current		7.0	13	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (V_{CC} = 5.0 V, T_A = 25°C)

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
t _{PLH} t _{PHL}	Turn-Off Time from A Input Turn-On Time from A Input			100 100	ns	C _L = 15 pF,		
t _{PHL} t _{PLH}	Turn-Off Time from RBI Input Turn-On Time from RBI Input			100 100	ns	$R_L = 665 \Omega$		

8-Input Multiplexer with 3-State Outputs

The TTL/MSI SN74LS251 is a high speed 8-Input Digital Multiplexer. It provides, in one package, the ability to select one bit of data from up to eight sources. The LS251 can be used as a universal function generator to generate any logic function of four variables. Both assertion and negation outputs are provided.

- Schottky Process for High Speed
- Multifunction Capability
- On-Chip Select Logic Decoding
- Inverting and Non-Inverting 3-State Outputs
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-2.6	mA
I _{OL}	Output Current – Low			24	mA



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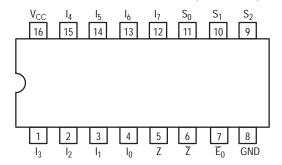
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping		
SN74LS251N	16 Pin DIP	2000 Units/Box		
SN74LS251D	16 Pin	2500/Tape & Reel		

CONNECTION DIAGRAM DIP (TOP VIEW)

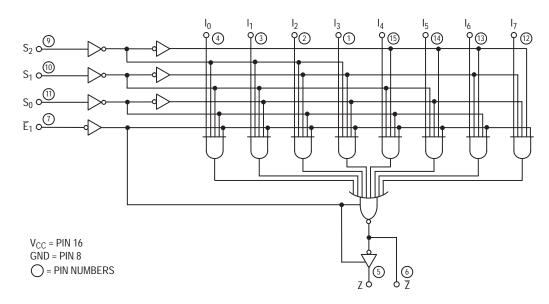


		LOADING	(Note a)
PIN NAMES		HIGH	LOW
$\begin{array}{l} S_0 - S_2 \\ \overline{E}_0 \\ I_0 - I_7 \\ \overline{Z} \end{array}$	Select Inputs Output Enable (Active LOW) Inputs Multiplexer Inputs Multiplexer Output Complementary Multiplexer Output	0.5 U.L. 0.5 U.L. 0.5 U.L. 65 U.L. 65 U.L.	0.25 U.L. 0.25 U.L. 0.25 U.L. 15 U.L. 15 U.L.

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS251 is a logical implementation of a single pole, 8-position switch with the switch position controlled by the state of three Select inputs, S_0 , S_1 , S_2 . Both assertion and negation outputs are provided. The Output Enable input (\overline{E}_O) is active LOW. When it is activated, the logic function provided at the output is:

$$\begin{split} Z &= \overline{E}_O \cdot (I_0 \cdot \overline{S}_0 \cdot \overline{S}_1 \cdot \overline{S}_2 + I_1 \cdot S_0 \cdot \overline{S}_1 \cdot \overline{S}_2 + I_2 \cdot \overline{S}_0 \cdot S_1 \cdot \\ & \overline{S}_2 + I_3 \cdot S_0 \cdot S_1 \cdot \overline{S}_2 + I_4 \cdot \overline{S}_0 \cdot \overline{S}_1 \cdot S_2 + I_5 \cdot S_0 \cdot \\ & \overline{S}_1 \cdot S_2 + I_6 \cdot \overline{S}_0 \cdot S_1 \cdot S_2 + I_7 \cdot S_0 \cdot S_1 \cdot S_2). \end{split}$$

When the Output Enable is HIGH, both outputs are in the high impedance (high Z) state. This feature allows multiplexer expansion by tying the outputs of up to 128 devices together. When the outputs of the 3-state devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. The Output Enable signals should be designed to ensure there is no overlap in the active LOW portion of the enable voltage.

TRUTH TABLE

Ē ₀	S ₂	S ₁	S ₀	I ₀	I ₁	l ₂	l ₃	I ₄	l ₅	I ₆	I ₇	Z	Z
Н	Х	Х	Χ	Х	Χ	Χ	Х	Χ	Χ	Χ	Χ	(Z)	(Z)
L	L	L	L	L	Χ	Χ	Χ	Χ	X	X	X	Н	L
L	L	L	L	Н	Χ	Χ	Χ	Χ	Χ	X	X	L	Н
L	L	L	Н	Х	L	Χ	Χ	Χ	Χ	X	X	Н	L
L	L	L	Н	Х	Н	Χ	Χ	Χ	X	X	X	L	Н
L	L	Н	L	Х	Χ	L	Χ	Χ	Χ	X	X	Н	L
L	L	Н	L	Х	Χ	Н	Χ	Χ	Χ	X	X	L	Н
L	L	Н	Н	Х	Χ	Χ	L	Χ	Χ	X	X	Н	L
L	L	Н	Н	Х	Χ	Χ	Н	Χ	X	Χ	X	L	Н
L	Н	L	L	Х	Χ	Χ	Χ	L	Χ	X	X	Н	L
L	Н	L	L	Х	Χ	Χ	Χ	Н	Χ	X	X	L	Н
L	Н	L	Н	Х	Χ	Χ	Χ	Χ	L	Χ	X	Н	L
L	Н	L	Н	Х	Χ	Χ	Χ	Χ	Н	X	X	L	Н
L	Н	Н	L	Х	Χ	Χ	Χ	Χ	X	L	X	Н	L
L	Н	Н	L	Х	Χ	Χ	Χ	Χ	X	Н	X	L	Н
L	Н	Н	Н	Х	Χ	Χ	X	X	X	Χ	L	Н	L
L	Н	Н	Н	Х	Χ	Χ	Χ	Χ	Χ	Χ	Н	L	Н

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

⁽Z) = High impedance (Off)

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits			nit Test Conditions			
Symbol	Parameter	Min	Тур	Max	Unit				
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for		
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	٧	V _{CC} = MIN, I _{IN} =	–18 mA		
V _{OH}	Output HIGH Voltage	2.4	3.1		V	$V_{CC} = MIN, I_{OH} = $ or V_{IL} per Truth T			
.,	0		0.25	0.4	٧	$I_{OL} = 12 \text{ mA}$ $V_{CC} = V_{CC} \text{ MIN},$			
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 24 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table		
I _{OZH}	Output Off Current HIGH			20	μА	$V_{CC} = MAX, V_{OU}$	_T = 2.7 V		
I _{OZL}	Output Off Current LOW			-20	μА	$V_{CC} = MAX, V_{OU}$	T = 0.4 V		
	Innut IIICI I Current			20	μА	V _{CC} = MAX, V _{IN}	= 2.7 V		
IH	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN}	= 7.0 V		
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V			
I _{OS}	Short Circuit Current (Note 1)	-30		-130	mA	V _{CC} = MAX			
	Dower Cumply Cumpet			10	mA	$V_{CC} = MAX, V_{E} = 0 V$			
Icc	Power Supply Current			12	mA	$V_{CC} = MAX, V_{E} =$	= 4.5 V		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions	
t _{PLH} t _{PHL}	Propagation Delay, Select to Z Output		20 21	33 33	ns	Figure 1	
t _{PLH} t _{PHL}	Propagation Delay, Select to Z Output		29 28	45 45	ns	Figure 2	
t _{PLH} t _{PHL}	Propagation Delay, Data to ℤ Output		10 9.0	15 15	ns	Figure 1	C _L = 15 pF,
t _{PLH} t _{PHL}	Propagation Delay, Data to Z Output		17 18	28 28	ns	Figures 2	$R_L = 2.0 \text{ k}\Omega$
t _{PZH} t _{PZL}	Output Enable Time to Z Output		17 24	27 40	ns	Figures 4, 5	
t _{PZH} t _{PZL}	Output Enable Time to Z Output		30 26	45 40	ns	Figures 3, 5	
t _{PHZ} t _{PLZ}	Output Disable Time to Z Output		37 15	55 25	ns	Figures 3, 5	$C_{L} = 5.0 pF,$
t _{PHZ} t _{PLZ}	Output Disable Time to Z Output		30 15	45 25	ns	Figures 4, 5	$R_L = 667 \text{ k}\Omega$

3-STATE AC WAVEFORMS

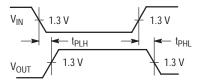


Figure 1.

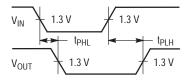


Figure 2.

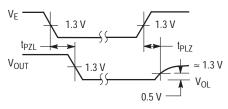


Figure 3.

0.5 V

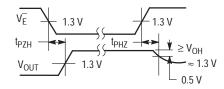


Figure 4.

AC LOAD CIRCUIT

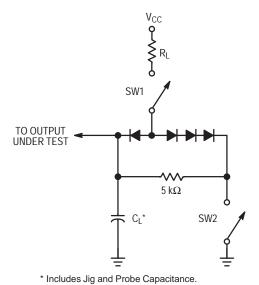


Figure 5.

SWITCH POSITIONS

SYMBOL	SW1	SW2		
t _{PZH}	Open	Closed		
t_{PZL}	Closed	Open		
t_{PLZ}	Closed	Closed		
t _{PHZ}	Closed	Closed		

Dual 4-Input Multiplexer with 3-State Outputs

The LSTTL/MSI SN74LS253 is a Dual 4-Input Multiplexer with 3-state outputs. It can select two bits of data from four sources using common select inputs. The outputs may be individually switched to a high impedance state with a HIGH on the respective Output Enable (\overline{E}_0) inputs, allowing the outputs to interface directly with bus oriented systems. It is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Schottky Process for High Speed
- Multifunction Capability
- Non-Inverting 3-State Outputs
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-2.6	mA
I _{OL}	Output Current – Low			24	mA



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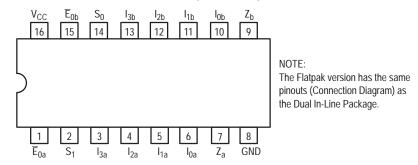
N SUFFIX CASE 648



SOIC **D SUFFIX CASE 751B**

Device	Package	Shipping		
SN74LS253N	16 Pin DIP	2000 Units/Box		
SN74LS253D	16 Pin	2500/Tape & Reel		

CONNECTION DIAGRAM DIP (TOP VIEW)

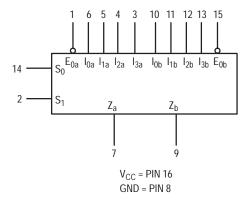


		LOADING	(Note a)
PIN NAMES		HIGH	LOW
S ₀ , S ₁	Common Select Inputs	0.5 U.L.	0.25 U.L.
Multiplexer A			
\overline{E}_{0a}	Output Enable (Active LOW) Input	0.5 U.L.	0.25 U.L.
$I_{0a} - I_{3a}$	Multiplexer Inputs	0.5 U.L.	0.25 U.L.
Za	Multiplexer Output	65 U.L.	15 U.L.
Multiplexer B			
E _{0b}	Output Enable (Active LOW) Input	0.5 U.L.	0.25 U.L.
$I_{0b} - I_{3b}$	Multiplexer Inputs	0.5 U.L.	0.25 U.L.
Z _b	Multiplexer Output	65 U.L.	15 U.L.

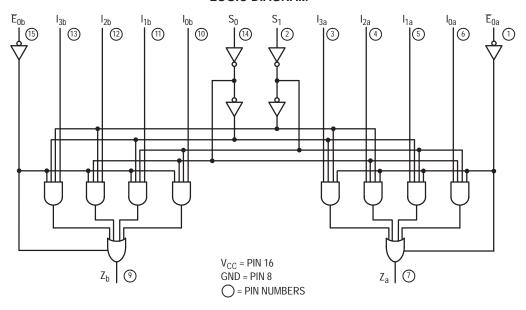
NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS253 contains two identical 4-Input Multiplexers with 3-state outputs. They select two bits from four sources selected by common select inputs (S₀, S₁). The 4-input multiplexers have individual Output Enable (\overline{E}_{0a} , \overline{E}_{0b}) inputs which when HIGH, forces the outputs to a high impedance (high Z) state.

The LS253 is the logic implementation of a 2-pole, 4-position switch, where the position of the switch is determined by the logic levels supplied to the two select inputs. The logic equations for the outputs are shown below:

$$\begin{split} Z_a &= \overline{E}_{0a} \cdot (I_{0a} \cdot \overline{S}_1 \cdot \overline{S}_0 + I_{1a} \cdot \overline{S}_1 \cdot S_0 \cdot I_{2a} \cdot S_1 \cdot \overline{S}_0 + I_{3a} \cdot S_1 \cdot S_0) \\ Z_b &= \overline{E}_{0b} \cdot (I_{0b} \ \overline{S}_1 \ \overline{S}_0 + I_{1b} \cdot \overline{S}_1 \cdot S_0 \ I_{2b} \cdot S_1 \cdot \overline{S}_0 + I_{3b} \cdot S_1 \cdot S_0) \end{split}$$

If the outputs of 3-state devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-state devices whose outputs are tied together are designed so that there is no overlap.

TRUTH TABLE

	ECT UTS	DATA INPUTS				OUTPUT ENABLE	OUTPUT
S ₀	S ₁	I ₀	I ₁	l ₂	l ₃	Ē₀	Z
Х	Х	Х	Χ	Х	Х	Н	(Z)
L	L	L	X	X	X	L	L
L	L	Н	X	Χ	Χ	L	Н
Н	L	Х	L	Χ	Χ	L	L
Н	L	Х	Н	Χ	Χ	L	Н
L	Н	Х	X	L	X	L	L
L	Н	Х	X	Н	Χ	L	Н
Н	Н	Х	X	X	L	L	L
Н	Н	Х	X	X	Н	L	Н

H = HIGH Level

L = LOW Level

X = Irrelevant

(Z) = High Impedance (off)

Address inputs S_0 and S_1 are common to both sections.

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input All Inputs	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input All Inputs	t LOW Voltage for	
V_{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = 0$	–18 mA	
V _{OH}	Output HIGH Voltage	2.4	3.1		V	$V_{CC} = MIN, I_{OH} =$ or V_{IL} per Truth T		
V	Outrot I OW//altana		0.25	0.4	٧	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$	
V _{OL}	Output LOW Voltage		0.35	0.5	٧	I _{OL} = 24 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table	
I _{OZH}	Output Off Current HIGH			20	μΑ	V _{CC} = MAX, V _{OU}	_T = 2.7 V	
I _{OZL}	Output Off Current LOW			-20	μΑ	V _{CC} = MAX, V _{OU}	T = 0.4 V	
	Innut HCH Current			20	μΑ	V _{CC} = MAX, V _{IN} :	= 2.7 V	
IH	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} :	= 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Short Circuit Current (Note 1)	-30		-130	mA	V _{CC} = MAX		
	Dower Cumply Current			12	mA	$V_{CC} = MAX, V_{E} = 0 V$		
Icc	Power Supply Current			14	mA	$V_{CC} = MAX, V_{E} =$: 4.5 V	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V) See SN74LS251 for Waveforms

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
t _{PLH} t _{PHL}	Propagation Delay, Data to Output		17 13	25 20	ns	Figure 1		
t _{PLH} t _{PHL}	Propagation Delay, Select to Output		30 21	45 32	ns	Figure 1	$C_L = 45 \text{ pF},$ $R_L = 667 \Omega$	
t _{PZH}	Output Enable Time		15 15	28 23	ns	Figures 4, 5		
t _{PHZ}	Output Disable Time		27 18	41 27	ns	Figures 3, 5	$C_L = 5.0 \text{ pF},$ $R_L = 667 \Omega$	

Quad 2-Input Multiplexer with 3-State Outputs

The LSTTL/MSI SN74LS257B and the SN74LS258B are Quad 2-Input Multiplexers with 3-state outputs. Four bits of data from two sources can be selected using a Common Data Select input. The four outputs present the selected data in true (non-inverted) form. The outputs may be switched to a high impedance state with a HIGH on the common Output Enable ($E_{\rm O}$) Input, allowing the outputs to interface directly with bus oriented systems. It is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Schottky Process For High Speed
- Multiplexer Expansion By Tying Outputs Together
- Non-Inverting 3-State Outputs
- Input Clamp Diodes Limit High Speed Termination Effects
- Special Circuitry Ensures Glitch Free Multiplexing
- ESD > 3500 Volts

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-2.6	mA
I _{OL}	Output Current – Low			24	mA



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> LOW POWER SCHOTTKY



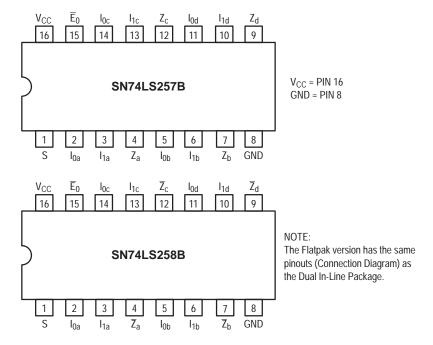
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

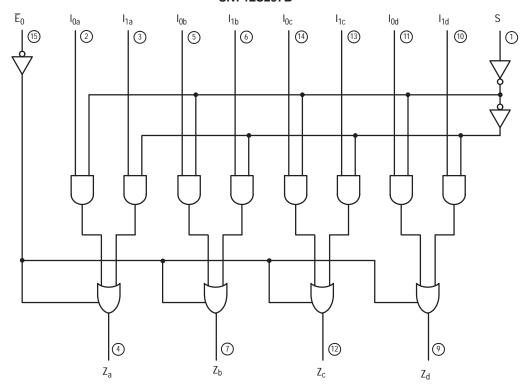
Device	Package	Shipping		
SN74LS257BN	16 Pin DIP	2000 Units/Box		
SN74LS257BD	16 Pin	2500/Tape & Reel		
SN74LS258BN	16 Pin DIP	2000 Units/Box		
SN74LS258BD	16 Pin	2500/Tape & Reel		

CONNECTION DIAGRAM DIP (TOP VIEW)

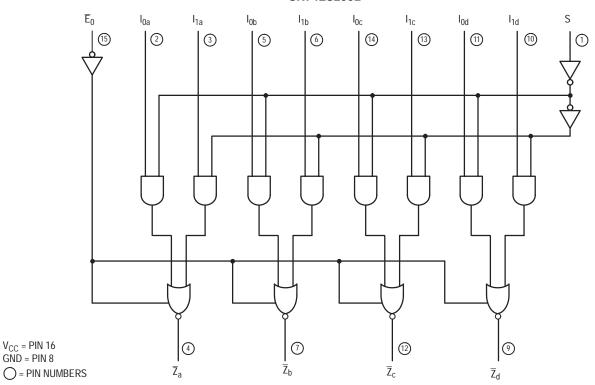


LOGIC DIAGRAMS

SN74LS257B



SN74LS258B



V_{CC} = PIN 16 GND = PIN 8

FUNCTIONAL DESCRIPTION

The LS257B and LS258B are Quad 2-Input Multiplexers with 3-state outputs. They select four bits of data from two sources each under control of a Common Data Select Input. When the Select Input is LOW, the $\rm I_0$ inputs are selected and when Select is HIGH, the $\rm I_1$ inputs are selected. The data on the selected inputs appears at the outputs in true (non-inverted) form for the LS257B and in the inverted form for the LS258B.

The LS257B and LS258B are the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select Input. The logic equations for the outputs are shown below:

$$\begin{array}{l} Z_a = \overline{E}_0 \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S}) \ Z_b = \overline{E}_0 \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S}) \\ \overline{Z}_c = \overline{E}_0 \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S}) \ \overline{Z}_d = \overline{E}_0 \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S}) \end{array}$$

When the Output Enable Input (\overline{E}_0) is HIGH, the outputs are forced to a high impedance "off" state. If the outputs are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-state devices whose outputs are tied together are designed so there is no overlap.

LS258B

$$\begin{array}{l} \overline{Z}_a = \overline{E}_0 \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S}) \ \overline{Z}_b = \overline{E}_0 \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S}) \\ \overline{Z}_c = \overline{E}_0 \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S}) \ \overline{Z}_d = \overline{E}_0 \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S}) \end{array}$$

TRUTH TABLE

OUTPUT ENABLE	SELECT INPUT	DATA INPUTS		OUTPUTS LS257B	OUTPUTS LS258B
Ēo	S	l ₀ l ₁		Z	Z
Н	Х	Х	Χ	(Z)	(Z)
L	Н	Х	L	L	Н
L	Н	Х	Н	Н	L
L	L	L	Χ	L	Н
L	L	Н	Χ	Н	L

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

⁽Z) = High Impedance (off)

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits							
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions			
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Inpu All Inputs	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Input LOW Voltage for All Inputs			
V_{IK}	Input Clamp Diode Voltage	1		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA		
V _{OH}	Output HIGH Voltage		2.4	3.1		V	V _{CC} = MIN, I _{OH} = or V _{IL} per Truth T			
V	Output LOW Voltage			0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{II} \text{ or } V_{IH}$		
V _{OL}	Output LOW Voltage			0.35	0.5	V	I _{OL} = 24 mA	per Truth Table		
I _{OZH}	Output Off Current — HIGH	1			20	μΑ	$V_{CC} = MAX, V_{OUT} = 2.7 V$			
I _{OZL}	Output Off Current — LOW	/			-20	μА	$V_{CC} = MAX, V_{OU}$	T = 0.4 V		
I _{IH}	Input HIGH Current Other Inputs S Inputs				20 40	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V		
	Other Inputs S Inputs				0.1 0.2	mA	V _{CC} = MAX, V _{IN}	= 7.0 V		
I _{IL}	Input LOW Current All Inputs				-0.4	mA	V _{CC} = MAX, V _{IN}	= 0.4 V		
I _{OS}	Short Circuit Current (Note	1)	-30		-130	mA	V _{CC} = MAX			
	Power Supply Current Total, Output HIGH	LS257B LS258B			10 9.0	mA				
I _{CC}	Total, Output LOW			16 14	mA	V _{CC} = MAX				
	Total, Output 3-State			19 16	mA					

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$) See SN74LS251 for Waveforms

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
t _{PLH} t _{PHL}	Propagation Delay, Data to Output		10 12	13 15	ns	Figures 1 & 2	C - 45 pE	
t _{PLH} t _{PHL}	Propagation Delay, Select to Output		14 14	21 21	ns	Figures 1 & 2	C _L = 45 pF	
t _{PZH}	Output Enable Time to HIGH Level		20	25	ns	Figures 4 & 5	C _L = 45 pF	
t _{PZL}	Output Enable Time to LOW Level		20	25	ns	Figures 3 & 5	$R_L = 667 \Omega$	
t _{PLZ}	Output Disable Time to LOW Level		16	25	ns	Figures 3 & 5	C _L = 5.0 pF	
t _{PHZ}	Output Disable Time from HIGH Level		18	25	ns	Figures 4 & 5	$R_L = 667 \Omega$	

8-Bit Addressable Latch

The SN74LS259 is a high-speed 8-Bit Addressable Latch designed for general purpose storage applications in digital systems. It is a multifunctional device capable of storing single line data in eight addressable latches, and also a 1-of-8 decoder and demultiplexer with active HIGH outputs. The device also incorporates an active LOW common Clear for resetting all latches, as well as, an active LOW Enable.

- Serial-to-Parallel Conversion
- Eight Bits of Storage With Output of Each Bit Available
- Random (Addressable) Data Entry
- Active High Demultiplexing or Decoding Capability
- Easily Expandable
- Common Clear

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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LOW **POWER SCHOTTKY**



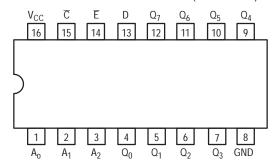
N SUFFIX CASE 648



SOIC **D SUFFIX CASE 751B**

Device	Package	Shipping
SN74LS259N	16 Pin DIP	2000 Units/Box
SN74LS259D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)

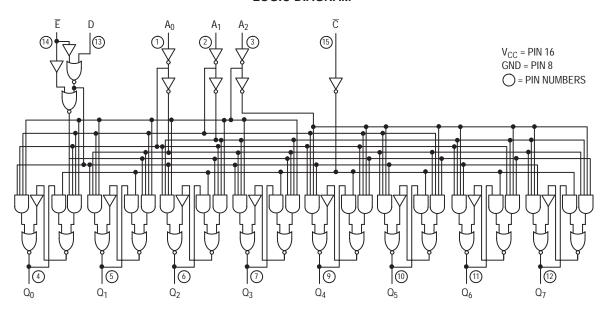


		LOADIN	G (Note a)
PIN NAMES		HIGH	LOW
A_0 , A_1 , A_2 D \overline{E} C $Q_0 - Q_7$	Address Inputs Data Input Enable (Active LOW) Input Clear (Active LOW) Input Parallel Latch Outputs	0.5 U.L. 0.5 U.L. 1.0 U.L. 0.5 U.L. 10 U.L.	0.25 U.L. 0.25 U.L. 0.5 U.L. 0.25 U.L. 5 U.L.

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The SN74LS259 has four modes of operation as shown in the mode selection table. In the addressable latch mode, data on the Data line (D) is written into the addressed latch. The addressed latch will follow the data input with all non-addressed latches remaining in their previous states. In the memory mode, all latches remain in their previous state and are unaffected by the Data or Address inputs.

In the one-of-eight decoding or demultiplexing mode, the addressed output will follow the state of the D input with all

other inputs in the LOW state. In the clear mode all outputs are LOW and unaffected by the address and data inputs.

When operating the SN74LS259 as an addressable latch, changing more then one bit of the address could impose a transient wrong address. Therefore, this should only be done while in the memory mode.

The truth table below summarizes the operations.

MODE SELECTION

TRUTH TABLE PRESENT OUTPUT STATES

Ē	С	MODE
L	Н	Addressable Latch
Н	Н	Memory
L	L	Active HIGH Eight-Channel Demultiplexer
Н	L	Clear

C	Ē	D	A_0	A_1	A_2	Q_0	Q_1	Q_2	Q_3	Q_4	Q_5	Q_6	Q_7	MODE
L	Н	Χ	Χ	Χ	Χ	L	L	L	L	L	L	L	L	Clear
L	L	L	L	L	L	L	L	L	L	L	L	L	L	Demultiplex
L	L	Н	L	L	L	Н	L	L	L	L	L	L	L	
L	L	L	Н	L	L	L	L	L	L	L	L	L	L	
L	L	Н	Н	L	L	L	Н	L	L	L	L	L	L	
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•					
L	L	Н	Н	Н	Н	L	L	L	L	L	L	L	Н	
Н	Н	Χ	Χ	Χ	Χ	Q _{N-1}							•	Memory
Н	ı	Ι	L	L	L	L	Q_{N-1}	Q_{N-1}	Q _{N-1} -				—	Addressable
Н	L	Н	L	L	L	Н	Q_{N-1}	Q_{N-1} -					-	Latch
Н	L	L	Н	L	L	Q_{N-1}	L	Q_{N-1}					-	
Н	L	Н	Н	L	L	Q _{N-1}	Н	Q_{N-1} -					-	
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•					
H	L	L	Н	Н	Н	Q_{N-1}					_	Q_{N-1}	L	
Н	L	Н	Н	Н	Н	Q_{N-1}						Q_{N-1}	Н	

$$\begin{split} & X = Don't \ Care \ Condition \\ & L = LOW \ Voltage \ Level \\ & H = HIGH \ Voltage \ Level \\ & Q_{N-1} = Previous \ Output \ State \end{split}$$

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
.,	0		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table	
	January I III Cl I Command			20	μΑ	$V_{CC} = MAX, V_{IN}$	= 2.7 V	
I _{IH}	Input HIGH Current			0.1	mA	$V_{CC} = MAX, V_{IN}$	= 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	$V_{CC} = MAX$, $V_{IN} = 0.4 V$		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current			36	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

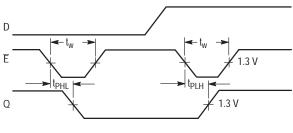
AC CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Turn-Off Delay, Enable to Output Turn-On Delay, Enable to Output		22 15	35 24	ns ns	
t _{PLH}	Turn-Off Delay, Data to Output Turn-On Delay, Data to Output		20 13	32 21	ns ns	C _L = 15 pF
t _{PLH} t _{PHL}	Turn-Off Delay, Address to Output Turn-On Delay, Address to Output		24 18	38 29	ns ns	
t _{PHL}	Turn-On Delay, Clear to Output		17	27	ns	

AC SET-UP REQUIREMENTS (T_A = 25° C, V_{CC} = 5.0 V)

		Limits			
Symbol	Parameter	Min	Тур	Max	Unit
t _s	Input Setup Time	20			ns
t _W	Pulse Width, Clear or Enable	15			ns
t _h	Hold Time, Data	5.0			ns
t _h	Hold Time, Address	20		·	ns

AC WAVEFORMS



OTHER CONDITIONS: $\overline{C} = H$, A = STABLE

Figure 1. Turn-on and Turn-off Delays, Enable To Output and Enable Pulse Width

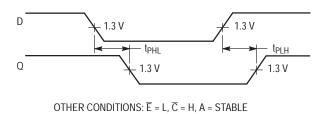
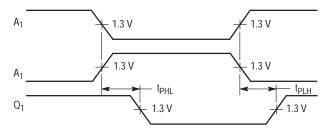
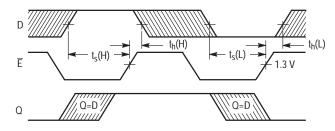


Figure 2. Turn-on and Turn-off Delays,
Data to Output



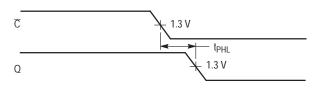
OTHER CONDITIONS: $\overline{E} = L$, $\overline{C} = L$, D = H

Figure 3. Turn-on and Turn-off Delays, Address to Output



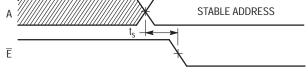
OTHER CONDITIONS: $\overline{C} = H$, A = STABLE

Figure 4. Setup and Hold Time, Data to Enable



OTHER CONDITIONS: $\overline{E} = H$

Figure 5. Turn-on Delay, Clear to Output



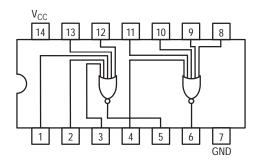
OTHER CONDITIONS: $\overline{C} = H$

Figure 6. Setup Time, Address to Enable (See Notes 1 and 2)

NOTES:

- 1. The Address to Enable Setup Time is the time before the HIGH-to-LOW Enable transition that the Address must be stable so that the correct latch is addressed and the other latches are not affected.
- 2. The shaded areas indicate when the inputs are permitted to change for predictable output performance.

Dual 5-Input NOR Gate





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> LOW POWER SCHOTTKY

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



PLASTIC N SUFFIX CASE 646



SOIC D SUFFIX CASE 751A

Device	Package	Shipping
SN74LS260N	14 Pin DIP	2000 Units/Box
SN74LS260D	14 Pin	2500/Tape & Reel

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} =$	–18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
.,	Output I OW/Vallage		0.25	0.4	٧	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table	
1	January I II Cold Command			20	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V	
t _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN}	= 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN}	= 0.4 V	
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current Total, Output HIGH			4.0	mA	V _{CC} = MAX		
	Total, Output LOW			5.5				

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Turn-Off Delay, Input to Output		5.0	15	ns	V _{CC} = 5.0 V
t _{PHL}	Turn-On Delay, Input to Output		6.0	15	ns	C _L = 15 pF

Octal D Flip-Flop with Clear

The SN74LS273 is a high-speed 8-Bit Register. The register consists of eight D-Type Flip-Flops with a Common Clock and an asynchronous active LOW Master Reset. This device is supplied in a 20-pin package featuring 0.3 inch lead spacing.

- 8-Bit High Speed Register
- Parallel Register
- Common Clock and Master Reset
- Input Clamp Diodes Limit High-Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



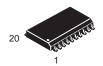
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> LOW POWER SCHOTTKY



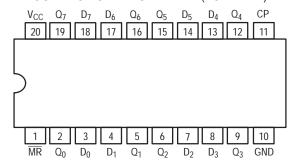
PLASTIC N SUFFIX CASE 738



SOIC DW SUFFIX CASE 751D

Device	Package	Shipping
SN74LS273N	16 Pin DIP	1440 Units/Box
SN74LS273DW	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



PIN NAMES

HIGH LOW СР Clock (Active HIGH Going Edge) Input 0.5 U.L. 0.25 U.L. Data Inputs 0.5 U.L. 0.25 U.L. $D_0 - D_7$ MR Master Reset (Active LOW) Input 0.5 U.L. 0.25 U.L. $Q_0 - Q_7$ Register Outputs 10 U.L. 5 U.L.

LOADING (Note a)

NOTES:

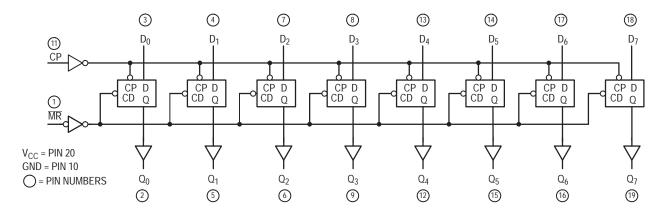
a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

TRUTH TABLE

MR	СР	D _x	Q _x
L	Х	Х	L
Н		Н	Н
Н		L	L

H = HIGH Logic Level L = LOW Logic Level X = Immaterial

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The SN74LS273 is an 8-Bit Parallel Register with a common Clock and common Master Reset.

When the \overline{MR} input is LOW, the Q outputs are LOW, independent of the other inputs. Information meeting the

setup and hold time requirements of the D inputs is transferred to the Q outputs on the LOW-to-HIGH transition of the clock input.

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input All Inputs	HIGH Voltage for	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input All Inputs	LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN$, $I_{IN} = -18 \text{ mA}$		
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
W	Output I OW/ Valta as		0.25	0.4	٧	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table	
	lament I II Cl I Commant			20	μΑ	V _{CC} = MAX, V _{IN} =	= 2.7 V	
l _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} =	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current			27	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

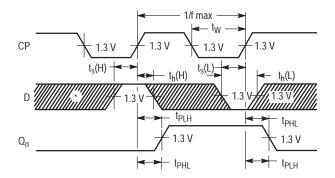
AC CHARACTERISTICS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
f _{MAX}	Maximum Input Clock Frequency	30	40		MHz	Figure 1
t _{PHL}	Propagation Delay, MR to Q Output		18	27	ns	Figure 2
t _{PLH} t _{PHL}	Propagation Delay, Clock to Output		17 18	27 27	ns	Figure 1

AC SETUP REQUIREMENTS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _w	Pulse Width, Clock or Clear	20			ns	Figure 1
t _s	Data Setup Time	20			ns	Figure 1
t _h	Hold Time	5.0			ns	Figure 1
t _{rec}	Recovery Time	25			ns	Figure 2

AC WAVEFORMS



^{*}The shaded areas indicate when the input is permitted to change for predictable output performance.

Figure 1. Clock to Output Delays, Clock Pulse Width, Frequency, Setup and Hold Times Data to Clock

DEFINITION OF TERMS

SETUP TIME (t_s) — is defined as the minimum time required for the correct logic level to be present at the logic input prior to the clock transition from LOW-to-HIGH in order to be recognized and transferred to the outputs.

HOLD TIME (t_h) — is defined as the minimum time following the clock transition from LOW-to-HIGH that the logic level must be maintained at the input in order to ensure

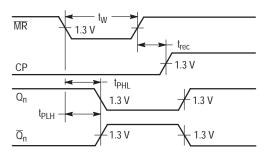


Figure 2. Master Reset to Output Delay, Master Reset Pulse Width, and Master Reset Recovery Time

continued recognition. A negative HOLD TIME indicates that the correct logic level may be released prior to the clock transition from LOW-to-HIGH and still be recognized.

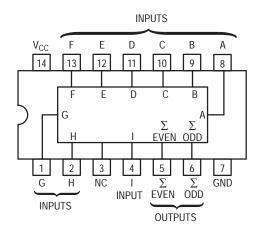
RECOVERY TIME (t_{rec}) — is defined as the minimum time required between the end of the reset pulse and the clock transition from LOW-to-HIGH in order to recognize and transfer HIGH data to the Q outputs.

9-Bit Odd/Even Parity Generators/Checkers

The SN74LS280 is a Universal 9-Bit Parity Generator/Checker. It features odd/even outputs to facilitate either odd or even parity. By cascading, the word length is easily expanded.

The LS280 is designed without the expander input implementation, but the corresponding function is provided by an input at Pin 4 and the absence of any connection at Pin 3. This design permits the LS280 to be substituted for the LS180 which results in improved performance. The LS280 has buffered inputs to lower the drive requirements to one LS unit load.

- Generates Either Odd or Even Parity for Nine Data Lines
- Typical Data-to-Output Delay of only 33 ns
- Cascadable for n-Bits
- Can Be Used To Upgrade Systems Using MSI Parity Circuits
- Typical Power Dissipation = 80 mW



FUNCTION TABLE

NUMBER OF INPUTS A	OUTP	UTS
THRU 1 THAT ARE HIGH	Σ EVEN	ΣODD
0, 2, 4, 6, 8	Н	L
1, 3, 5, 7, 9	L	Н

H = HIGH Level, L = LOW Level

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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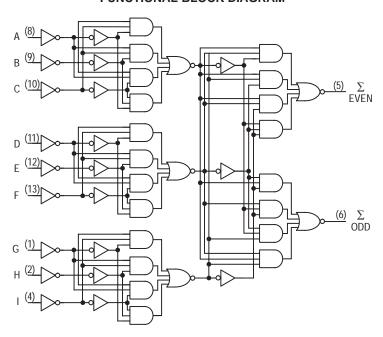
LOW POWER SCHOTTKY





Device	Package	Shipping
SN74LS280N	14 Pin DIP	2000 Units/Box
SN74LS280D	14 Pin	2500/Tape & Reel

FUNCTIONAL BLOCK DIAGRAM



DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
.,	0 / 1/0//////		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table	
	1			20	μΑ	V _{CC} = MAX, V _{IN} :	= 2.7 V	
Iн	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current			27	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Propagation Delay, Data to Output ΣEVEN		33 29	50 45	ns	C - 45 pF
t _{PLH} t _{PHL}	Propagation Delay, Data to Output ΣΟDD		23 31	35 50	ns	C _L = 15 pF

4-Bit Binary Full Adder with Fast Carry

The SN74LS283 is a high-speed 4-Bit Binary Full Adder with internal carry lookahead. It accepts two 4-bit binary words $(A_1-A_4,\,B_1-B_4)$ and a Carry Input (C_0) . It generates the binary Sum outputs $(\Sigma_1-\Sigma_4)$ and the Carry Output (C_4) from the most significant bit. The LS283 operates with either active HIGH or active LOW operands (positive or negative logic).

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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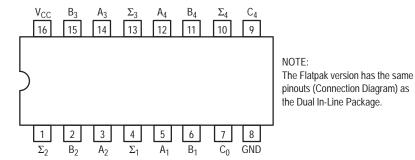
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping
SN74LS283N	16 Pin DIP	2000 Units/Box
SN74LS283D	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)

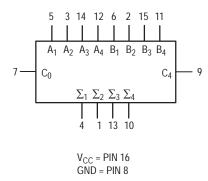


		LOADING (Note a)			
PIN NAMES		HIGH	LOW		
$A_1 - A_4$	Operand A Inputs	1.0 U.L.	0.5 U.L.		
$B_1 - B_4$	Operand B Inputs	1.0 U.L.	0.5 U.L.		
C_0	Carry Input	0.5 U.L.	0.25 U.L.		
$\Sigma_1 - \Sigma_4$	Sum Outputs	10 U.L.	5 U.L.		
C_4	Carry Output	10 U.L.	5 U.L.		

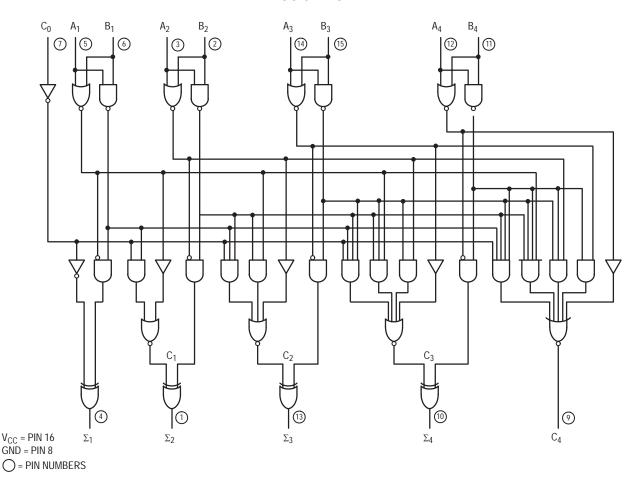
NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The LS283 adds two 4-bit binary words (A plus B) plus the incoming carry. The binary sum appears on the sum outputs $(\Sigma_1 - \Sigma_4)$ and outgoing carry (C4) outputs.

$$\begin{array}{l} C_0 + (A_1 + B_1) + 2(A_2 + B_2) + 4(A_3 + B_3) + 8(A_4 + B_4) = \sum_1 + 2 \\ \sum_2 + 4 \sum_3 + 8 \sum_4 + 16C_4 \end{array}$$

Where: (+) = plus

Due to the symmetry of the binary add function the LS283 can be used with either all inputs and outputs active HIGH (positive logic) or with all inputs and outputs active LOW (negative logic). Note that with active HIGH inputs, Carry Input can not be left open, but must be held LOW when no carry in is intended.

Example:

	C ₀	A ₁	A ₂	A ₃	A ₄	B ₁	B ₂	В3	B ₄	Σ_1	Σ_{2}	Σ3	Σ4	C ₄	
logic levels	L	L	Н	L	Н	Н	L	L	Н	Н	Н	L	L	Н	
Active HIGH	0	0	1	0	1	1	0	0	1	1	1	0	0	1	(1
Active LOW	1	1	0	1	0	0	1	1	0	0	0	1	1	0	(car

(10+9=19) (carry+5+6=12)

Interchanging inputs of equal weight does not affect the operation, thus C_0 , A_1 , B_1 , can be arbitrarily assigned to pins 7, 5 or 3.

FUNCTIONAL TRUTH TABLE

C (n-1)	An	B _n	Σ_{n}	C _n
L	L	L	L	L
L	L	Н	Н	L
L	Н	L	Н	L
L	Н	Н	L	Н
Н	L	L	Н	L
Н	L	Н	L	Н
Н	Н	L	L	Н
Н	Н	Н	Н	Н

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

				Limits					
Symbol	Paramete	r	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	Input HIGH Voltage				V	Guaranteed Inpu All Inputs	t HIGH Voltage for	
V _{IL}	Input LOW Voltage	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for	
V_{IK}	Input Clamp Diode Vol	tage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage		2.7	3.5		V	$V_{CC} = MIN, I_{OH} =$ or V_{IL} per Truth T		
.,	Outroot I OW/Vallage			0.25	0.4	V	$I_{OL} = 4.0 \text{ mA}$ $V_{CC} = V_{CC} \text{ MIN},$		
V _{OL}	Output LOW Voltage			0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table	
		C ₀			20	μА	V MAY V	0.7.1/	
	Innuit I II Cl I Current	Any A or B			40	μА	$V_{CC} = MAX, V_{IN}$	≡ 2.7 V	
Iн	Input HIGH Current	C ₀			0.1	mA	V _{CC} = MAX, V _{IN} :	- 7 O V	
		Any A or B			0.2	mA	VCC = IVIAX, VIN	= 7.0 V	
L.	Input I OW Current	C ₀			-0.4	mA	V MAY V	-041/	
I _{IL}	Input LOW Current	Any A or B			-0.8	mA	$V_{CC} = MAX, V_{IN} = 0.4 V$		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current Total, Output HIGH Total, Output LOW				34	mA	V _{CC} = MAX		
					39]			

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

 C_1 – C_3 are generated internally C_0 is an external input C_4 is an output generated internally

AC CHARACTERISTICS (T_A = 25° C, V_{CC} = 5.0 V)

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay, C_0 Input to Any Σ Output		16 15	24 24	ns	
t _{PLH} t _{PHL}	Propagation Delay, Any A or B Input to Σ Outputs		15 15	24 24	ns	C _L = 15 pF
t _{PLH} t _{PHL}	Propagation Delay, C_0 Input to C_4 Output		11 11	17 22	ns	Figures 1 & 2
t _{PLH} t _{PHL}	Propagation Delay, Any A or B Input to C ₄ Output		11 12	17 17	ns	

AC WAVEFORMS

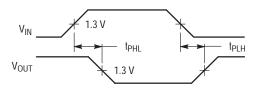


Figure 1.

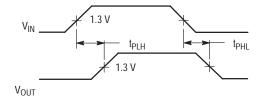


Figure 2.

Quad 2-Input Multiplexer with Storage

The SN74LS298 is a Quad 2-Port Register. It is the logical equivalent of a quad 2-input multiplexer followed by a quad 4-bit edge-triggered register. A Common Select input selects between two 4-bit input ports (data sources.) The selected data is transferred to the output register synchronous with the HIGH to LOW transition of the Clock input.

The LS298 is fabricated with the Schottky barrier process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Select From Two Data Sources
- Fully Edge-Triggered Operation
- Typical Power Dissipation of 65 mW
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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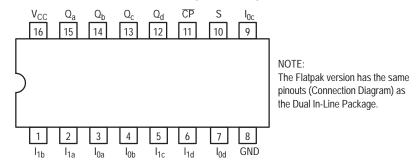
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping		
SN74LS298N	16 Pin DIP	2000 Units/Box		
SN74LS298D	16 Pin	2500/Tape & Reel		

CONNECTION DIAGRAM DIP (TOP VIEW)

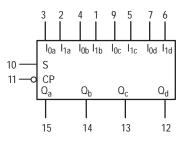


		LOADING (Note a)		
PIN NAMES		HIGH	LOW	
$\frac{S}{CP}$ $I_{0a} - I_{0d}$ $I_{1a} - I_{1d}$ $Q_a - Q_d$	Common Select Input Clock (Active LOW Going Edge) Input Data Inputs from Source 0 Data Inputs from Source 1 Register Outputs	0.5 U.L. 0.5 U.L. 0.5 U.L. 0.5 U.L. 10 U.L.	0.25 U.L. 0.25 U.L. 0.25 U.L. 0.25 U.L. 5 U.L.	

NOTES:

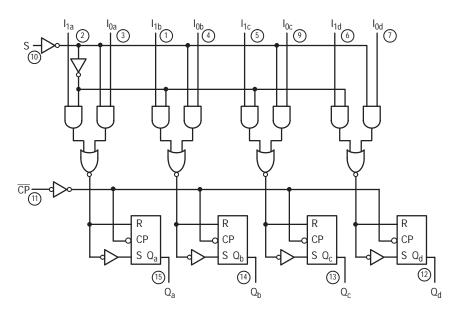
a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



V_{CC} = PIN 16 GND = PIN 8

LOGIC OR BLOCK DIAGRAM



V_{CC} = PIN 16 GND = PIN 8 = PIN NUMBERS

FUNCTIONAL DESCRIPTION

The LS298 is a high speed Quad 2-Port Register. It selects four bits of data from two sources (ports)under the control of a Common Select Input (S). The selected data is transferred to the 4-bit output register synchronous with the HIGH to LOW transition of the Clock input (\overline{CP}). The 4-bit output register is fully edge-triggered. The Data inputs (I) and Select input (S) must be stable only one setup time prior to the HIGH to LOW transition of the clock for predictable operation.

TRUTH TABLE

	OUTPUT		
S	I ₀	l ₁	Q
I	I	Х	L
l l	h	Х	Н
h	Х	I	L
h	Х	h	Н

L = LOW Voltage Level H = HIGH Voltage Level

X = Don't Care

 $\label{eq:lower} I = LOW \ Voltage \ Level \ one \ setup \ time \ prior \ to \ the \ HIGH \ to \ LOW \ clock \ transition.$

 $h = HIGH \ Voltage \ Level \ one \ setup \ time \ prior \ to \ the \ HIGH \ to \ LOW \ clock \ transition.$

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA	
V _{OH}	Output HIGH Voltage	2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
.,			0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table
1	January I II Cold Command			20	μΑ	V _{CC} = MAX, V _{IN} = 2.7 V	
Iн	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	$V_{CC} = MAX$, $V_{IN} = 0.4 V$	
Ios	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX	
I _{CC}	Power Supply Current			21	mA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Propagation Delay,		18	27	ns	$V_{CC} = 5.0 \text{ V},$
t _{PHL}	Clock to Output		21	32	ns	C _L = 15 pF

AC SET-UP REQUIREMENTS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	Clock Pulse Width	20			ns	
t _s	Data Setup Time	15			ns	
t _s	Select Setup Time	25			ns	V _{CC} = 5.0 V
t _h	Data Hold Time	5.0			ns	
t _h	Select Hold Time	0				

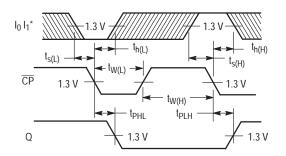
DEFINITIONS OF TERMS

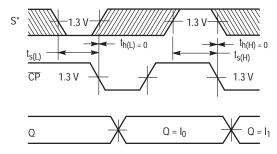
SETUP TIME (t_s) — is defined as the minimum time required for the correct logic level to be present at the logic input prior to the clock transition from LOW to HIGH in order to be recognized and transferred to the outputs.

 $HOLD\ TIME\ (t_h)$ — is defined as the minimum time following the clock transition from LOW to HIGH that the

logic level must be maintained at the input in order to ensure continued recognition. A negative HOLD TIME indicates that the correct logic level may be released prior to the clock transition from LOW to HIGH and still be recognized.

AC WAVEFORMS





^{*}The shaded areas indicate when the input is permitted to change for predictable output performance.

Figure 1. Figure 2.

8-Bit Shift/Storage Register with 3-State Outputs

The SN74LS299 is an 8-Bit Universal Shift/Storage Register with 3-state outputs. Four modes of operation are possible: hold (store), shift left, shift right and load data.

The parallel load inputs and flip-flop outputs are multiplexed to reduce the total number of package pins. Separate outputs are provided for flip-flops Q_0 and Q_7 to allow easy cascading. A separate active LOW Master Reset is used to reset the register.

- Common I/O for Reduced Pin Count
- Four Operation Modes: Shift Left, Shift Right, Load and Store
- Separate Shift Right Serial Input and Shift Left Serial Input for Easy Cascading
- 3-State Outputs for Bus Oriented Applications
- Input Clamp Diodes Limit High-Speed Termination Effects
- ESD > 3500 Volts

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
ІОН	Output Current – High Q ₀ , Q ₇			-0.4	mA
l _{OL}	Output Current – Low Q ₀ , Q ₇			8.0	mA
ІОН	Output Current – High I/O ₀ – 1/O ₇			-2.6	mA
l _{OL}	Output Current – Low I/O ₀ – 1/O ₇			24	mA



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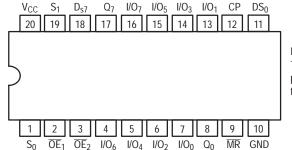
PLASTIC N SUFFIX CASE 738



SOIC DW SUFFIX CASE 751D

Device	Package	Shipping
SN74LS299N	16 Pin DIP	1440 Units/Box
SN74LS299DW	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)

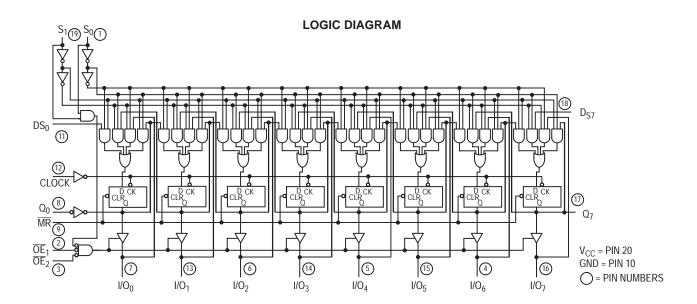


The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

		LOADING	(Note a)
PIN NAMES	S	HIGH	LOW
CP	Clock Pulse (Active Positive–Going Edge) Input	0.5 U.L.	0.25 U.L.
DS0	Serial Data Input for Right Shift	0.5 U.L.	0.25 U.L.
DS7	Serial Data Input for Left Shift	0.5 U.L.	0.25 U.L.
I/O _n	Parallel Data Input or	0.5 U.L.	0.25 U.L.
	Parallel Output (3-State)	65 U.L.	15 U.L.
\overline{OE}_1 , \overline{OE}_2	3-State Output Enable (Active LOW) Inputs	0.5 U.L.	0.25 U.L.
Q ₀ , Q ₇	Serial Outputs	10 U.L.	5 U.L.
MR	Asynchronous Master Reset (Active LOW) Input	0.5 U.L.	0.25 U.L.
S ₀ , S ₁	Mode Select Inputs	1 U.L.	0.5 U.L.

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.



FUNCTION TABLE

	INPUTS						RESPONSE	
MR	S ₁	S ₀	OE ₁	ŌE ₂	СР	DS ₀	DS ₇	
L L	X X H	X X H	H X X	X H X	X X X	X X X	X X X	Asynchronous Reset; $Q_0 = Q_7 = LOW$ I/O Voltage Undetermined
L L	L X	X L	L L	L L	X X	X X	X X	Asynchronous Reset; $Q_0 = Q_7 = LOW$ I/O Voltage LOW
H H	L	H	X L	X L	44	D D	X X	Shift Right; $D \rightarrow Q_0$; $Q_0 \rightarrow Q_1$; etc. Shift Right; $D \rightarrow Q_0 \& I/O_0$; $Q_0 \rightarrow O_1 \& I/O_1$; etc.
H H	H H	L L	X L	X L	44	X X	D D	Shift Left; $D \rightarrow Q_7$; $Q_7 \rightarrow Q_6$; etc. Shift Left; $D \rightarrow Q_7$ & I/O ₇ ; $Q_7 \rightarrow Q_6$ & I/O ₆ ; etc.
Н	Н	Н	Х	Х	Կ	Х	Х	Parallel Load; I/O _n →Q _n
H H	L L	L L	H X	X H	X X	X X	X X	Hold: I/O Voltage undetermined
Н	L	L	L	L	Х	Х	Х	Hold: $I/O_n = Q_n$

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

	Parameter		Limits					
Symbol			Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage		2.0			٧	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage				0.8	٧	Guaranteed Inpu All Inputs	ut LOW Voltage for
V _{IK}	Input Clamp Diode Vol	tage		-0.65	-1.5	٧	V _{CC} = MIN, I _{IN} =	: –18 mA
V _{OH}	Output HIGH Voltage I/O ₀ -I/O ₇		2.4	3.1		V	V _{CC} = MIN, I _{OH}	= MAX
V _{OH}	Output HIGH Voltage Q ₀ , Q ₇		2.7	3.4		V	V _{CC} = MIN, I _{OH}	= MAX
	Output LOW Voltage			0.25	0.4	V	I _{OL} = 12 mA	V _{CC} = V _{CC} MIN,
V _{OL}	I/O ₀ -I/O ₇			0.35	0.5	٧	I _{OL} = 24 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
	Output LOW Voltage				0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$
V_{OL}	I/O ₀ -I/O ₇				0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
I _{OZH}	Output Off Current HIGH I/O ₀ -I/O ₇				40	μА	V _{CC} = MAX, V _{OI}	_{JT} = 2.7 V
I _{OZL}	Output Off Current LO'	W			-400	μΑ	V _{CC} = MAX, V _{OI}	_T = 0.4 V
		Others			20	μА		
		S ₀ , S ₁ , I/O ₀ -I/O ₇			40	μΑ	$V_{CC} = MAX, V_{IN} = 2.7 V$	= 2.7 V
I _{IH}	Input HIGH Current	Others			0.1	mA	V 840V V	701/
		S ₀ , S ₁			0.2	mA	$V_{CC} = MAX, V_{IN}$	= 1.0 V
		I/O ₀ -I/O ₇			0.1	mA	V _{CC} = MAX, V _{IN}	= 5.5 V
lu.	Input LOW Current	Others			-0.4	mA	V00 = MAY V	- 0.4 V
I _{IL}	input LOW Current	S ₀ , S ₁			-0.8	mA	$V_{CC} = MAX, V_{IN} = 0.4 V$	
I _{OS}	Short Circuit Current	Q ₀ , Q ₇	-20		-100	mA	V _{CC} = MAX	
	(Note 1)	I/O ₀ -I/O ₇	-30		-130	mA	V _{CC} = MAX	
Icc	Power Supply Current				53	mA	$V_{CC} = MAX$	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
f _{MAX}	Maximum Clock Frequency	25	35		MHz	
t _{PHL} t _{PLH}	Propagation Delay, Clock to Q ₀ or Q ₇		26 22	39 33	ns	C _L = 15 pF
t _{PHL}	Propagation Delay, Clear to \mathbf{Q}_0 or \mathbf{Q}_7		27	40	ns	
t _{PHL} t _{PLH}	Propagation Delay, Clock to I/O ₀ -I/O ₇		26 17	39 25	ns	
t _{PHL}	Propagation Delay, Clear to I/O ₀ -I/O ₇		26	40	ns	$C_L = 45 \text{ pF},$ $R_L = 667 \Omega$
t _{PZH} t _{PZL}	Output Enable Time		13 19	21 30	ns	
t _{PHZ} t _{PLZ}	Output Disable Time		10 10	15 15	ns	C _L = 5.0 pF

AC SETUP REQUIREMENTS (TA = 25°C, V_{CC} = 5.0 V)

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	Clock Pulse Width HIGH	25			ns	
t _W	Clock Pulse Width LOW	13			ns	
t _W	Clear Pulse Width LOW	20			ns	
t _s	Data Setup Time	20			ns	V 50V
t _S	Select Setup Time	35			ns	V _{CC} = 5.0 V
t _h	Data Hold Time	0			ns	
t _h	Select Hold Time	10			ns	
t _{rec}	Recovery Time	20			ns	

3-STATE WAVEFORMS

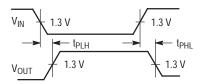


Figure 1.

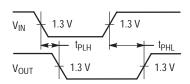


Figure 2.

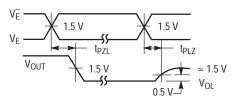


Figure 3.

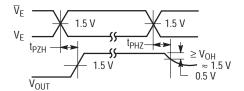


Figure 4.

AC LOAD CIRCUIT

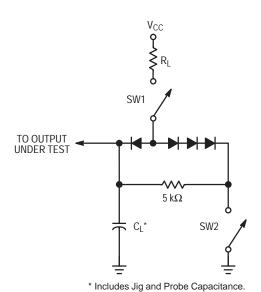


Figure 5.

SWITCH POSITIONS

SYMBOL	SW1	SW2
t _{PZH}	Open	Closed
t _{PZL}	Closed	Open
t _{PLZ}	Closed	Closed
t _{PH7}	Closed	Closed

SN74LS365A SN74LS367A SN74LS368A

3-State Hex Buffers

These devices are high speed hex buffers with 3-state outputs. They are organized as single 6-bit or 2-bit/4-bit, with inverting or non-inverting data (D) paths. The outputs are designed to drive 15 TTL Unit Loads or 60 Low Power Schottky loads when the Enable (E) is LOW.

When the Output Enable (E) is HIGH, the outputs are forced to a high impedance "off" state. If the outputs of the 3-state devices are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-state devices whose outputs are tied together are designed so there is no overlap.



Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-2.6	mA
I _{OL}	Output Current – Low			24	mA



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LOW POWER SCHOTTKY



PLASTIC N SUFFIX CASE 648

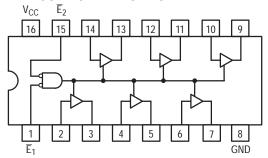


SOIC D SUFFIX CASE 751B

Device	Package	Shipping	
SN74LS365AN	16 Pin DIP	2000 Units/Box	
SN74LS365AD	16 Pin	2500/Tape & Reel	
SN74LS367AN	16 Pin DIP	2000 Units/Box	
SN74LS367AD	16 Pin	2500/Tape & Reel	
SN74LS368AN	16 Pin DIP	2000 Units/Box	
SN74LS368AD	16 Pin	2500/Tape & Reel	

SN74LS365A SN74LS367A SN74LS368A

SN74LS365A HEX 3-STATE BUFFER WITH COMMON 2-INPUT NOR ENABLE



TRUTH TABLE

II	IPUT	OUTPUT	
Ē ₁	E ₂	D	OUTFUT
L	L	L	L
L	L	Н	Н
Н	Х	Х	(Z)
Х	Η	Х	(Z)

SN74LS367A HEX 3-STATE BUFFER SEPARATE 2-BIT AND 4-BIT SECTIONS

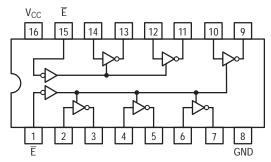
V_{CC} E
16 15 14 13 12 11 10 9

1 2 3 4 5 6 7 8
GND

TRUTH TABLE

INP	JTS	OUTPUT
Ē	D	0011 01
L	L	L
L	Н	Н
Н	Х	(Z)

SN74LS368A HEX 3-STATE INVERTER BUFFER SEPARATE 2-BIT AND 4-BIT SECTIONS



TRUTH TABLE

INP	JTS	ОИТРИТ		
Ē	D			
L L H	L H X	H L (Z)		

SN74LS365A SN74LS367A SN74LS368A

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Tes	st Conditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA
V _{OH}	Output HIGH Voltage	2.4	3.1		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
	Outset I OW/Veller		0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 24 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
I _{OZH}	Output Off Current HIGH	1		20	μΑ	V _{CC} = MAX, V _{OUT} = 2.7 V	
I _{OZL}	Output Off Current LOW			-20	μΑ	V _{CC} = MAX, V _{OL}	_{JT} = 0.4 V
	Input HIGH Current			20	μΑ	$V_{CC} = MAX, V_{IN}$	= 2.7 V
IH	input nigh current			0.1	mA	$V_{CC} = MAX, V_{IN}$	= 7.0 V
	Input LOW Current E Inputs			-0.4	mA	V _{CC} = MAX, V _{IN}	= 0.4 V
I _{IL}	D Inputs			-20	μА	V _{CC} = MAX, V _{IN} = 0.5 V Either E Input at 2.0 V	
				-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V Both E Inputs at 0.4 V	
los	Short Circuit Current (Note 1)	-40		-225	mA	V _{CC} = MAX	
I _{CC}	Power Supply Current LS365A, 367A			24	mA	V _{CC} = MAX	
	LS368A			21]		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)

		Limits							
		LS36	LS365A/LS367A LS36		LS366A/LS368A				
Symbol	Parameter	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay		10 9.0	16 22		7.0 12	15 18	ns	C _L = 45 pF,
t _{PZH} t _{PZL}	Output Enable Time		19 24	35 40		18 28	35 45	ns	$R_L = 667 \Omega$
t _{PHZ} t _{PLZ}	Output Disable Time			30 35			32 35	ns	C _L = 5.0 pF

Octal Transparent Latch with 3-State Outputs; Octal D-Type Flip-Flop with 3-State Output

The SN74LS373 consists of eight latches with 3-state outputs for bus organized system applications. The flip-flops appear transparent to the data (data changes asynchronously) when Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup times is latched. Data appears on the bus when the Output Enable (\overline{OE}) is LOW. When \overline{OE} is HIGH the bus output is in the high impedance state.

The SN74LS374 is a high-speed, low-power Octal D-type Flip-Flop featuring separate D-type inputs for each flip-flop and 3-state outputs for bus oriented applications. A buffered Clock (CP) and Output Enable (OE) is common to all flip-flops. The SN74LS374 is manufactured using advanced Low Power Schottky technology and is compatible with all ON Semiconductor TTL families.

- Eight Latches in a Single Package
- 3-State Outputs for Bus Interfacing
- Hysteresis on Latch Enable
- Edge-Triggered D-Type Inputs
- Buffered Positive Edge-Triggered Clock
- Hysteresis on Clock Input to Improve Noise Margin
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-2.6	mA
I _{OL}	Output Current – Low			24	mA



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> LOW POWER SCHOTTKY



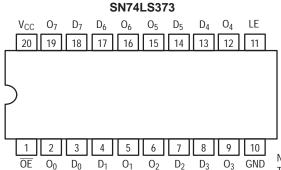
PLASTIC N SUFFIX CASE 738



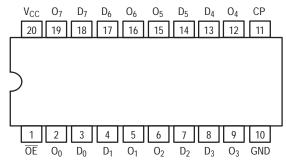
SOIC DW SUFFIX CASE 751D

Device	Package	Shipping
SN74LS373N	16 Pin DIP	1440 Units/Box
SN74LS373DW	16 Pin	2500/Tape & Reel
SN74LS374N	16 Pin DIP	1440 Units/Box
SN74LS374DW	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



SN74LS374



NOTE:

The Flatpak version has the same pinouts (Connection Diagram) as the Dual In-Line Package.

PIN NAMES

 $D_0 - D_7$ Data Inputs LĚ Latch Enable (Active HIGH) Input СР Clock (Active HIGH Going Edge) Input ΟE Output Enable (Active LOW) Input

Outputs $O_0 - O_7$

NOTES:

a) 1 TTL Unit Load (U.L.) = $40 \mu A HIGH/1.6 mA LOW$.

LOADING (Note a)

HIGH	LOW
0.5 U.L.	0.25 U.L.
65 U.L.	15 U.L.

TRUTH TABLE

LS373

D _n	LE	OE	On
Η	Η	L	Н
L	Н	L	L
Х	L	L	Q_0
Х	Х	Н	Z*

H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial

Z = High Impedance

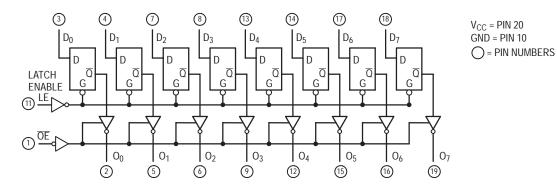
D _n	LE	ΟE	On
Н	4	L	Н
L	4	L	L
Х	Х	Н	Z*

LS374

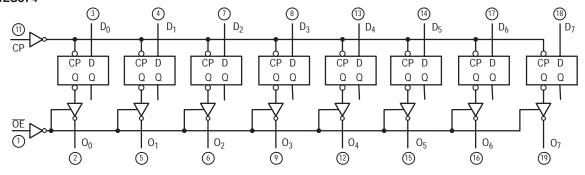
^{*} Note: Contents of flip-flops unaffected by the state of the Output Enable input (OE).

LOGIC DIAGRAMS

SN74LS373



SN74LS374



DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu	t HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu	t LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA
V _{OH}	Output HIGH Voltage	2.4	3.1		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
.,	Output I OW/Vallages		0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$
V_{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 24 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
I _{OZH}	Output Off Current HIGH			20	μΑ	$V_{CC} = MAX, V_{OU}$	_T = 2.7 V
I _{OZL}	Output Off Current LOW			-20	μΑ	$V_{CC} = MAX, V_{OU}$	T = 0.4 V
	Input HICH Current			20	μΑ	$V_{CC} = MAX, V_{IN} = 2.7 V$	
Iн	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	$V_{CC} = MAX$, $V_{IN} = 0.4 V$	
I _{OS}	Short Circuit Current (Note 1)	-30		-130	mA	V _{CC} = MAX	
I _{CC}	Power Supply Current			40	mA	$V_{CC} = MAX$	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

			Limits						
			LS373		LS374				
Symbol	Parameter	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
f _{MAX}	Maximum Clock Frequency				35	50		MHz	
t _{PLH} t _{PHL}	Propagation Delay, Data to Output		12 12	18 18				ns	C 45 pF
t _{PLH} t _{PHL}	Clock or Enable to Output		20 18	30 30		15 19	28 28	ns	$C_L = 45 \text{ pF},$ $R_L = 667 \Omega$
t _{PZH} t _{PZL}	Output Enable Time		15 25	28 36		20 21	28 28	ns	
t _{PHZ} t _{PLZ}	Output Disable Time		12 15	20 25		12 15	20 25	ns	C _L = 5.0 pF

AC SETUP REQUIREMENTS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

		Limit		nits		
		LS:	373	LS:	374	
Symbol	Parameter	Min	Max	Min	Max	Unit
t _W	Clock Pulse Width	15		15		ns
t _s	Setup Time	5.0		20		ns
t _h	Hold Time	20		0		ns

DEFINITION OF TERMS

SETUP TIME (t_s) — is defined as the minimum time required for the correct logic level to be present at the logic input prior to LE transition from HIGH-to-LOW in order to be recognized and transferred to the outputs.

HOLD TIME (t_h) — is defined as the minimum time following the LE transition from HIGH-to-LOW that the logic level must be maintained at the input in order to ensure continued recognition.

SN74LS373

AC WAVEFORMS

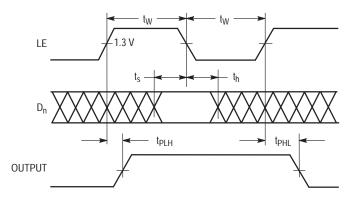


Figure 1.

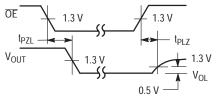


Figure 2.

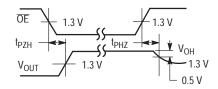


Figure 3.

AC LOAD CIRCUIT

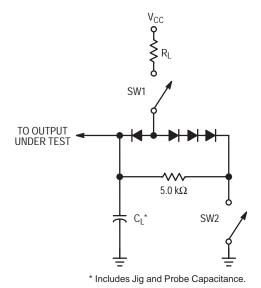


Figure 4.

SWITCH POSITIONS

SYMBOL	SW1	SW2
t _{PZH}	Open	Closed
t _{PZL}	Closed	Open
t _{PLZ}	Closed	Closed
t _{PHZ}	Closed	Closed

SN74LS374

AC WAVEFORMS

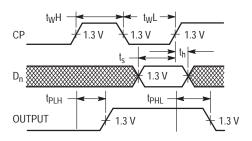
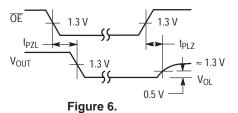


Figure 5.



0E 1.3 V 1.3 V 1.3 V V_{OUT} 1.3 V V_{OUT} 1.3 V V_{OUT} 0.5 V

Figure 7.

AC LOAD CIRCUIT

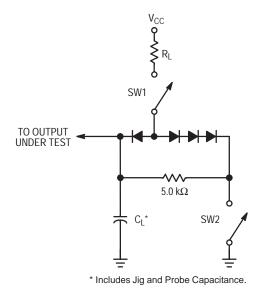


Figure 8.

SWITCH POSITIONS

SYMBOL	SW1	SW2
t _{PZH}	Open	Closed
t _{PZL}	Closed	Open
t _{PLZ}	Closed	Closed
t _{PHZ}	Closed	Closed

Octal D Flip-Flop with Enable

The SN74LS377 is an 8-bit register built using advanced Low Power Schottky technology. This register consists of eight D-type flip-flops with a buffered common clock and a buffered common clock enable.

- 8-Bit High Speed Parallel Registers
- Positive Edge-Triggered D-Type Flip Flops
- Fully Buffered Common Clock and Enable Inputs
- True and Complement Outputs
- Input Clamp Diodes Limit High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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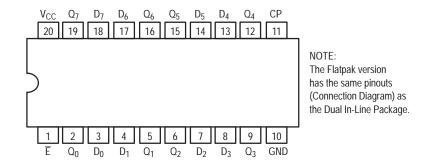
PLASTIC N SUFFIX CASE 738



SOIC DW SUFFIX CASE 751D

Device	Package	Shipping
SN74LS377N	16 Pin DIP	1440 Units/Box
SN74LS377DW	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



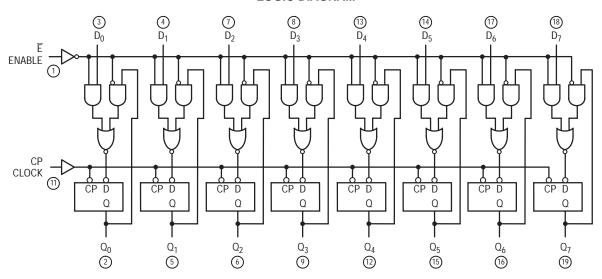
LOADING (Note a)

PIN NAMES	3	HIGH	LOW
Ē	Enable (Active LOW) Input	0.5 U.L.	0.25 U.L.
$D_0 - D_3$	Data Inputs	0.5 U.L.	0.25 U.L.
CP	Clock (Active HIGH Going Edge) Input	0.5 U.L.	0.25 U.L.
$Q_0 - Q_3$	True Outputs	10 U.L.	5 U.L.
$\overline{Q}_0 - \overline{Q}_3$	Complemented Outputs	10 U.L.	5 U.L.

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μA HIGH/1.6 mA LOW.

LOGIC DIAGRAM



DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input All Inputs	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs		
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	٧	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$		
V _{OH}	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN$, $I_{OH} = MAX$, $V_{IN} = V_{IH}$ or V_{IL} per Truth Table		
V	Outrot I OM Value		0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$	
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table	
	lament HCH Commant			20	μΑ	V _{CC} = MAX, V _{IN} :	= 2.7 V	
I _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V		
I _{OS}	Short Circuit Current (Note 1)	-20		-100	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current			28	mA	V _{CC} = MAX, NOT	E 1	

NOTE: With all inputs open and GND applied to all data and enable inputs, I_{CC} is measured after a momentary GND, then 4.5 V is applied to clock. Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
f _{MAX}	Maximum Clock Frequency	30	40		MHz	V 50V
t _{PLH} t _{PHL}	Propagation Delay, Clock to Output		17 18	27 27	ns	$V_{CC} = 5.0 \text{ V}$ $C_L = 15 \text{ pF}$

AC SETUP REQUIREMENTS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

			Limits				
Symbol	Para	meter	Min	Тур	Max	Unit	Test Conditions
t _W	Any Pulse Width		20			ns	
t _s	Data Setup Time		20			ns	
	Enable Setup	Inactive — State	10			ns	$V_{CC} = 5.0 \text{ V}$
t _s	Time	Active — State	25			ns	
t _h	Any Hold Time		5.0			ns	

DEFINITION OF TERMS

SETUP TIME (ts) — is defined as the minimum time required for the correct logic level to be present at the logic input prior to the clock transition from LOW-to-HIGH in order to be recognized and transferred to the outputs.

 $HOLD\ TIME\ (t_h)$ — is defined as the minimum time following the clock transition from LOW-to-HIGH that the

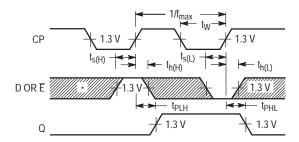
logic level must be maintained at the input in order to ensure continued recognition. A negative HOLD TIME indicates that the correct logic level may be released prior to the clock transition from LOW-to-HIGH and still be recognized.

TRUTH TABLE

Ē	СР	D _n	Q _n	\overline{Q}_n
Н		X	No Change	No Change
L	\	Н	Н	L
L	_	L	L	Н

L = LOW Voltage Level H = HIGH Voltage Level X = Immaterial

AC WAVEFORM



^{*}The shaded areas indicate when the input is permitted to change for predictable output performance.

Dual 4-Stage Binary Counter

The SN74LS393 contains a pair of high-speed 4-stage ripple counters.

Each half of the LS393 operates as a Modulo-16 binary divider, with the last three stages triggered in a ripple fashion. In the LS393, the flip-flops are triggered by a HIGH-to-LOW transition of their CP inputs. Each half of each circuit type has a Master Reset input which responds to a HIGH signal by forcing all four outputs to the LOW state.

- Dual Versions
- Individual Asynchronous Clear for Each Counter
- Typical Max Count Frequency of 50 MHz
- Input Clamp Diodes Minimize High Speed Termination Effects

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-0.4	mA
I _{OL}	Output Current – Low			8.0	mA



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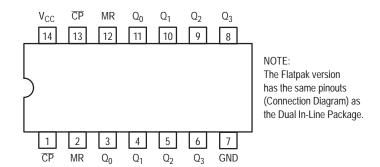
PLASTIC N SUFFIX CASE 646



SOIC D SUFFIX CASE 751A

Device	Package	Shipping
SN74LS393N	14 Pin DIP	2000 Units/Box
SN74LS393D	14 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



		LOADING (Note a)	
PIN NAMES		HIGH	LOW
CP	Clock (Active LOW Going Edge)		
	Input to +16 (LS393)	0.5 U.L.	1.0 U.L.
CP₀	Clock (Active LOW Going Edge)		
	Input to ÷2 (LS390)	0.5 U.L.	1.0 U.L.
CP₁	Clock (Active LOW Going Edge)		
	Input to ÷ 5 (LS390)	0.5 U.L.	1.5 U.L.
MR	Master Reset (Active HIGH) Input	0.5 U.L.	0.25 U.L.
$Q_0 - Q_3$	Flip–Flop Outputs	10 U.L.	5 U.L.

NOTES:

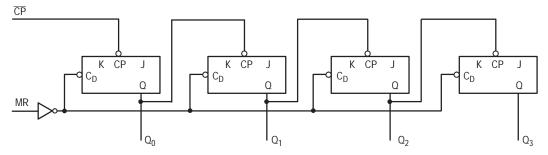
a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

FUNCTIONAL DESCRIPTION

Each half of the SN74LS393 operates in the Modulo 16 binary sequence, as indicated in the $\div 16$ Truth Table. The first flip-flop is triggered by HIGH-to-LOW transitions of the CP input signal. Each of the other flip-flops is triggered by a HIGH-to-LOW transition of the Q output of the preceding flip-flop. Thus state changes of the Q outputs do

not occur simultaneously. This means that logic signals derived from combinations of these outputs will be subject to decoding spikes and, therefore, should not be used as clocks for other counters, registers or flip-flops. A HIGH signal on MR forces all outputs to the LOW state and prevents counting.

SN74LS393 LOGIC DIAGRAM (one half shown)



TRUTH TABLE

COUNT		OUTF	PUTS		
COUNT	Q_3	Q_2	Q ₁	Q_0	
0 1 2 3			ココエエ	⊔ H ⊔ H	•
4 5 6 7		HHHH	LLHH	L H L	
8 9 10 11	H H H		LHH	L H L	
12 13 14 15	H H H H	1111		L H L H	

H = HIGH Voltage Level L = LOW Voltage Level

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

				Limits				
Symbol	Parameter		Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for
V_{IK}	Input Clamp Diode Volt	age		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA
V _{OH}	Output HIGH Voltage		2.7	3.5		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table	
				0.25	0.4	V	I _{OL} = 4.0 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage			0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
	Innut HCH Current				20	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V
I _{IH}	Input HIGH Current				0.1	mA	V _{CC} = MAX, V _{IN}	= 7.0 V
		MR			-0.4	mA		
I_{IL}	Input LOW Current	CP, CP ₀			-1.6	mA	$V_{CC} = MAX, V_{IN}$	= 0.4 V
		CP ₁			-2.4	mA		
I _{OS}	Short Circuit Current (N	Note 1)	-20		-100	mA	V _{CC} = MAX	
I _{CC}	Power Supply Current				26	mA	V _{CC} = MAX	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

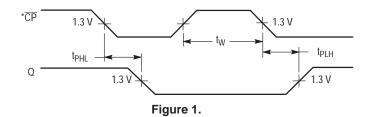
AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

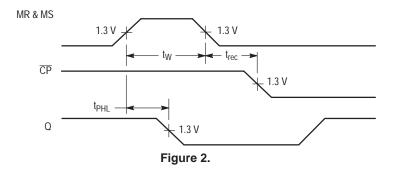
			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
f _{MAX}	Maximum Clock Frequency CP ₀ to Q ₀	25	35		MHz	
f _{MAX}	Maximum Clock Frequency CP ₁ to Q ₁	20			MHz	
t _{PLH} t _{PHL}	Propagation Delay, CP to Q ₀		12 13	20 20	ns	C _L = 15 pF
t _{PLH} t _{PHL}	CP to Q₃		40 40	60 60	ns	
t _{PHL}	MR to Any Output		24	39	ns	

AC SETUP REQUIREMENTS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)

		Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	Clock Pulse Width	20			ns	
t _W	MR Pulse Width	20			ns	V _{CC} = 5.0 V
t _{rec}	Recovery Time	25			ns	

AC WAVEFORMS





 * The number of Clock Pulses required between t_{PHL} and t_{PLH} measurements can be determined from the appropriate Truth Table.

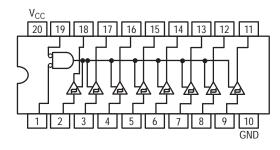
Octal Buffer/Line Driver with 3-State Outputs

The SN74LS541 is an octal buffer and line driver with the same functions as the LS241, but with pinouts on the opposite side of the package.

This device type is designed to be used as a memory address driver, clock driver and bus-oriented transmitter/receiver. This device is especially useful as output ports for the microprocessors, allowing ease of layout and greater PC board density.

- Hysteresis at Inputs to Improve Noise Margin
- PNP Inputs Reduce Loading
- 3-State Outputs Drive Bus Lines
- Inputs and Outputs Opposite Side of Package, Allowing Easier Interface to Microprocessors
- Input Clamp Diodes Limit High-Speed Termination Effects

LOGIC AND CONNECTION DIAGRAM DIP (TOP VIEW)



GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-15	mA
I _{OL}	Output Current – Low			24	mA



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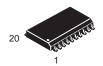
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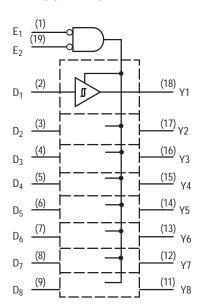
PLASTIC N SUFFIX CASE 738



SOIC DW SUFFIX CASE 751D

Device	Package	Shipping		
SN74LS541N	16 Pin DIP	1440 Units/Box		
SN74LS541DW	16 Pin	2500/Tape & Reel		

BLOCK DIAGRAM



IN	IPUTS	3	OUTPUTS				
E ₁	E ₂	D	LS540	LS541			
L	L	Н	L	Н			
Н	Х	Х	Z	Z			
Χ	Н	Х	Z	Z			
L	L	L	Н	L			

L = LOW Voltage Level

H = HIGH Voltage Level

X = Immaterial

Z = High Impedance

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input All Inputs	t HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Input All Inputs	t LOW Voltage for
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	٧	V _{CC} = MIN, I _{IN} =	–18 mA
V	Outrot HCH Veltage	2.4	3.4		٧	V _{CC} = MIN, I _{OH} =	: –3.0 mA
V _{OH}	Output HIGH Voltage	2.0			V	V _{CC} = MIN, I _{OH} =	: MAX, V _{IL} = 0.5 V
.,	0 / // 0 // //		0.25	0.4	٧	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage		0.35	0.5	٧	I _{OL} = 24 mA	$V_{IN} = V_{IL}$ or V_{IH} per Truth Table
$V_{T+}-V_{T-}$	Hysteresis	0.2	0.4		٧	V _{CC} = MIN	
I _{OZH}	Output Off Current HIGH			20	μА	V _{CC} = MAX, V _{OU}	_T = 2.7 V
I _{OZL}	Output Off Current LOW			-20	μА	V _{CC} = MAX, V _{OU}	_T = 0.4 V
	Innut IIICI Current			20	μА	V _{CC} = MAX, V _{IN} :	= 2.7 V
t _{IH}	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} :	= 7.0 V
I _{IL}	Input LOW Current			-0.2	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
Ios	Short Circuit Current (Note 1)	-40		-225	mA	V _{CC} = MAX	
	Power Supply Current Total, Output HIGH			32	mA		
Icc	Total, Output LOW			52	mA	$V_{CC} = MAX$	
	Total Output 3-State			55	mA	1	

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions	
t _{PLH}	Propagation Delay,		12	15			
t _{PHL}	Data to Output		12	18	ns	V 50V	
t _{PZH}	Output Enable Time to HIGH Level		15	32	ns	V_{CC} = 5.0 V C_L = 45 pF R_L = 667 Ω	
t _{PZL}	Output Enable Time to LOW Level		20	38	ns		
t _{PHZ}	Output Disable Time to HIGH Level		10	18	ns	0 50.55	
t _{PLZ}	Output Disable Time to LOW Level		15	29	ns	C _L = 5.0 pF	

AC WAVEFORMS

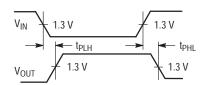


Figure 1.

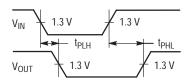


Figure 2.

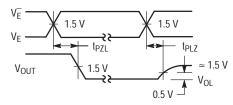


Figure 3.

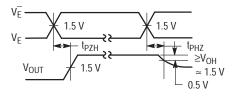
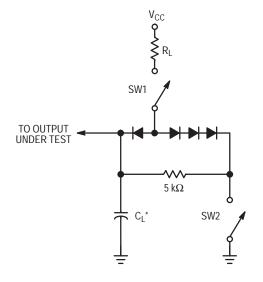


Figure 4.



SWITCH POSITIONS

SYMBOL	SW1	SW2
t _{PZH}	Open	Closed
t _{PZL}	Closed	Open
t _{PLZ}	Closed	Closed
t _{PHZ}	Closed	Closed

Figure 5.

SN74LS640 SN74LS641 SN74LS642 SN74LS645

Octal Bus Transceivers

These octal bus transceivers are designed for asynchronous two-way communication between data buses. Control function implementation minimizes external timing requirements. These circuits allow data transmission from the A bus to B or from the B bus to A bus depending upon the logic level of the direction control (DIR) input. Enable input (\overline{G}) can disable the device so that the buses are effectively isolated.

DEVICE	OUTPUT	LOGIC
LS640	3-State	Inverting
LS641	Open-Collector	True
LS642	Open-Collector	Inverting
LS645	3-State	True



CONTROL INPUTS		OPERATION					
G	DIR	LS640 LS642	LS641 LS645				
L	L	B data to A bus	B data to A bus				
L	Н	Ā data to B bus	A data to B bus				
Н	Х	Isolation	Isolation				

H = HIGH Level, L = LOW Level, X = Irrelevant

GUARANTEED OPERATING RANGES (SN74LS640, SN74LS645)

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-3.0	mA
				-15	mA
I _{OL}	Output Current – Low			24	mA

GUARANTEED OPERATING RANGES (SN74LS641, SN74LS642)

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
V _{OH}	Output Voltage – High			5.5	V
I _{OL}	Output Current – Low		·	24	mA



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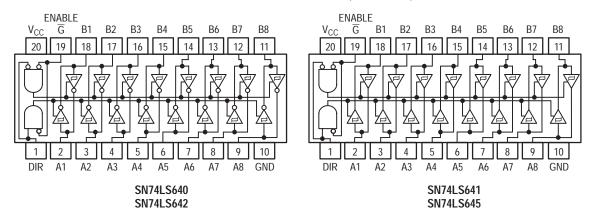


SOIC DW SUFFIX CASE 751D

Device	Package	Shipping			
SN74LS640N	16 Pin DIP	1440 Units/Box			
SN74LS640DW	16 Pin	2500/Tape & Reel			
SN74LS641N	16 Pin DIP	1440 Units/Box			
SN74LS641DW	16 Pin	2500/Tape & Reel			
SN74LS642N	16 Pin DIP	1440 Units/Box			
SN74LS642DW	16 Pin	2500/Tape & Reel			
SN74LS645N	16 Pin DIP	1440 Units/Box			
SN74LS645DW	16 Pin	2500/Tape & Reel			

SN74LS640 SN74LS641 SN74LS642 SN74LS645

CONNECTION DIAGRAMS DIP (TOP VIEW)



SN74LS640 SN74LS641 SN74LS642 SN74LS645

SN74LS640 • SN74LS645

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits						
Symbol	Parame	eter	Min	Тур	Max	Unit	Test (Conditions	
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Input All Inputs	: HIGH Voltage for	
V _{IL}	Input LOW Voltage				0.6	V	Guaranteed Input All Inputs	LOW Voltage for	
V _{IK}	Input Clamp Diode Vo	ltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V	Outside HIOLE Value as		2.4	3.4		V	V _{CC} = MIN, I _{OH} =	3.0 mA	
V _{OH}	Output HIGH Voltage		2.0			V	V _{CC} = MIN, I _{OH} = MAX		
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	Output LOW Voltage			0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$	
V _{OL}	Output LOW Voltage			0.35	0.5	V	I _{OL} = 24 mA	per Truth Table	
I _{OZH}	Output Off Current HI	GH			20	μА	V _{CC} = MAX, V _{OU}	T = 2.7 V	
l _{OZL}	Output Off Current LC	W			-400	μА	$V_{CC} = MAX, V_{OUT} = 0.4 V$		
		A or B, DIR or \overline{G}			20	μΑ	V _{CC} = MAX, V _{IN} :	= 2.7 V	
I _{IH}	Input HIGH Current	DIR or G			0.1	mA	V _{CC} = MAX, V _{IN} :	= 7.0 V	
		A or B			0.1	mA	V _{CC} = MAX, V _{IN} :	= 5.5 V	
I _{IL}	Input LOW Current				-0.4	mA	V _{CC} = MAX, V _{IN} :	= 0.4 V	
I _{OS}	Output Short Circuit Current (Note 1)		-40		-225	mA	V _{CC} = MAX		
	Power Supply Current Total Output HIGH				70	^			
Icc	Total, Output LOW				90	mA	V _{CC} = MAX		
	Total at HIGH Z				95				

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

		Limits							
			LS640			LS645			
Symbol	Parameter	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Propagation Delay A to B		6.0 8.0	10 15		8.0 11	15 15	ns	
t _{PLH}	Propagation Delay B to A		6.0 8.0	10 15		8.0 11	15 15	ns	C _L = 45 pF,
t _{PZL} t _{PZH}	Output Enable Time G, DIR to A		31 23	40 40		31 26	40 40	ns	$R_L = 667 \Omega$
t _{PZL} t _{PZH}	Output Enable Time G, DIR to B		31 23	40 40		31 26	40 40	ns	
t _{PLZ} t _{PHZ}	Output Disable Time G, DIR to A		15 15	25 25		15 15	25 25	ns	C ₁ = 5.0 pF
t _{PLZ} t _{PHZ}	Output Disable Time G, DIR to B		15 15	25 25		15 15	25 25	ns	O _L = 3.0 μr

SN74LS640 SN74LS641 SN74LS642 SN74LS645

SN74LS641 • SN74LS642

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test	Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Inpu	t HIGH Voltage for	
V _{IL}	Input LOW Voltage			0.6	V	Guaranteed Input All Inputs	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$		
I _{OH}	Output HIGH Current			100	μА	V _{CC} = MIN, V _{OH} = MAX		
V	Output LOW Voltage		0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$	
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 24 mA	per Truth Table	
	Input HICH Current			20	μΑ	V _{CC} = MAX, V _{IN} :	= 2.7 V	
I _{IH}	Input HIGH Current			-0.1	mA	V _{CC} = MAX, V _{IN} :	= 7.0 V	
I _{IL}	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} :	= 0.4 V	
	Power Supply Current Total, Output HIGH			70				
Icc	Total, Output LOW			90	mA	$V_{CC} = MAX$		
	Total at HIGH Z			95	1			

AC CHARACTERISTICS ($T_A = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$)

		Limits							
			LS641		LS642		1		
Symbol	Parameter	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay, A to B		17 16	25 25		19 14	25 25	ns	
t _{PLH} t _{PHL}	Propagation Delay, B to A		17 16	25 25		19 14	25 25	ns	C _L = 45 pF,
t _{PLH} t _{PHL}	Propagation Delay, G, DIR to A		23 34	40 50		26 43	40 60	ns	$R_L = 667 \Omega$
t _{PLH} t _{PHL}	Propagation Delay, G, DIR to B		25 37	40 50		28 39	40 60	ns	

4 x 4 Register File with 3-State Outputs

The TTL/MSI SN74LS670 is a high-speed, low-power 4 x 4 Register File organized as four words by four bits. Separate read and write inputs, both address and enable, allow simultaneous read and write operation.

The 3-state outputs make it possible to connect up to 128 outputs to increase the word capacity up to 512 words. Any number of these devices can be operated in parallel to generate an n-bit length.

- Simultaneous Read/Write Operation
- Expandable to 512 Words by n-Bits
- Typical Access Time to 20 ns
- 3-State Outputs for Expansion
- Typical Power Dissipation of 125 mW

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-2.6	mA
I _{OL}	Output Current – Low			24	mA



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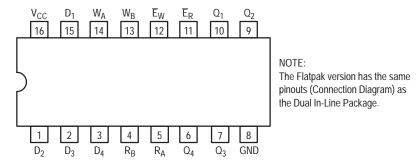
PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B

Device	Package	Shipping		
SN74LS670N	16 Pin DIP	2000 Units/Box		
SN74LS670D	16 Pin	2500/Tape & Reel		

CONNECTION DIAGRAM DIP (TOP VIEW)

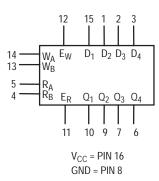


		LOADING	(Note a)
PIN NAMES		HIGH	LOW
D ₁ – D ₄	Data Inputs	0.5 U.L.	0.25 U.L.
W_A , W_B	Write Address Inputs	0.5 U.L.	0.25 U.L.
\overline{E}_{W}	Write Enable (Active LOW) Input	1.0 U.L.	0.5 U.L.
R_A , R_B	Read Address Inputs	0.5 U.L.	0.25 U.L.
\overline{E}_R	Read Enable (Active LOW) Input	1.5 U.L.	0.75 U.L.
Q ₁ – Q ₄	Outputs	65 U.L.	15 U.L.

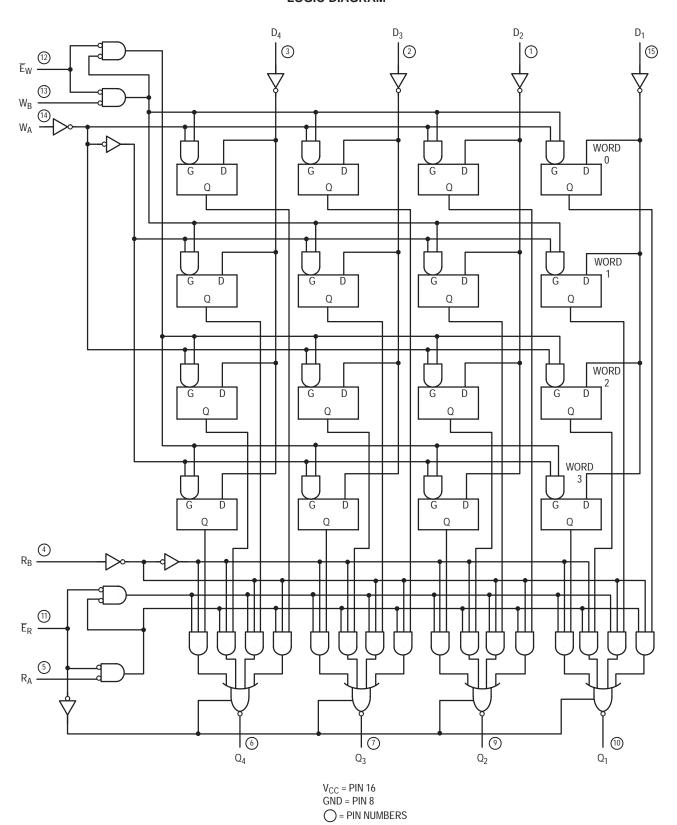
NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC SYMBOL



LOGIC DIAGRAM



DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	–18 mA	
V _{OH}	Output HIGH Voltage	2.4	3.1		V	V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH} or V_{IL} per Truth Table		
.,	0 / / 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0		0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$	
V_{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 24 mA	 V_{IN} = V_{IL} or V_{IH} per Truth Table 	
I _{OZH}	Output Off Current HIGH			20	μА	$V_{CC} = MAX, V_O = 2.7 V$		
I _{OZL}	Output Off Current LOW			-20	μΑ	$V_{CC} = MAX, V_O = 0.4 V$		
I _{IH}	Input HIGH Current D, R, W E _W E _R			20 40 60	μА	V _{CC} = MAX, V _{IN}	= 2.7 V	
	D, R, W E _W E _R			0.1 0.2 0.3	mA	V _{CC} = MAX, V _{IN} = 7.0 V		
I _{IL}	Input LOW Current D, R, W E _W E _R			-0.4 -0.8 -1.2	mA	$V_{CC} = MAX$, $V_{IN} = 0.4 V$		
Ios	Short Circuit Current (Note 1)	-30		-130	mA	V _{CC} = MAX		
I _{CC}	Power Supply Current			50	mA	V _{CC} = MAX		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay, R _A or R _B to Output		23 25	40 45	ns	
t _{PLH} t _{PHL}	Propagation Delay, $\overline{\mathbb{E}}_{W}$ to Output		26 28	45 50	ns	V _{CC} = 5.0 V, C _L = 45 pF
t _{PLH} t _{PHL}	Propagation Delay, Data to Output		25 23	45 40	ns	C _L = 45 pF
t _{PZH} t _{PZL}	Output Enable Time		15 22	35 40	ns	
t _{PLZ} t _{PHZ}	Output Disable Time		16 30	35 50	ns	C _L = 5.0 pF

AC SETUP REQUIREMENTS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _W	Pulse Width	25			ns	
t _s	Setup Time, (D)	10			ns	
t _s	Setup Time, (W)	15			ns	V 50V
t _h	Hold Time, (D)	15			ns	V _{CC} = 5.0 V
t _h	Hold Time, (W)	5.0			ns	
t _{rec}	Recovery Time	25			ns	

AC WAVEFORMS

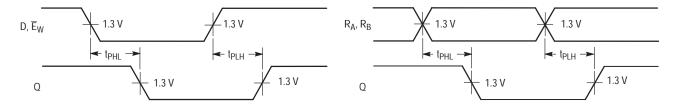


Figure 1. Figure 2.

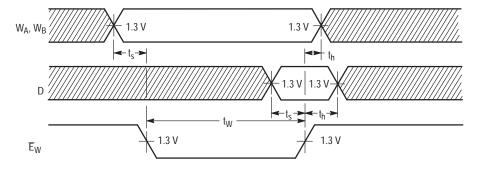


Figure 3.

8-Bit Magnitude **Comparators**

The SN74LS682, 684, 688 are 8-bit magnitude comparators. These device types are designed to perform comparisons between two eight-bit binary or BCD words. All device types provide $\overline{P} = \overline{Q}$ outputs and the LS682 and LS684 have $\overline{P}>Q$ outputs also.

The LS682, LS684 and LS688 are totem pole devices. The LS682 has a 20 $k\Omega$ pullup resistor on the Q inputs for analog or switch data.

TYPE	P = Q	P > Q	OUTPUT ENABLE	OUTPUT CONFIGURATION	PULLUP
LS682	yes	yes	no	totem-pole	yes
LS684	yes	yes	no	totem-pole	no
LS688	yes	no	yes	totem-pole	no

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			- 0.4	mA
I _{OL}	Output Current – Low			24	mA



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> LOW **POWER SCHOTTKY**



PLASTIC N SUFFIX CASE 738

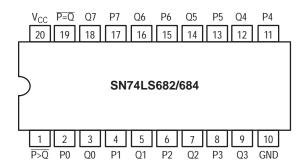


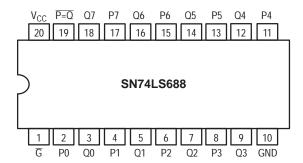
SOIC **DW SUFFIX CASE 751D**

ORDERING INFORMATION

Device	Package	Shipping		
SN74LS682N	16 Pin DIP	1440 Units/Box		
SN74LS682DW	16 Pin	2500/Tape & Reel		
SN74LS684N	16 Pin DIP	1440 Units/Box		
SN74LS684DW	16 Pin	2500/Tape & Reel		
SN74LS688N	16 Pin DIP	1440 Units/Box		
SN74LS688DW	16 Pin	2500/Tape & Reel		

CONNECTION DIAGRAMS (TOP VIEW)





FUNCTION TABLE

	INPUTS			PUTS
DATA	ENABL	ES		
P, Q	G, GT	G2	P = Q	P > Q
P = Q	L	L L		Н
P > Q	L	L	Н	L
P < Q	L	L	Н	Н
X	Н	Н	Н	Н

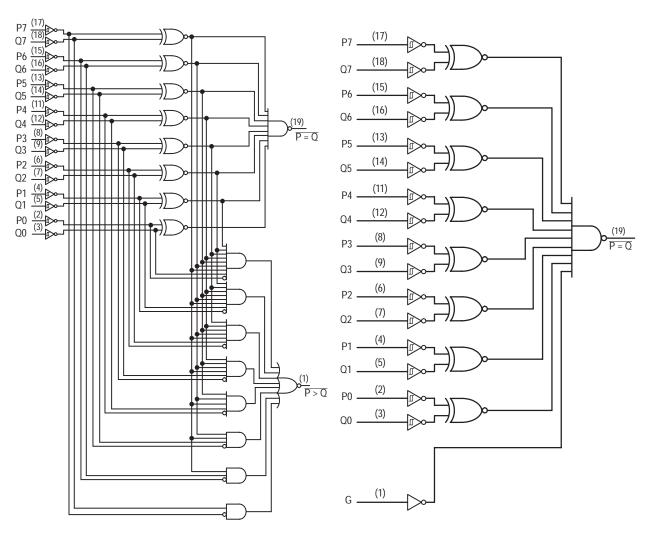
H = HIGH Level, L = LOW Level, X = Irrelevant

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

				Limits				
Symbol	Parameter		Min	Тур	Max	Unit	Test	Conditions
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for
V_{IK}	Input Clamp Diode Vo	oltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} =	−18 mA
V _{OH}	Output HIGH Voltage		2.7	3.5		V	V _{CC} = MIN, I _{OH} or V _{IL} per Truth	= MAX, V _{IN} = V _{IH} Table
.,				0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$
V _{OL}	Output LOW Voltage			0.35	0.5	V	I _{OL} = 24 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
					20	μΑ	$V_{CC} = MAX, V_{IN}$	= 2.7 V
I _{IH}	Input HIGH Current	LS682-Q Inputs			0.1	mA	V _{CC} = MAX, V _{IN} = 5.5 V	
		Others			0.1	mA	$V_{CC} = MAX, V_{IN}$	= 7.0 V
I	Input LOW Current	LS682-Q Inputs			-0.4	mA	V MAY V	-041/
1 _{IL}	Input LOW Current	Others			-0.2	mA	$V_{CC} = MAX, V_{IN} = 0.4 V$	
I _{OS}	Short Circuit Current	(Note 1)	-30		-130	mA	V _{CC} = MAX	
	LS682				70	mA		
I _{CC}	Power Supply Current	LS684			65	mA	V _{CC} = MAX	
		LS688			65	mA		

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

LOGIC DIAGRAMS



SN74LS682 and LS684

SN74LS688

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

SN74LS682

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay, P to $\overline{P} = \overline{Q}$		13 15	25 25	ns	
t _{PLH} t _{PHL}	Propagation Delay, Q to $\overline{P} = \overline{Q}$		14 15	25 25	ns	$V_{CC} = 5.0 \text{ V}$ $C_L = 45 \text{ pF}$
t _{PLH} t _{PHL}	Propagation Delay, P to P > Q		20 15	30 30	ns	$R_L = 667 \Omega$
t _{PLH}	Propagation Delay, Q to P > Q		21 19	30 30	ns	

SN74LS684

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay, P to $\overline{P} = \overline{Q}$		15 17	25 25	ns	
t _{PLH} t _{PHL}	Propagation Delay, Q to $\overline{P} = \overline{Q}$		16 15	25 25	ns	V _{CC} = 5.0 V C _L = 45 pF
t _{PLH} t _{PHL}	Propagation Delay, P to $\overline{P} > \overline{Q}$		22 17	30 30	ns	$R_L = 667 \Omega$
t _{PLH} t _{PHL}	Propagation Delay, Q to P > Q		24 20	30 30	ns	

SN74LS688

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH} t _{PHL}	Propagation Delay, P to $\overline{P} = \overline{Q}$		12 17	18 23	ns	
t _{PLH} t _{PHL}	Propagation Delay, Q to $\overline{P} = \overline{Q}$		12 17	18 23	ns	$V_{CC} = 5.0 \text{ V}$ $C_L = 45 \text{ pF}$ $R_I = 667 \Omega$
t _{PLH} t _{PHL}	Propagation Delay, \overline{G} , $\overline{G1}$ to $\overline{P} = \overline{Q}$		12 13	18 20	ns	ı



CHAPTER 5 Reliability Data

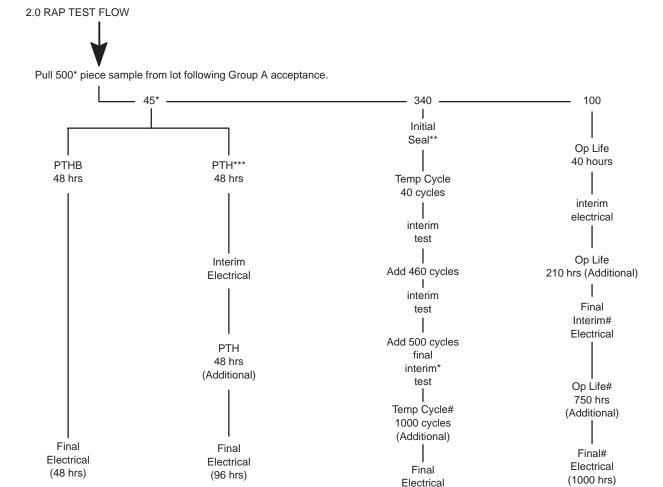


"RAP" Reliability Audit Program for Logic Integrated Circuits

1.0 INTRODUCTION

The Reliability Audit Program developed in March 1977 is the ON Semiconductor internal reliability audit which is designed to assess outgoing product performance under accelerated stress conditions. Logic Reliability Engineering has overall responsibility for RAP, including updating its requirements, interpreting its results, administration at offshore locations, and monthly reporting of results. These reports are available at all sales offices.

RAP is a system of environmental and electrical tests performed periodically on randomly selected samples of standard products. Each sample receives the tests specified in section 2.0. Frequency of testing is specified per internal document 12MRM15301A.



- # One sample per month for LS, 10H, 10K, MG CMOS, and HSL CMOS.
- * PTHB or PTH not required for hermetic products: reduce total sample size to 450 pcs. Additional sample reductions for high pin-count devices per TABLE II notes.
- ** Seal (Fine & Gross Leak) required for hermetic products.
- *** PTH to be used when sockets for PTHB are not available.

3.0 TEST CONDITIONS AND COMMENTS

scrap

PTHB — 15 psig/121 $^{\circ}$ C/100% RH at rated V_{CC} or V_{EE} — to be performed on plastic encapsulated devices only.

TEMP CYCLING — MIL-STD-883, Method 1010, Condition C, $-65^{\circ}C/+150^{\circ}C$.

OP LIFE — MIL-STD-883, Method 1005, Condition C (Power plus Reverse Bias), $T_A = 145$ °C.

NOTES:

& Seal** (2000 cycles)

scrap

1. All standard 25°C dc and functional parameters will be measured Go/No/Go at each readout.

scrap

- 2. Any indicated failure is first verified and then submitted to the Product Analysis Lab for detailed analysis.
- 3. Sampling to include all package types routinely.
- 4. Device types sampled will be by generic type within each logic I/C product family (MECL, TTL, etc.) and will include all assembly locations.
- 5. 16 hrs. PTHB is equivalent to approximately 800 hours of 85°C/85% RH THB for $V_{CC} \le 15$ V.
- 6. Only moisture related failures (like corrosion) are criteria for failure on PTHB test.
- 7. Special device specifications (48A's) for logic products will reference 12MRM15301A as source of generic data for any customer required monthly audit reports.

CHAPTER 6 Package Information Including Surface Mount



BIPOLAR LOGIC SURFACE MOUNT

WHY SURFACE MOUNT?

Surface Mount Technology is now being utilized to offer answers to many problems that have been created in the use of insertion technology.

Limitations have been reached with insertion packages and PC board technology. Surface Mount Technology offers the opportunity to continue to advance the State-of-the-Art designs that cannot be accomplished with Insertion Technology.

Surface Mount Packages allow more optimum device performance with the smaller Surface Mount configuration. Internal lead lengths, parasitic capacitance and inductance that placed limitations on chip performance have been reduced.

The lower profile of Surface Mount Packages allows more boards to be utilized in a given amount of space. They are stacked closer together and utilize less total volume than insertion populated PC boards.

Printed circuit costs are lowered with the reduction of the number of board layers required. The elimination or reduction of the number of plated through holes in the board, contribute significantly to lower PC board prices.

Surface Mount assembly does not require the preparation of components that are common on insertion technology lines. Surface Mount components are sent directly to the assembly line, eliminating an intermediate step.

Automatic placement equipment is available that can place Surface Mount components at the rate of a few thousand per hour to hundreds of thousands of components per hour.

Surface Mount Technology is cost effective, allowing the manufacturer the opportunity to produce smaller units and/or offer increased functions with the same size product.

SURFACE MOUNT AVAILABILITY

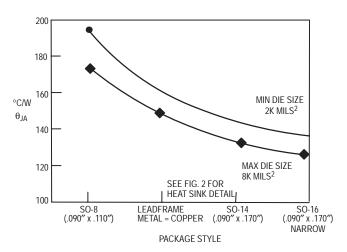
Bipolar Logic is currently offering LS-TTL in production quantities in SOIC packages.

Refer to the following Selector Guide (SG366/D) which indicate availability and package type for these families.

These families may be ordered in rails or on Tape and Reel. Refer to Tape and Reel information for ordering details.

THERMAL DATA

The power dissipation of surface mount packages is dependent on many factors that must be taken into consideration in the initial board design. The board material, the board surface metal thickness, pad area and the proximity to other heat generating components all have a bearing on the device dissipation capability.



DATA TAKEN USING PHILIPS SO TEST BOARD # 7322-078, 80873

Figure 1. Thermal Resistance, Junction-To-Ambient (°C/W)

Measurement specimens are solder mounted on printed circuit card 19 mm \times 28 mm \times 1.5 mm in still air. No auxiliary thermal condition aids are used.

This data was collected using thermal test die in 20-pin PLCC packages on PLCC test boards (2.24" x 2.24" x .062" glass epoxy, type FR-4, with solder coated 1 oz./sq. ft. copper).

TAPE AND REEL

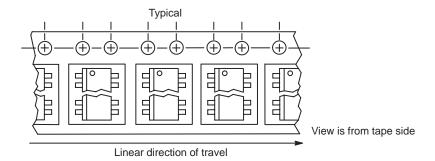
STANDARD BIPOLAR LOGIC INTEGRATED CIRCUITS

ON Semiconductor has now added the convenience of Tape and Reel packaging for our growing family of standard Integrated Circuit products. The packaging fully conforms

to the latest EIA RS-481A specification. The antistatic embossed tape provides a secure cavity sealed with a peel-back cover tape.

MECHANICAL POLARIZATION

SOIC DEVICES



GENERAL INFORMATION

Reel Size
Tape Width
13 inch (330 mm) Suffix R2
12 mm to 24 mm (see table)

— Units/Reel (see table)

- No Partial Reel Counts Available and Minimum Lot Size is Per Table

ORDERING INFORMATION

To order devices which are to be delivered in Tape and Reel, add the suffix R2 to the device number being ordered.

Table 1
Tape and Reel Data

Device Type	Tape Width (mm)	Device/Reel	Reel Size (inch)	Min Lot Size Per Part No. Tape and Reel
SO-8	12	2,500	13	5,000
SO-14	16	2,500	13	5,000
SO-16	16	2,500	13	5,000
SO-16 Wide	16	1,000	13	5,000
SO-20 Wide	24	1,000	13	5,000

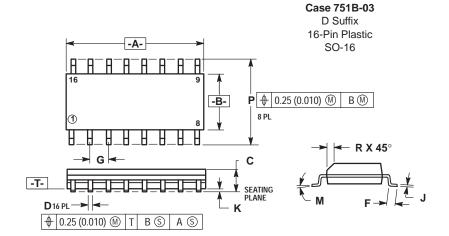
PACKAGE OUTLINES

SOIC

Case 751A-02 D Suffix 14-Pin Plastic SO-14 -A-**P** | ♦ | 0.25 (0.010) M B M-B-1 R X 45° С G -T-SEATING ¹ K PLANE ♦ 0.25 (0.010) M T B S A S

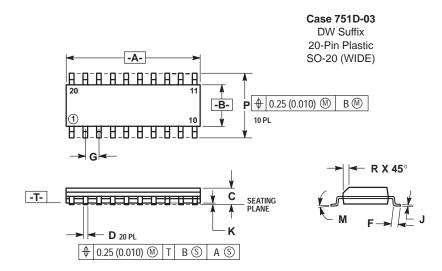
- 1. DIMENSIONS "A" AND "B" ARE DATUMS AND "T" IS A DATUM SURFACE.
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- PER SIDE. 751A-01 IS OBSOLETE, NEW STANDARD

	MILLIM	ETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	8.55	8.75	0.337	0.344	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0°	7°	0°	7°	
P	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- PER SIDE. 751B-01 IS OBSOLETE, NEW STANDARD 751B-03.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A AND B DO NOT INCLUDE MOLD
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- 751D-01, AND -02 OBSOLETE, NEW STANDARD 751D-03.

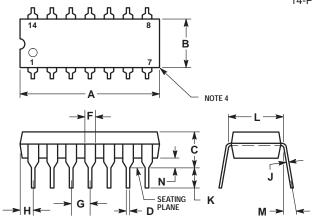
	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	12.65	12.95	0.499	0.510	
В	7.40	7.60	0.292	0.299	
С	2.35	2.65	0.093	0.104	
D	0.35	0.49	0.014	0.019	
F	0.50	0.90	0.020	0.035	
G	1.27 BSC		0.050	BSC	
J	0.25	0.32	0.010	0.012	
K	0.10	0.25	0.004	0.009	
M	0°	7°	0°	7°	
P	10.05	10.55	0.395	0.415	
R	0.25	0.75	0.010	0.029	

PACKAGE OUTLINES

PLASTIC

Case 646-06

N Suffix 14-Pin Plastic



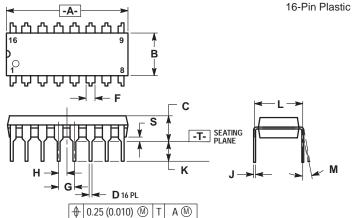
NOTES:

- 1. LEADS WITHIN 0.13 mm (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
- DIMENSION "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
- DIMENSION "B" DOES NOT INCLUDE MOLD FLASH.
- 4. ROUNDED CORNERS OPTIONAL.
 5. 646-05 OBSOLETE, NEW STANDARD 646-06.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	18.16	19.56	0.715	0.770
В	6.10	6.60	0.240	0.260
С	3.69	4.69	0.145	0.185
D	0.38	0.53	0.015	0.021
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
Н	1.32	2.41	0.052	0.095
J	0.20	0.38	0.008	0.015
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300	BSC
M	0°	10°	0°	10°
N	0.39	1.01	0.015	0.039

Case 648-08

N Suffix

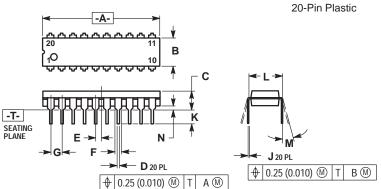


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
- DIMENSION "B" DOES NOT INCLUDE MOLD FLASH.
- ROUNDED CORNERS OPTIONAL.
 648-01 THRU -07 OBSOLETE, NEW STANDARD

l	MILLIMETERS		INC	HF2	
DIM	MIN	MAX	MIN	MAX	
Α	18.80	19.55	0.740	0.770	
В	6.35	6.85	0.250	0.270	
С	3.69	4.44	0.145	0.175	
D	0.39	0.53	0.015	0.021	
F	1.02	1.77	0.040	0.070	
G	2.54 BSC		0.100	0 BSC	
Н	1.27 BSC		0.050	50 BSC	
J	0.21	0.38	0.008	0.015	
K	2.80	3.30	0.110	0.130	
L	7.50	7.74	0.295	0.305	
M	0°	10°	0°	10°	
S	0.51	1.01	0.020	0.040	

Case 738-03

N Suffix



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 CONTROLLING DIMENSION: INCH.

 JUMENSION "L" TO CENTER OF LEAD WHEN
- FORMED PARALLEL.
- 4. DIMENSION "B" DOES NOT INCLUDE MOLD FLASH.
- 5. 738-02 OBSOLETE, NEW STANDARD 738-03.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	25.66	27.17	1.010	1.070	
В	6.10	6.60	0.240	0.260	
С	3.81	4.57	0.150	0.180	
D	0.39	0.55	0.015	0.022	
E	1.27 BSC		0.050 BSC		
F	1.27	1.77	0.050	0.070	
G	2.54 BSC		0.100	0 BSC	
J	0.21	0.38	0.008	0.015	
K	2.80	3.55	0.110	0.140	
L	7.62 BSC		0.300	BSC	
M	0°	15°	0°	15°	
N	0.51	1.01	0.020	0.040	

ON SEMICONDUCTOR WORLDWIDE SALES OFFICES

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Huntsville(256)464–6800
CALIFORNIA
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GEORGIA
Atlanta (770)338–3810
ILLINOIS Chiange (947)442, 2500
Chicago (847)413–2500 MASSACHUSETTS
Boston (781)932–9700
MICHIGAN
Detroit (248)347–6800
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Plymouth (612)249–2360
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REFERENCE MANUAL

A Reference Manual is a publication that contains a comprehensive system or device–specific description of the structure and function (operation) of a particular part/system; used overwhelmingly to describe the functionality of a microprocessor, microcontroller, or some other sub–micron sized device. Procedural information in a Reference Manual is limited to less than 40 percent (usually much less).

USER'S GUIDE

A User's Guide contains procedural, task—oriented instructions for using or running a device or product. A User's Guide differs from a Reference Manual in the following respects:

- * Majority of information (> 60%) is procedural, not functional, in nature
- * Volume of information is typically less than for Reference Manuals
- * Usually written more in active voice, using second-person singular (you) than is found in Reference Manuals
- * May contain photographs and detailed line drawings rather than simple illustrations that are often found in Reference Manuals

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A Pocket Guide is a pocket–sized document that contains technical reference information. Types of information commonly found in pocket guides include block diagrams, pinouts, alphabetized instruction set, alphabetized registers, alphabetized third–party vendors and their products, etc.

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A Product Preview is a summary document for a product/device under consideration or in the early stages of development. The Product Preview exists only until an "Advance Information" document is published that replaces it. The Product Preview is often used as the first section or chapter in a corresponding reference manual. The Product Preview displays the following disclaimer at the bottom of the first page: "ON Semiconductor reserves the right to change or discontinue this product without notice."

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Notes

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